



FRONTPGRADE

DATASHEET

UT36PFD103

36V Smart Power Switch Controller

3/7/2025

Version 3.4

Case Temperature	Radiation Immunity
-55°C to +125°C	TID >100k rad(Si) SEL Immune ≤ 100 MeV-cm ² /mg SEU Immune ≤ 40 MeV-cm ² /mg SET Immune ≤ 80 MeV-cm ² /mg

1 Features

- 8V-36V eFUSE Power Switch Controller
 - Single- or Dual-Supply Operation
- MIL-STD-461 CS106 Compatible to 56V
- Source Power Switching with Inrush current limiting
- Forward Overcurrent and Short Circuit Protection
 - <500ns typical short circuit break response
- Optional OR_FET with Reverse Current Protection
- Line and Load Side Voltage Monitor and Protection
- Optional Digital Voltage and Current Telemetry
 - 10-bit VIN/VOUT/IDS Telemetry (via PMBus®)
- Latching/Retriggerable/Pulsing Power FET Control
- Package Options:
 - 47-Lead Dual Flatpack
 - 16.1 x 10.75 mm, 0.635 mm pitch
 - Mass = 2.3gm
- Standard Microcircuit Drawing: 5962-20206

2 Introduction

The UT36PFD103 Smart Power Switch Controller (SPSC) is an intelligent PowerMOSFET controller with load-side inrush current limiting and eFuse protection of current faults. An optional Ideal Diode (OR FET) facilitates redundant power architectures such as uninterruptable power supplies. The SPSC accommodates protection of the PowerFET SOA while providing flexible power switching control for a wide range of space applications.

3 Applications

- Power Distribution with Short Circuit Protection
- SpaceVPX – SpaceUM VS1 (+12V) Power Switching
- Uninterruptable Power Supplies
- Launch-Vehicle Long Power Harness Splicing
- Pyro ARM-FIRE Controller
- Thruster and Waveguide Actuation Controller

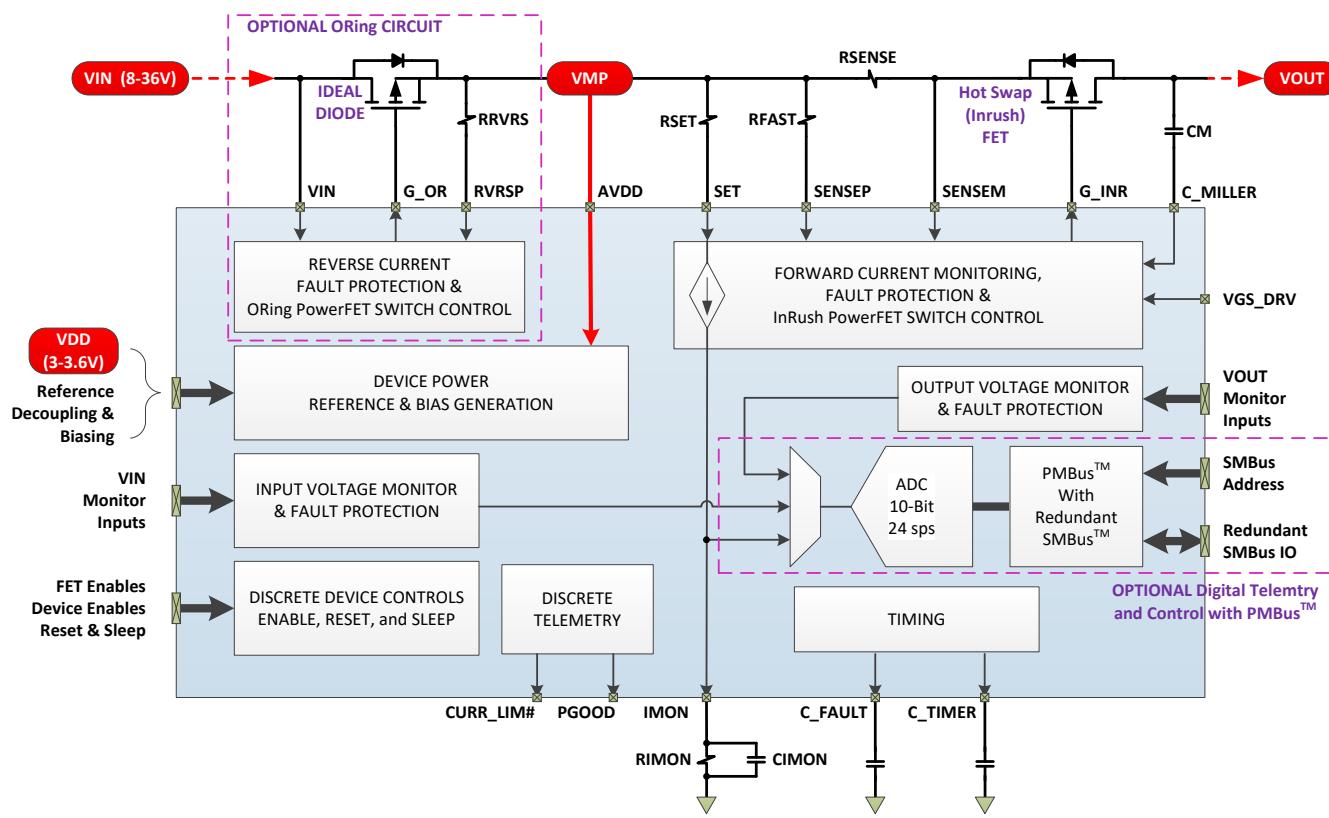


Figure 1-3-1. UT36PFD103 Block Diagram

TABLE OF CONTENTS

1	Features.....	2
2	Introduction	2
3	Applications.....	2
4	Pinout Package Arrangement.....	6
5	Pinlist.....	6
6	Functional Overview.....	11
6.1	Load Slew Rate Control and Inrush Current Limiting	11
6.2	OR FET Switch	11
6.3	Forward Current Monitoring	11
6.4	Overcurrent Fault Protection	12
6.5	Short Circuit Break Fault Protection	12
6.6	Voltage Fault Protection	13
6.7	Voltage Monitoring	13
6.8	PMBus	13
7	Absolute Maximum Ratings ^(1, 2)	14
8	Operational Environment.....	14
9	Recommended Operating Conditions ⁽¹⁾	15
10	Electrical Characteristics ⁽¹⁾	15
11	Timing Characteristics.....	25
12	Typical Performance Characteristics ⁽¹⁾ Sample Size for most of the following charts is N>=95	34
13	Detailed Functional Description	47
13.1	PMBus® / SMBus Functional Description.....	47
13.1.1	PMBus Command Definitions	51
13.1.2	SMBus Ternary Addressing with Parity	60
13.1.3	SMBus Address Resolution Protocol (ARP) and Unique Device Identification (UDID)	62
14	Application Configurations.....	66
15	Packaging Drawings	68
16	Ordering information	69
16.1	Frontgrade Part Number	69
16.2	SMD Part Number.....	70
17	Revision History.....	71
Date	71	
Version	71	
Editor	71	
Datasheet Level.....	71	
Change Description	71	

TABLE OF FIGURES

Figure 1-3-1. UT36PFD103 Block Diagram.....	3
Figure 4-1. Package Pinout with Signal Groupings	6
Figure 10-1. ADC Ideal Transfer Function.....	24
Figure 11-1. Current Limit Response Timing Diagram	25
Figure 11-2. Reverse Current and Short Circuit Break Timing Diagram	26
Figure 11-3. Voltage Fault and PGOOD Timing Diagram.....	27
Figure 11-4. Commanded Enable and Disable Timing Diagram	28
Figure 11-5. Power Up/Down and Reset Timing Diagram	29
Figure 11-6. Master Reset Timing Diagram.....	30
Figure 11-7. Sleep Timing Diagram.....	31
Figure 11-8. SMBus Timing Diagram	32
Figure 11-9. SMBus IO Test Load	33
Figure 13-1. SPSC PMBus / SMBus Block Diagram	47
Figure 13-2. PMBus / SMBus System At a Glance.....	48
Figure 13-3. I ² C Address Byte Formatting	48
Figure 13-4. I ² C Data Byte Formatting	49
Figure 13-5. SMBus Network Layer Protocol Formatting Summary	49
Figure 13-6. PMBus Protocol Formatting and Supported Commands	50
Figure 13-7. ARP GENERAL GET UDID Command with SPSC Ternary Address 29h (41 decimal)	64
Figure 13-8. ARP DIRECTED GET UDID Command with SPSC Ternary Address 29h (41 decimal).....	65
Figure 14-1. Essential Hot Swap Controller Configuration with eFuse Fault Protection	66
Figure 14-2. Essential SPSC Load-Switch control with	67
Figure 15-1: 47-Lead Flatpack Outline Drawing	68

4 Pinout Package Arrangement

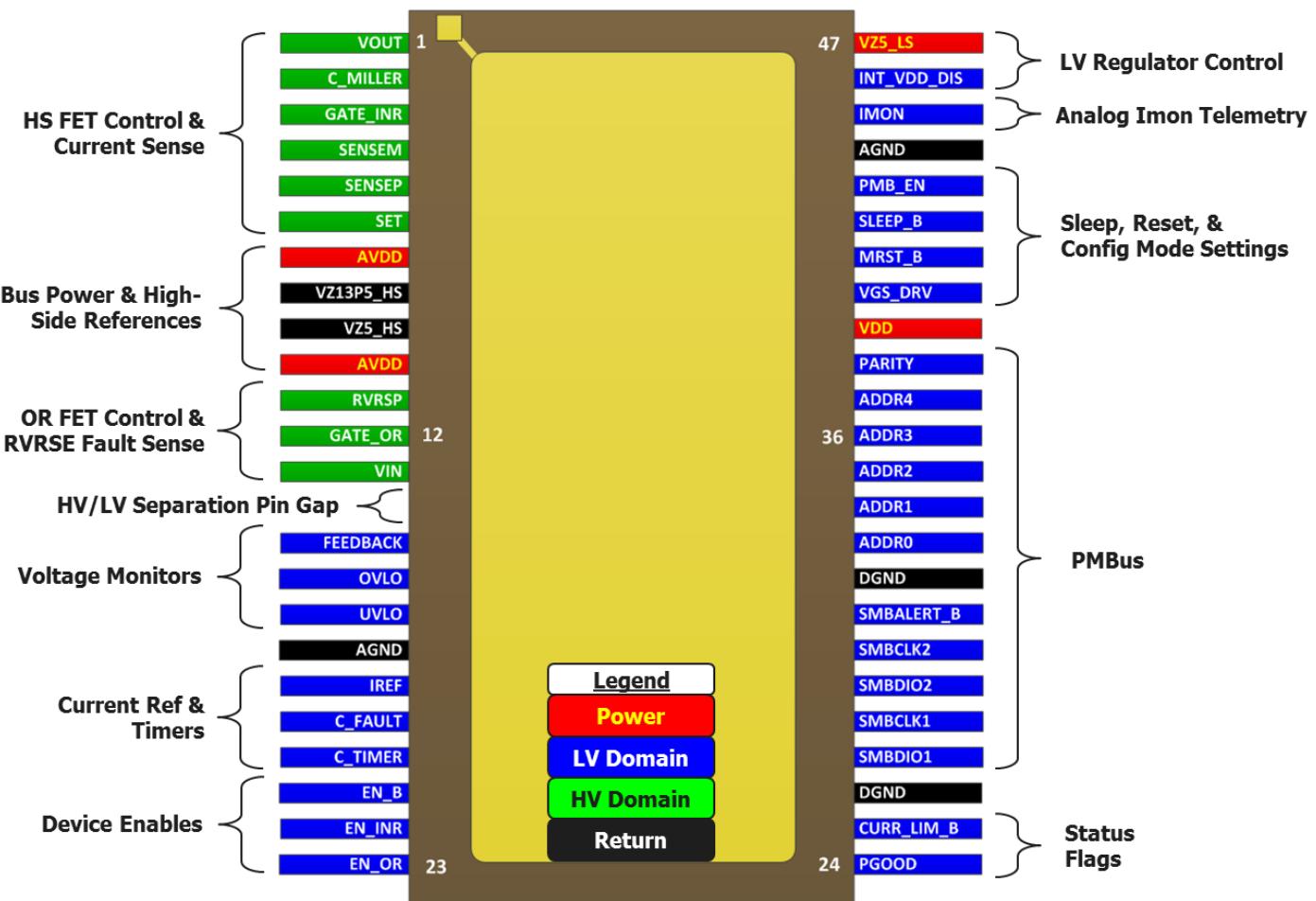


Figure 4-1. Package Pinout with Signal Groupings

5 Pinlist

Table 5-1: Pin Type Legend

Abbreviation	Description
IPU	CMOS Input with Internal Pull-Up
I	CMOS Compatible Input
OD	Open Drain Output
SMIO	SMBus IO
SMI	SMBus Input
SMO	SMBus Output
TERN	Ternary Inputs
AI	Analog Input
AI	Analog Input
AO	Analog Output
AI0	Analog Input/Output
P	Power

Table 5-2: Pin Definitions (Note 1)

Number	Name	Type	Active	Description
26, 32	DGND	P		Digital ground return pins.
17, 44	AGND	P		Analog ground return pins. These pins need to be connected to a quiet ground plane on the PCB.
7, 10	AVDD	P (Reference to AGND)	-	8V-36V High voltage input power supply to chip provided from VIN power line in single FET power switching application or SOURCE terminal of ORing FET in ORing applications.
39	VDD/CBYP	P (Reference to DGND)	-	Bypass capacitor and VDD pin. A bypass capacitor must be connected from this pin to GND if internal 3.3V regulator is enabled. This pin must be connected to external 3.3V power supply if internal regulator is disabled i.e. INT_VDD_DIS is forced to VZ5_LS, high (5V typical)
46	INT_VDD_DIS	I (Power domain VZ5_LS reference to DGND)	-	Internal 3.3V regulator disable pin. Connecting this pin to VZ5_LS pin will disable the internal 3.3V regulator. If this pin is tied to GND the internal 3.3V regulator is enabled. A bypass capacitor will be required from VDD/CBYP pin to DGND.
9	VZ5_HS	P (Reference to AVDD domain)		Internal high side Zener based regulated supply typically 5V below AVDD. Bypass cap required from this pin to AVDD.
8	VZ13P5_HS	P (Reference to AVDD domain)		Internal high side Zener based regulated supply typically 13.5V below AVDD. Bypass cap required from this pin to AVDD
47	VZ5_LS	P (Reference to AGND)		Internal low side Zener based regulated supply typically 5V with reference to AGND. It is driven from AVDD. Bypass cap required from this pin to AGND.
18	IREF	AI (Power domain VDD reference to AGND)	-	A nominally 1V reference pin that sets the device's precision bias current when a 24.9KΩ resistor is connected from this pin to AGND. This pin also represents 50% of the ADC voltage reference.
5	SENSEP	AI (Power domain AVDD reference to VZ5_HS)	-	Fast trip sense pin for very high current limit. External resistor is connected from positive terminal of sense resistor to this pin.
6	SET	AI (Power domain AVDD reference to VZ5_HS)	-	Current limit programming pin. External resistor is connected from positive terminal of sense resistor to this pin.
4	SENSEM	AI (Power domain AVDD reference to VZ5_HS)	-	Negative terminal of sense resistor and source of load PCH_MOSFET
3	GATE_INR	AO (Power domain AVDD reference to VZ13P5_HS)	-	Gate driver output for external inrush switch PCH_MOSFET
2	C_MILLER	AO (Power domain AVDD reference to VZ13P5_HS)	-	Slew-rate limiting miller capacitor

Number	Name	Type	Active	Description
11	RVRSP	AI (Power domain AVDD reference to VZ5_HS)	-	Positive reverse current detection pin. External resistor is connected from positive terminal of sense resistor / source of ORing PCH power FET to this pin.
12	GATE_OR	AO (Power domain AVDD reference to VZ13P5_HS)	-	Gate driver output for external ORING switch PCH_MOSFET
45	IMON	AIO (Power domain VDD reference to AGND)	-	Analog current monitor and current limit adjustable pin. A 1.6KΩ resistor is connected from this pin to AGND. Ratio of this resistor to SET pin resistor programs the threshold for current limit
24	PGOOD	OD (Power domain VDD reference to DGND)	HIGH	Power GOOD status (active high open drain). True when internal device power domains and VIN, and FEEDBACK (e.g. VOUT) are within their operating range as set by voltage dividers. This pin can be used to drive enable pin for other devices.
25	CURR_LIM_B	OD (Power domain VDD reference to DGND)	LOW	Active low open drain output. When LOW, this pin indicates a current limit fault.
19	C_FAULT	AIO (Power domain VDD reference to AGND)		Adjustable fault timer for over-current timeout. A capacitor connected from this pin to AGND will set the pulse width for the analog current limit timer. This timer gets activated if the over-current limit is detected. When nothing is connected to this pin, then the default timer is set internally.
20	C_TIMER	AIO (Power domain VDD reference to DGND)		Capacitor connected from this pin to DGND will program the clock frequency of a local oscillator to be used in timer circuits.
40	VGS_DRV	I (Power domain VDD reference to DGND)	-	CMOS inputs VGS_DRV will set the VGS drive on external PCH_FET switch. When high, sets VZ13P5_HS to 13.5V below AVDD, typical. When low, sets VZ13P5_HS to 8.7V below AVDD, typical.
22	EN_INR	AI (Power domain VDD reference to AGND)	-	Active high input to enable inrush gate driver. This enable input is logically combined with EN_B and PMBUS serial interface operation command register ON/OFF bit 7.
23	EN_OR	AI (Power domain VDD reference to AGND)	-	Active high input to enable ORing gate driver. This enable input is logically combined with the EN_B and PMBUS serial interface operation command register ON/OFF bit 7.
21	EN_B	AI (Power domain VDD reference to AGND)	LOW	Active low master device enable input. The active state of this pin, combined with the active state of EN_INR, EN_OR, and PMBus Operation Register Bit 7 determines if the FET gate controls can be driven active. For Pulse Mode applications: If this pin is tied to AGND the on/off pulsing duration may be controlled by the PMBUS serial interface. If EN_B pin is driven by micro controller open drain output and PMB_EN is tied to AGND, the on/off pulsing duration is adjusted by external R and C connected to EN_B pin.

Number	Name	Type	Active	Description
13	VIN	AI (Power domain VDD reference to AGND)	-	Source input bus voltage to internal ADC. The voltage on this input is scaled by 20:1 V/V and passed as VOUT telemetry to the 10-bit ADC. Internal measurements of this pin voltage are only accessible through PMBus.
16	UVLO	AI (Power domain VDD reference to AGND)	-	Under Voltage Lock Out pin monitors the voltage VIN (Power supply) for Under Voltage fault. A resistor voltage divider from VIN to AGND is compared with internal VREF. If voltage on UVLO gets below the UVLO threshold level the load FET gate and output will be disabled.
15	OVLO	AI (Power domain VDD reference to AGND)	-	Over Voltage Lock Out pin monitors the voltage VIN (Power supply) for Over Voltage fault. A resistor voltage divider from VIN to AGND to be compared with internal VREF. If voltage on OVLO exceeds the OVLO threshold level the load FET gate and output will be disabled.
1	VOUT	AI (Power domain VDD reference to AGND)	-	Monitor input to the switched load side supply voltage. The voltage on this input is scaled by 20:1 V/V and passed as VOUT telemetry to the 10-bit ADC. Internal measurements of this pin voltage are only accessible through PMBus.
14	FEEDBACK	AI (Power domain VDD reference to AGND)		Output feedback voltage. Resistor divider from LOAD PFET Drain Terminal to this pin determines if the LOAD voltage is above its minimum allowable operating voltage. If the voltage drops below the set value, PGOOD output will fall LOW. If FEEDBACK is under its threshold voltage, no action will be taken to affect the load FET gate driver.
41	MRST_B	I (Power domain VDD reference to DGND)	LOW	Active low master reset pin. When driven low, this pin turns off the external power FETs with a strong driver, clears any faults conditions, and places all internal logic states to their POR condition.
42	SLEEP_B	IPU (Power domain VDD reference to DGND)	LOW	Active low digital input. If SLEEP_B pin is driven LOW, SPSC is put in lowest power sleep mode, disabling some of the internal circuits, and both external power FETs will be disabled. Active analog and PMBUS circuits will be in low power mode. If this pin is set to high digital level, or left floating, SPSC device operates normally, actively controlling inrush and ORing power FETs, based on power good status, voltage monitoring and fault status.
43	PMB_EN	I (Power domain VDD reference to DGND)	HIGH	Active high PMBus Enable pin. If PMB_EN pin is connected to DGND, the PMBus circuitry is disabled and all PMBus oriented functions are blocked from affecting device operation. If PMB_EN pin is connected to VDD; it enables the PMBus and all associated functions to include the SMBus interface.
27	SMBDIO1	SMIO (Power domain VDD reference to DGND)	-	SMBus bi-directional data for side 1. Open drain, 5V tolerant.
28	SMBCLK1	SMI (Power domain VDD reference to DGND)	-	SMBus clock input for side 1. Open drain, 5V tolerant.
31	SMBALERT_B	SMO (Power domain VDD reference to DGND)	LOW	Active low SMBus alert output. Open drain, 5V tolerant.

Number	Name	Type	Active	Description
29	SMBDIO2	SMIO (Power domain VDD reference to DGND)	-	SMBus bi-directional data for side 2. Open drain, 5V tolerant.
30	SMBCLK2	SMI (Power domain VDD reference to DGND)	-	SMBus clock input for side 2. Open drain, 5V tolerant.
37	ADDR4	TERN (Power domain VDD reference to DGND)	-	Ternary address line 4 for device address ID; It has 3 state, connect to digital supply (VDD), DGND, or left floating.
36	ADDR3	TERN (Power domain VDD reference to DGND)	-	Ternary address line 3 for device address ID; It has 3 state, connect to digital supply (VDD), DGND, or left floating.
35	ADDR2	TERN (Power domain VDD reference to DGND)	-	Ternary address line 2 for device address ID; It has 3 state, connect to digital supply (VDD), DGND, or left floating.
34	ADDR1	TERN (Power domain VDD reference to DGND)	-	Ternary address line 1 for device address ID; It has 3 state, connect to digital supply (VDD), DGND, or left floating.
33	ADDR0	TERN (Power domain VDD reference to DGND)	-	Ternary address line 0 for device address ID; It has 3 state, connect to digital supply (VDD), DGND, or left floating.
38	PARITY	I (Power domain VDD reference to DGND)	-	Odd parity bit for equivalent terminal address defined by the 5-bit ternary decoder. This parity bit will be evaluated against the ternary set address when the SPSC exits reset. If parity is good and the address is not reserved, the SPSC SMBus will take the pin-programmed address. If parity is bad and/or the address is reserved, the SPSC SMBus address will take on the SMBus special "DEFAULT ADDRESS: 1100001b".

Note:

- 1) The SPSC is offered in a 47-Lead Flatpack providing an unpopulated pin gap between pins 13 and 14 to reduce the risk of shorting signals on the high-voltage domain to those on the low-voltage domain. The gap also helps ensure proper device orientation and reference for debug.

6 Functional Overview

The Smart Power Switch Controller (SPSC) provides a single device solution for controlling the gate of P-Channel Power MOSFETs while ensuring they remain within their specified Safe Operating Areas (SOAs). Combining adjustable current and voltage monitoring capability with flexible fault detection, isolation, and recovery, the SPSC integrates many of the critical functions required for power switching applications and often implemented with a number of discrete components. By integrating essential voltage and current monitoring the SPSC is able to reliably enable/disable the Power Switching MOSFET in accordance with detected fault conditions while providing telemetry to the power system manager. The following sections provide a brief summary of the major functional blocks making up the Smart Power Switch Controller.

6.1 Load Slew Rate Control and Inrush Current Limiting

The fundamental responsibility of the power switch controller is to turn a power bus isolating switch ON and OFF when commanded. To this end, the SPSC drives the gate of a P-Channel Power MOSFET (PFET) to establish/break the connection between the power line and a load. The SPSC monitors a variety of sources to determine if the LOAD switch should be ON or OFF.

When commanded to turn the switch ON, a Miller capacitor connected between the C_MILLER pin and PFET DRAIN (LOAD side) terminal will limit the inrush current which results when the input supply charges the load capacitance. By knowing the application overcurrent limit (I_{LIM}) or target peak inrush current, the C_MILLER value is calculated as follows:

$$\text{Rising VOUT: } C_{MILLER} = \left(\left(\frac{V_{GATE}-V_T}{R_{PD}} \right) + I_{BOOT} \right) * \frac{C_{LOAD}}{I_{LIM}} \quad \text{Falling VOUT: } C_{MILLER} = \left(\frac{V_T}{R_{PU}} - I_{BOOT} \right) * \frac{C_{LOAD}}{I_{LIM}}$$

Where V_T is the threshold voltage of the external PowerFET; V_{GATE} , R_{PD} , R_{PU} , and I_{BOOT} are gate driver characteristics specified in the electrical tables later in this datasheet. C_{LOAD} and I_{LIM} are application dependent.

Alternatively, if you know the rate at which you want to ramp the load voltage, you can calculate C_MILLER with the following equation:

$$\text{Rising VOUT: } C_{MILLER} = \left(\left(\frac{V_{GATE}-V_T}{R_{PD}} \right) + I_{BOOT} \right) * \frac{\Delta t}{\Delta V_{OUT}} \quad \text{Falling VOUT: } C_{MILLER} = \left(\frac{V_T}{R_{PU}} - I_{BOOT} \right) * \frac{\Delta t}{\Delta V_{OUT}}$$

Normally, the user would select a miller capacitor value that satisfies the desired ramp rate and current limit. Additionally, it is strongly recommended for the user to include a series 1.5k-ohm resistor between the C_MILLER pin and the C_MILLER capacitor. This resistor behaves as a current limiter for transient currents that may pass through the miller capacitor into the C_MILLER pin during a rapid, short circuit, eFusing event of the load.

6.2 OR FET Switch

In many applications, especially those that are spaceborne, redundancy and cross strapping systems are extremely important. The SPSC includes the ability to control a second, ORing, PFET to provide an ideal diode function. When enabled and as long as monitored voltage and currents are appropriate, the SPSC will activate the ORing FET. If a reverse current is detected the OR FET will be disabled.

The proper orientation of the ORing PFET is to have common source configuration with the Hot Swap PFET connecting the LOAD side supply (as shown in Figure 1-3-1). This ensures the highest input line power will reach the Source terminal on the LOAD switch, powering the SPSC while blocking unintentional power to the load and reverse powering a redundant, disabled, or lower voltage line supply.

If the application doesn't require ORing, the feature can be disabled by driving the EN_OR pin low and connecting RVRSP and AVDD to VIN.

6.3 Forward Current Monitoring

By installing a current sensing resistor in series with the input power line and the LOAD PFET Source terminal and by connecting a gain setting resistor from the SET pin to the input power line, the user can measure the line-to-load current

through the SPSC. Using the voltage drop across the sense resistor, the SPSC mirrors a proportional current to the IMON pin. With a 1.6KΩ resistor connected between the IMON pin and GND, a voltage proportional to the load current is produced.

To set the desired line-load current limit, the user selects a SET resistor that produces a 1mA current when the voltage drop across the sense resistor is reached at the current limit. In equation form, the SET resistor is determined by:

$$R_{set} = \frac{R_{sense} * I_{limit}}{1mA}$$

The line-load current limit state occurs when V_{IMON} exceeds 1.6V. This occurs when 1mA flows through the 1.6Kohm resistor from IMON pin to AGND.

The user can either measure the IMON voltage to determine the current through the LOAD FET using the equation:

$$I_{LOAD} = \frac{V_{IMON} * R_{SET}}{R_{IMON} * R_{SENSE}}$$

or by using the PMBus functionality to read the 10-bit digitized representation of the IMON voltage. The full-scale ADC voltage relating IMON is 2V with 1.6V corresponding to the user defined Overcurrent threshold.

6.4 Overcurrent Fault Protection

Internally, the Smart Power Switch Controller compares the IMON voltage to a reference voltage. When the voltage surpasses 1.6V, nominal, the C_FAULT pin begins to charge. The SPSC includes a "hiccup" feature that charges and discharges C_FAULT based on the over/under threshold voltage of IMON. The charge/discharge ratio is 20:1.

If the C_FAULT pin rises to the 1.6V threshold, the device declares an overcurrent fault condition. The SPSC responds by treating the LOAD PFET as an eFuse, switching it off to remove the voltage source from the load. Simultaneously, the CURR_LIM_B output is driven low.

Once a current fault is detected, the GATE_INR controlling the LOAD PFET's gate is latched OFF and a restart command must be received to restore power to the load. A restart command occurs when one of the device control pins (EN_B, EN_INR, MRST_B, SLEEP_B) is toggled.

Alternatively, the PMBus interface may be used to program the number of allowable restart attempts and the cool-down period before the restart is initiated.

Important Note: The PMBus command to re-start the SPSC from the LATCHED-OFF state by asserting PMBus OPERATION command bit 7 does not have an effect to de-latch the G_INR control and resume charging the load. A work around is to configure the SPSC in the re-triggered configuration with a preferred number of re-start cycles and a long enough cool-down delay to allow the host controller to manually toggle the START bit (Operation bit 7). This approach will prevent the SPSC from immediately latching the G_INR control OFF and allowing the PMBus control to take effect.

6.5 Short Circuit Break Fault Protection

While the Overcurrent Fault Protection allows the system to trigger a fault based on an arbitrarily long elevated current condition, the Short Circuit Fault Protection circuitry monitors for a significantly higher current condition and rapidly opens (eFuses) the circuit by disabling the LOAD PFET when the user defined threshold is crossed.

With a resistor (R_{FAST}) installed between the SENSEP pin and the bus power side of the current sense resistor (R_{SENSE}), the SPSC's Short-Circuit Fault comparator evaluates the voltage drop across the sense resistor and R_{FAST} . As the load current increases, the voltage drop across R_{SENSE} increases. When the voltage drop across R_{SENSE} becomes large enough, the Short Circuit Fault comparator declares a fault condition; disabling the LOAD PFET within 500ns, typical.

Important Note: Once a short circuit fault is detected, the GATE_INR controlling the LOAD PFET's gate is latched OFF and a restart command must be received to restore power to the load. A restart command only occurs when one of the device control pins (EN_B, EN_INR, MRST_B, SLEEP_B) is toggled. PMBus control to restart from short circuit faults is not an option.

6.6 Voltage Fault Protection

By implementing a voltage divider between the input line voltage and the OVLO, UVLO pins and between the VOUT and FEEDBACK pins, the user can set thresholds for over-voltage (OVLO) and under-voltage (UVLO) faults on the input line voltage and for under-voltage (FEEDBACK) on the load side.

In the event of a fault on either UVLO or OVLO the G_INR pin is driven to AVDD to disable the load PFET, PGOOD is driven low, and fault status information is updated in the PMBus fault response registers if PMBus functionality is enabled. A fault on FEEDBACK only affects the PGOOD output and corresponding PMBus status information.

6.7 Voltage Monitoring

When using the SPSC's PMBus functionality, the voltage on pins VIN and VOUT are digitized to 10-bit with 40.00V being the full-scale voltage range. PMbus commands READ_VIN and READ_VOUT are used by power management host to obtain this telemetry along with the monitored current.

6.8 PMBus

To get the maximum functionality from the SPSC, the PMBus feature must be utilized. Through the PMBus interface, a remote host controller can

- enable/disable the device
- configure Latched, Retrigger, and Pulsed modes
- obtain status on all fault conditions
- set retrigger and pulse delays
- defined retrigger count limits
- read 10-bit digitized representation of VIN, VLOAD, and IDS (aka IMON)

For spaceborne applications, system fault tolerance is often managed through redundancy. For this purpose, the SPSC provides a redundant SMBus port to access the common PMBus functions. The redundant SMBus implementation is coherent; allowing simultaneous PMBus access from the primary and secondary SMBus ports.

For applications that do not wish to use PMBus, the SPSC provides a PMB_EN control signal to disable the PMBus functionality. The SPSC can perform bus switching, monitoring, and protection tasks without any PMBus involvement.

7 Absolute Maximum Ratings ^(1, 2)

Table 7-1: Absolute Maximum Ratings

Symbol	Parameter	Min	Max	Units
V _{HV_TECH} ^(3, 4)	High Voltage Technology Capability	---	+56	V
AVDD ⁽⁵⁾	Positive High Voltage Supply – Continuous Operation	-0.5	+40	V
HVIO1 ⁽⁵⁾	High Voltage IO Group 1: VIN & VOUT	-0.5	+40	V
HVIO2	High Voltage IO Group 2: GATE_INR, GATE_OR, C_MILLER	VZ13P5_HS - 0.5	AVDD + 0.5	V
HVIO3	High Voltage IO Group 3: RVRSP, SET, SENSEP, SENSEM	VZ5_HS - 0.5	AVDD + 0.5	V
VDD	Positive Low Voltage Supply	-0.5	+7.2	V
LVIO	Low Voltage Digital and Analog I/O within 3.3V Domain	-0.5	VDD + 0.5	V
IO _{DC}	Average Steady State IO Current	-10	+10	mA
P _D ⁽⁶⁾	Power Dissipation Permitted @ T _C =125°C	---	3.33	W
T _J	Junction Temperature		+175	°C
θ _{JC}	Thermal Resistance, Junction-to-Case	---	15	°C/W
T _{STG}	Storage Temperature	-65	+150	°C
ESD _{HBM} ⁽⁷⁾	ESD Protection all Pins	---	2000	V
ESD _{HBM_SMBUS} ⁽⁷⁾	Extended ESD Protection SMBus IO only	---	4000	V

Note:

- 1) Stresses outside the listed absolute maximum ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond limits indicated in the operational sections of this specification are not recommended. Exposure to absolute maximum rating conditions for extended periods may affect device reliability and performance.
- 2) All absolute voltages referenced to AGND.
- 3) Technology voltage capability is provided to facilitate system derating requirements. This is not a recommended operating threshold.
- 4) Device compatible with CS106 EM Conducted Susceptibility testing.
- 5) This absolute maximum rating is limited by ground referenced ESD clamp, not by technology capability rating.
- 6) Per MIL-STD-883, method 1012, section 3.4.1, PD=(TJ(max)-TC(max))/θJC.
- 7) Per MIL-STD-883, method 3015.

8 Operational Environment

Table 8-1: Operational Environment

Symbol	Parameter	Limit	Units
TID ⁽¹⁾	Total Ionizing Dose	100	krad(Si)
SEL ⁽²⁾	Single Event Latchup Immunity	≤ 100	MeV-cm ² /mg
SEGR ^(3, 4)	Single Event Gate Rupture Immunity	≤ 60	MeV-cm ² /mg
SEB ⁽³⁾	Single Event Burnout Immunity	≤ 100	MeV-cm ² /mg
SEU ⁽⁵⁾	Single Event Upset Immune	≤ 40	MeV-cm ² /mg
SET ⁽⁵⁾	Single Event Transient Immune	≤ 80	MeV-cm ² /mg

Note:

- 1) For devices procured with a total ionizing dose tolerance guarantee, post-irradiation performance is guaranteed at 25°C per MIL-STD-883 Method 1019, Condition A at an effective dose rate of 1 rad(Si)/sec up to maximum TID level procured.
- 2) Performed at VDD = 3.6V & AVDD = 36V at 125°C.
- 3) Performed at VDD = 3.6V & AVDD = 36V at 25°C.
- 4) Performed with highest energy ion selected at normal incidence.
- 5) Performed at VDD = 3.0V & AVDD = 36V at 25°C.

9 Recommended Operating Conditions ⁽¹⁾

Table 9-1: Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
T _c	Case Operating Temperature Range	-55	+125	°C
AVDD ⁽²⁾	High Voltage Power Supply	+8V	+36V	V
VDD	Low Voltage Digital and Analog Power Supply	+3.0	+3.6	V
HVIO1	VIN & VOUT Voltage Range	0	AVDD+1	V
HVIO2	GATE_OR, GATE_INR, & C_MILLER Voltage Range	VZ13P5_HSx ⁽³⁾	AVDD+0.5	V
HVIO3	RVRSP, SET, SENSEM & SENSEP Voltage Range	AVDD-0.5	AVDD+0.5	V
LVIO	Low Voltage Digital and Analog I/O within 3.3V Domain	0	VDD	V
tRF _{DIG}	Digital Input Rise & Fall Time (20%-80% of VDD) Pins: MRST_B, SLEEP_B, PMB_EN, VGS_DRV, PARITY		50	ns
AGND ⁽⁴⁾	Analog Ground Return	0		V
DGND ⁽⁴⁾	Digital Ground Return	AGND-10	AGND+10	mV

Note:

- 1) AVDD and VDD are referenced to AGND.
- 2) 36V maximum continuous operation already accounts for 65% de-rating from the 56V technology capability.
- 3) Refer to Table 10-1 for potential VZ13P5_HSx voltages.
- 4) AGND and DGND shall be shorted together at a common point on the user's PCB.

10 Electrical Characteristics ⁽¹⁾

(AVDD = 8V to 36V, VDD = 3.3V ± 0.3V, -55°C < T_c < +125°C);Unless otherwise noted, T_c is per the temperature range ordered.

Table 10-1: Power Supply and Reference Characteristics

Unless otherwise noted, the following parameters are tested with VDD = 3.0V

Symbol	Parameter	Conditions	Min	Max	Units
AVDD	High Voltage Power Supply	AVDD = 8V to 36V; Referenced to AGND	+8V	+36	V
CBYP _{AVDD}	AVDD Bypass Capacitor	Connect between AVDD & AGND, 1 each per AVDD pin	0.1		µF
VZ5_HS	High Voltage Logic Reference	AVDD ≥ 8V	AVDD -5.5	AVDD -4	V
CBYP _{VZ5_HS}	VZ5_HS Bypass Capacitor	Connect between AVDD & VZ5_HS, 1 each per AVDD pin	0.1		µF
VZ13P5_HS1	High Voltage Gate Driver Reference	AVDD ≥ 15.5V; VGS_DRV = High	AVDD -15	AVDD -12	V
VZ13P5_HS2	High Voltage Gate Driver Reference	AVDD ≥ 10.5V; VGS_DRV = Low	AVDD -10	AVDD -7	V
VZ13P5_HS3 ⁽²⁾	High Voltage Gate Driver Reference	AVDD = 8V to 10.5V; VGS_DRV=H or L		AGND	V
CBYP _{VZ13P5_HS} ⁽³⁾	VZ13P5_HS Bypass Capacitor	Connect between AVDD & VZ13P5_HS, 1 each per AVDD pin	1		µF
VZ5_LS	Low Voltage Internal Regulator for Analog References & Biases	AVDD ≥ 8V Referenced to AGND	+4.0	+5.5	V
CBYP _{VZ5_LS}	VZ5_LS Bypass Capacitor	Connect between VZ5_LS & AGND	0.1		µF
VDD	Low Voltage Power Supply	Referenced to AGND	+3	+3.6	V
CBYP _{VDD}	VDD Bypass Capacitor	Connect one each bypass cap from VDD to AGND and VDD to DGND	0.1		µF

Note:

- 1) All voltages referenced to DGND or AGND as appropriate.
- 2) For operation where 8V ≤ AVDD ≤ 10.5V, user should short VZ13P5_HS to AGND to achieve maximum G_INR & G_OR potential.
- 3) CBYP_{VZ13P5_HS} must be at least 4 times larger than capacitance added to the C_MILLER pin.

Table 10-2: Power Supply Current Consumption Characteristics

Symbol	Parameter	Conditions	Min	Max	Units
Single Supply Current Consumption					
Test conditions unless otherwise noted:					
AI _{AVDD1_SNGL}	Active High Voltage Supply Current			2.8	mA
QI _{AVDD_SNGL}	Quiescent High Voltage Supply Current	EN_B=MRST_B=SLEEP_B=High; EN_INR=EN_OR=PMB_EN=Low; VOUT=Float; No PMBus Activity		2.7	mA
SI _{AVDD_SNGL}	Sleep High Voltage Supply Current	SLEEP_B=Low; VOUT=Float		1.4	mA
Dual Supply Current Consumption					
Test conditions unless otherwise noted:					
AI _{AVDD1_DUAL}	Active High Voltage Supply Current			1.7	mA
AI _{VDD1_DUAL}	Active Low Voltage Supply Current			1.7	mA
QI _{AVDD_DUAL}	Quiescent High Voltage Supply Current	EN_B=MRST_B=SLEEP_B=High; EN_INR=EN_OR=PMB_EN=Low; VOUT=Float; No PMBus Activity		1.6	mA
QI _{VDD_DUAL}	Quiescent Low Voltage Supply Current	SLEEP_B=Low; VOUT=Float		1.6	mA
SI _{AVDD_DUAL}	Sleep High Voltage Supply Current			1	mA
SI _{VDD_DUAL}	Sleep Low Voltage Supply Current			250	µA

Note:

- 1) All voltages referenced to DGND or AGND as appropriate.

Table 10-3: Low Voltage Digital I/O Electrical Characteristics

Unless otherwise noted, the following parameters are tested with AVDD=8V and VDD = 3.0V & 3.6V.

Symbol	Parameter	Conditions	Min	Max	Units
Standard Digital Inputs (Referenced to DGND)					
PARITY, VGS_DRV, MRST_B, PMB_EN					
V _{IH}	High Level Input Voltage	For VGS_DRV only AVDD = 36V	0.7* VDD		V
V _{IL}	Low Level Input Voltage	For VGS_DRV only AVDD = 36V		0.3* VDD	V
I _{IL}	Input Leakage Current	VDD=3.6V INPUT = 0V or VDD	-1	1	µA
C _{IN} ⁽¹⁾	Input Capacitance			15	pF
Standard Digital Inputs with Pull-Ups and (Referenced to DGND)					
SLEEP_B					
V _{IH}	High Level Input Voltage		0.7* VDD		V
V _{IL}	Low Level Input Voltage			0.3* VDD	V
I _{IL_PU}	Input Leakage Current Pull-Up	VDD=3.6V; INPUT=0V	-20	-5	µA
I _{IL}	Input Leakage Current	VDD=3.6V; INPUT= VDD		2	µA
C _{IN} ⁽¹⁾	Input Capacitance			15	pF
5V Digital Inputs (Referenced to DGND)					
INT_VDD_DIS					
V _{IH}	High Level Input Voltage		0.7* VZ5_LS		V
V _{IL}	Low Level Input Voltage			0.3* VZ5_LS	V
I _{IL}	Input Leakage Current	VZ5_LS=5V; VDD=3.6V; INPUT = 0V or VZ5_LS	-1	1	µA
C _{IN} ⁽¹⁾	Input Capacitance			15	pF
Ternary Inputs (Referenced to DGND)					
ADDR0-ADDR4					
V _{IH_TERN}	High Level Input Voltage		VDD -0.3		V
V _{IM_TERN} ⁽⁴⁾	Mid Level Input Voltage		VDD/2 -0.3	VDD/2 +0.3	V
V _{IL_TERN}	Low Level Input Voltage			0.6	V
I _{ILL} ⁽³⁾	Low Level Input Leakage Current While Latching ADDR4-ADDR0	MRST_B=Low; VDD=3.6V; Pin under test: VADDR[x]=0V;	-100	-20	µA
I _{ILM} ^(3,4)	Mid Level Input Leakage Current While Latching ADDR4-ADDR0	MRST_B=Low; VDD=3.6V; Pin under test: VADDR[x]=VDD÷2;	3	40	µA
I _{ILH} ⁽³⁾	High Level Input Leakage Current While Latching ADDR4-ADDR0	MRST_B=Low; VDD=3.6V; Pin under test: VADDR[x]=3.6V;	20	100	µA
C _{IN} ⁽¹⁾	Input Capacitance			15	pF
Open Drain Digital Outputs (Referenced to DGND)					
PGOOD, CURR_LIM_B					
V _{OL}	Low Level Output Voltage	ISINK = 4mA		0.4	V
I _{SC} ⁽²⁾	Output Short Circuit Current	VDD=3.6V; OUTPUT= VDD	25	50	mA
I _{OZ}	Output Leakage Current	VDD=3.6V; OUTPUT = 0 or VDD;	-2	2	µA
C _{OUT} ⁽¹⁾	Input Capacitance			15	pF

Symbol	Parameter	Conditions	Min	Max	Units
SMBus I/O with Schmitt Trigger Inputs (Referenced to DGND)					
SMBCLK1, SMBDIO1, SMBCLK2, SMBDIO2, SMBALERT_B					
V _{T+}	Positive Going Input Threshold Voltage			1.89	V
V _{T-}	Negative Going Input Threshold Voltage		0.8		V
V _H	Threshold Voltage Hysteresis		80	550	mV
V _{OL}	Low Level Output Voltage	ISINK = 12mA		0.4	V
I _{SC1} ⁽²⁾	Output Short Circuit Current	VDD=3.6V; OUTPUT=VDD	65	125	mA
I _{OZ}	Output Leakage Current	VDD=3.6V; OUTPUT = 0 or VDD;	-2	2	µA
C _{IO} ⁽¹⁾	Input Capacitance			15	pF
C _{SMB_LOAD} ⁽²⁾	Total SMBus Load Capacitance			800	pF

Note:

- 1) Guaranteed by characterization; not tested.
- 2) Provided as applications information only, neither guaranteed nor tested.
- 3) Guaranteed by design, not tested.
- 4) For ADDR4, only, the mid point ternary specifications do not apply because only a HIGH and LOW state are required for the address decoding logic.

Table 10-4: Low Voltage Analog I/O Electrical Characteristics

Unless otherwise noted, the following parameters are tested with AVDD=8V and VDD = 3.0V & 3.6V.

Symbol	Parameter	Conditions	Min	Max	Units	
Current Monitor and Overcurrent Analog Comparator (referenced to AGND)						
IMON						
V _{IMON_RANGE} ⁽⁴⁾	IMON Operating Voltage Range		0	VDD	V	
V _{IMON_CL}	IMON Voltage Threshold at Current Limit	Detect by ΔV on C_FAULT Pin	1.6		V	
V _{IMON_TOL} ⁽¹⁾	IMON Voltage Threshold Tolerance		-60	60	mV	
I _{IMON_CL} ⁽⁴⁾	IMON Current at Current Limit	V _{IMON} = 1.6V	-1		mA	
I _{IMON_TOL} ^(2, 4)	IMON Current Tolerance at Current Limit	V _{T_CL} = 25mV	± 1.5		%	
		V _{T_CL} = 50mV	± 2			
		V _{T_CL} = 100mV	± 2.5			
I _{OZ}	Output Leakage Current	VDD=3.6V; V _{AVDD} =V _{SENSE} OUTPUT = 0V or VDD	-2	2	μA	
R _{IMON} ⁽⁵⁾	IMON Shunt Resistor	Recommended 1% Tolerance	1.6		k Ω	
C _{IMON} ⁽⁵⁾	IMON Low Pass Filter Capacitance	$45kHz LPF \approx \frac{1}{2\pi * R_{IMON} * C_{IMON}}$	2.2		nF	
C _{IN} ⁽³⁾	Pin Capacitance			25	pF	
Analog Comparator Inputs with Hysteresis and (referenced to AGND)						
EN_B, EN_INR, EN_OR, UVLO, OVLO, FEEDBACK						
V _{T+}	Positive Going Input Threshold Voltage			1.73	V	
V _{T-}	Negative Going Input Threshold Voltage		1.43		V	
V _H	Threshold Voltage Hysteresis		35	100	mV	
I _{IL}	Input Leakage Current	VDD=3.6V 0V \leq INPUT \leq VDD;	-2	2	μA	
C _{IN} ⁽³⁾	Pin Capacitance			15	pF	
Adjustable Fault Timer (referenced to AGND)						
C_FAULT						
V _{T_FAULT}	Nominal Input Voltage Threshold	Detect by change on Curr_Lim_B	1.6		V	
V _{T_TOL}	Input Threshold Tolerance		-45	45	mV	
I _{CHARGE}	Charging Current		-125	-90	μA	
I _{DISCHARGE}	Discharging Current		4.5	6.0	μA	
C _{FAULT_INT} ⁽³⁾	Internal Pin Capacitance			30	pF	
Adjustable Oscillator (referenced to DGND)						
C_TIMER						
V _{T+}	Positive Going Input Threshold Voltage			1.45	V	
V _{T-}	Negative Going Input Threshold Voltage		0.6		V	
V _H	Threshold Voltage Hysteresis		225	450	mV	
I _{CHARGE}	Charging Current		-6	-4.5	μA	
I _{DISCHARGE}	Discharging Current		4.5	6	μA	
F _{C_TIMER} ⁽⁸⁾	C_TIMER Frequency	C_TIMER pin capacitance \sim 10nF	600	1000	Hz	
DC _{C_TIMER}	C_TIMER Duty Cycle	C_TIMER pin capacitance \sim 10nF	45	55	%	
C _{TIMER_INT} ⁽³⁾	Internal Pin Capacitance			30	pF	
Analog Comparator Error Sources						
EN_B, EN_INR, EN_OR, UVLO, OVLO, FEEDBACK, IMON, C_FAULT, C_TIMER						
V _{OS} ^(4,6)	Comparator Offset Voltage	Threshold difference between comparator positive and negative terminals	-10	+10	mV	
V _{1P6REF_TOL} ^(4,6)	1.6V Reference Voltage Tolerance		-40	+40	mV	
Noise ^(4,6)	Peak-Peak Noise Voltage on AGND		-15	15	mV	

Symbol	Parameter	Conditions	Min	Max	Units
Bias Current Generator (reference to AGND)					
I _{REF}	R _{REF} ⁽⁵⁾	Required I _{REF} Load Resistor	Connected between I _{REF} and AGND	24.9	kΩ
R _{REF_TOL} ⁽⁴⁾	R _{REF_TOL} ⁽⁴⁾	Recommended I _{REF} Load Resistor Tolerance		± 1	%
V _{REF}	V _{REF}	Voltage at I _{REF} Pin		0.925	1.075
C _{REF} ^(3,7)	C _{REF} ^(3,7)	I _{REF} Pin External Load Capacitance		20	pF

Note:

- 1) V_{IMON_TOL} only includes comparator error sources that are specific to the device: Offset Voltage, Reference Accuracy, and Noise. Effective current limit detection tolerance will increase in a Root Sum Square (RSS) fashion with I_{IMON_TOL} and user dependent error sources such as R_{IMON}, R_{SENSE} and R_{SET} tolerances.
- 2) I_{IMON_TOL} is a function of current sense amplifier error sources (Amplifier Offset Voltage and Gain Error) at the target current limit.
- 3) Guaranteed by characterization; not tested.
- 4) Provided as applications information only, neither guaranteed nor tested.
- 5) Functionally tested only.
- 6) Effective comparator threshold tolerance can be approximated using root sum square of error sources

(e.g. $\sqrt{\%V_{OS}^2 + \%V1P6_{REF_TOL}^2 + \%Noise^2 + RSENSE_{TOL}^2 + RSET_{TOL}^2 + RIMON_{TOL}^2}$)

- 7) An external capacitor on the I_{REF} pin is not recommended for normal operation. A probe load up to the specified maximum capacitance is allowed for test and debug purposes.
- 8) The frequency of the adjustable C_TIMER clock is set by connecting a user selectable capacitor from the C_TIMER pin to DGND. Oscillator frequency can be calculated with the following equations. Refer to Section 12. Typical Performance Characteristics for more detailed data to populate the variables in these equations.

$$T_{C_TIMER} = \frac{2 * (V_{T+} - V_{T-}) * C_{TIMER}}{mean(I_{CHARGE}, I_{DISCHARGE})} - 1\mu s; F_{C_TIMER} = \frac{1}{T_{C_TIMER}}$$

Table 10-5: High Voltage Analog I/O Electrical Characteristics

Unless otherwise noted, the following parameters are tested with AVDD = 8V and VDD = 3.0V

Symbol	Parameter	Conditions	Min	Max	Units		
PMOS Power FET Gate Driver (referenced to AVDD)							
G_OR, G_INR							
V _{OFF}	Power FET Gate OFF Voltage		AVDD - 0.1	AVDD +0.1	V		
V _{ON} ⁽¹⁾	Power FET Gate ON Voltage below AVDD	VGS_DRV = HIGH @AVDD=36V	12	15	V		
		VGS_DRV = LOW @AVDD=36V	7.5	10	V		
R _{PU_FAST}	Fast Gate Driver Pull-Up Resistance	AVDD = 36V	3	12	Ω		
R _{PU_NORM}	Normal Gate Driver Pull-Up Resistance	AVDD = 36V	20K	42K	Ω		
R _{PD_INR}	INR Gate Driver Pull-Down Resistance	AVDD = 36V	140K	260K	Ω		
R _{PD_OR}	OR Gate Driver Pull-Down Resistance	AVDD = 36V	70K	130K	Ω		
I _{BOOT}	Driver Pull-down Bootstrap Current	AVDD = 36V	8	30	μA		
C _{OUT} ⁽²⁾	Pin Capacitance			50	pF		
Miller Capacitance (referenced to AVDD)							
C_Miller							
V _{FS} ⁽³⁾	Full-Scale Voltage Range	AVDD = 36V	AVDD - 15	AVDD	V		
R _{PU} ^(3,4)	Charging/Pull-Up Resistance	MRST_B=LOW	3	12	Ω		
		During Short Circuit Break	3	12			
		During Normal Gate Driver Disable	20K	42K			
R _{PD} ⁽³⁾	Discharging/Pull-Down Resistance		140K	260K	Ω		
C _{IN} ⁽²⁾	Pin Capacitance			20	pF		
Input and Output Bus Voltage Monitor (referenced to AGND)							
VIN, VOUT							
V _{FS} ⁽⁵⁾	Full-Scale Voltage Range		0	40	V		
R _{IN} ⁽³⁾	Input Resistance		5	10	MΩ		
I _{IN}	Input Current	AVDD=VIN=VOUT=36V	3.65	7.25	μA		
C _{IN} ⁽²⁾	Pin Capacitance			20	pF		
Chopper Stabilized High-Side Current Sense Amplifier (referenced to VZ5_HS)							
SET (-), SENSEM (+) (Inputs); IMON (Output)							
V _{T_CL}	Current Limit Threshold (V _{AVDD} -V _{SENSEM})	G_INR=LOW (≈ VZ13P5_HS) EN_INR=HIGH EN_B=LOW	R _{SET} = 25Ω	22	30	mV	
			R _{SET} = 50Ω	45	58		
			R _{SET} = 100Ω	90	110		
R _{SET_TOL} ⁽³⁾	Recommended R _{SET} Tolerance		±0.1		%		
V _{OS} ⁽³⁾	Input Offset Voltage	(V _{AVDD} -V _{SENSEM}) < 5mV	-4.8	4.8	mV		
			(V _{AVDD} -V _{SENSEM}) > 5mV	-200	200	μV	
G _{ERR} ⁽³⁾	Gain Error at IMON	@ 20% of V _{T_CL}	V _{T_CL} = 25mV	± 6.9		%	
			V _{T_CL} = 50mV	± 3.4			
			V _{T_CL} = 100mV	± 1.7			
		@ 100% of V _{T_CL}	V _{T_CL} = 25mV	± 0.6			
			V _{T_CL} = 50mV	± 1.1			
			V _{T_CL} = 100mV	± 2.2			
VCMR ⁽³⁾	Common Mode Voltage Range		AVDD - 0.5	AVDD + 0.5	V		
CMRR ⁽³⁾	Common Mode Rejection Ratio			-75	dB		
PSRR ⁽³⁾	Power Supply Rejection Ratio			-60	dB		
C _{IN} ⁽²⁾	Internal Pin Capacitance (SET and SENSEM pins)			35	pF		

Symbol	Parameter	Conditions	Min	Max	Units
Fast Short Circuit and Reverse Current Detect Comparator (referenced to VZ5_HS) SENSEP (+), SENSEM (-) of Short Circuit Comparator and RVRSP (+), VIN (-) of Reverse Current Comparator					
V _{T_SC}	Short Circuit Fault Threshold (V _{AVDD} -V _{SENSEM}) $R_{FAST} * I_{BIAS} = R_{SENSE} * I_{SC}$	R _{FAST} = 875Ω	28	44	mV
		R _{FAST} = 5kΩ	185	230	
		R _{FAST} = 10kΩ	370	460	
R _{FAST} ⁽⁵⁾	Recommended Short Circuit Threshold Setting Resistor	Recommended Tolerance ±0.1%	0.875	10	kΩ
V _{T_RVRS}	Reverse Current Fault Threshold (V _{AVDD} -V _{VIN}) $R_{RVRS} * I_{BIAS} = R_{FET_RDSON} * I_{RVRS}$	R _{RVRS} = 2.5kΩ	85	115	mV
		R _{RVRS} = 5kΩ	185	230	
		R _{RVRS} = 10kΩ	370	460	
R _{RVRS} ⁽⁵⁾	Recommended Reverse Current Fault Threshold Setting Resistor	Recommended Tolerance ±0.1%	2.5	10	kΩ
V _{OS} ⁽³⁾	Input Offset Voltage		-5	5	mV
I _{BIAS}	SENSEP and RVRSP Input Bias Current		40		μA
I _{BIAS_TOL}	SENSEP and RVRSP Input Bias Current Tolerance		-4	+6	μA
VCMR ⁽³⁾	Common Mode Voltage Range		VZ5_HS + 1.5	AVDD + 0.1	V
CMRR ⁽³⁾	Common Mode Rejection Ratio			-60	dB
PSRR ⁽³⁾	Power Supply Rejection Ratio			-60	dB
C _{IN} ⁽²⁾	Internal Pin Capacitance (SENSEP & RVRSP pins)			35	pF

Note:

- 1) The G_INR and G_OR pins drive the Gate terminal of externally supply P-Channel MOSFETs. Their turn-on voltages are below the AVDD rail and limited by the voltage of the VZ13P5_HS pin and the state of VGS_DRV.
- 2) Guaranteed by characterization; not tested.
- 3) Provided as applications information only, neither guaranteed nor tested.
- 4) The charging (Pull-Up) resistance on the C_MILLER pin depends on the condition commanding the pin to AVDD. During reset (Power-on-reset, and manual reset) and short circuit detection, C_MILLER is charged with an independent pull-up from standard gate driver controls. All other commanded (e.g. EN_INR, EN_OR, etc) and fault driven (e.g. UVLO, Overcurrent, etc.) disabling of G_INR rely on the normal G_INR pull-up resistance to charge C_MILLER to AVDD.
- 5) Functionally tested only.

Table 10-6: Three Channel Analog-to-Digital Converter Characteristics

Unless otherwise noted, the following parameters are tested with AVDD = 40V and VDD = 3.0V & 3.6V

Symbol	Parameter	Conditions	Min	Max	Units
ADC with 3-Channel Analog Mux Functional Characteristics (referenced to AGND)					
ADC _{RES} ⁽³⁾	ADC Resolution		10		Bits
ADC _{FSV} ⁽⁴⁾	ADC Full-Scale Voltage	Can be approximated by $V_{REF} * 2$	1.85	2.15	V
ADC _{LSB} ⁽⁴⁾	ADC Least Significant Bit		1.81	2.1	mV
ADC _{ACQ_CH} ⁽¹⁾	ADC Channel Acquisition Time	Time to sample and convert any of VOUT, VIN, or IMON	5		ms/s
ADC _{RR_CYCLE} ⁽¹⁾	ADC Round Robin Cycle Time	Time to Convert and Acquire VOUT, VIN, and IMON	65	131	ms/cyc
INL ⁽⁴⁾	Integral Non-Linearity	20% FSV ≤ ADC Input ≤ 80% FSV	±5		LSB
DNL ⁽⁴⁾	Differential Non-Linearity	20% FSV ≤ ADC Input ≤ 80% FSV	±0.95		LSB
ERR _{OFFSET} ⁽⁴⁾	ADC Offset Error		±20		LSB
ERR _{GAIN}	ADC Gain Error	Calculated by: $E_{GAIN} = \frac{V_{FSV} - V_{OFFSET}}{V_{LSB}} - (2^{10} - 2)$	±40		LSB
CMRR ⁽¹⁾	Common Mode Rejection Ratio		-80		dB
PSRR ⁽¹⁾	Power Supply Rejection Ratio	ΔVDD = 300mV	-70		dB
R _{CHNL} ⁽¹⁾	Analog Mux Channel Resistance	0.0V ≤ ADC Input ≤ 2.0V	218	4640	Ω
CH _{ISO} ⁽¹⁾	Channel-to-Channel Isolation	Δ Aggressor Channel = 1V	-80		dB
ADC Telemetry Input Characteristics (referenced to AGND)					
VIN, VOUT, IMON (Inputs); Results Obtained from PMBus Commands (88h, 8Bh, 8Ch)					
VIN _{FSV} ⁽⁴⁾	VIN Full-Scale Voltage		40		V
VIN _{LSB} ⁽⁴⁾	VIN Least Significant Bit	$VIN_{LSB} = \frac{ADC_{FSV}}{1024} * 20$	36.13	41.99	mV/bit
VIN _{GAIN} ⁽¹⁾	VIN Gain		0.05		V/V
VIN _{INACCURACY} ^(1,2,4)	VIN Inaccuracy at ADC Output	Measured at Full-Scale Voltage	±7.5		%
VOUT _{FSV} ⁽⁴⁾	VOUT Full-Scale Voltage		40		V
VOUT _{LSB} ⁽⁴⁾	VOUT Least Significant Bit	$VOUT_{LSB} = \frac{ADC_{FSV}}{1024} * 20$	36.13	41.99	mV/bit
VOUT _{GAIN} ⁽¹⁾	VOUT Gain		0.05		V/V
VOUT _{INACCURACY} ^(1,2,4)	VOUT Inaccuracy at ADC Output	Measured at Full-Scale Voltage	±7.5		%
IMON _{LSB} ⁽¹⁾	IMON Least Significant Bit	$IMON_{LSB} = \frac{R_{SET}}{R_{SENSE}} * \frac{ADC_{FS}}{R_{IMON}} * \frac{1}{1024}$	Derived		mA/bit
IMON _{GAIN} ⁽¹⁾	IMON Gain	V _{T_CL} = 25mV	64		V/V
		V _{T_CL} = 50mV	32		V/V
		V _{T_CL} = 100mV	16		V/V
IMON _{INACCURACY} ^(1,2)	IMON Inaccuracy at ADC Output	@ 20% of V _{T_CL}	V _{T_CL} = 25mV	± 8.3	%
			V _{T_CL} = 50mV	± 5.7	
			V _{T_CL} = 100mV	± 4.82	
		@ 100% of V _{T_CL}	V _{T_CL} = 25mV	± 2.82	
			V _{T_CL} = 50mV	± 2.9	
			V _{T_CL} = 100mV	± 3.44	

Note:

- 1) Provided as applications information only, neither guaranteed nor tested.
- 2) Accuracy at the ADC output includes all device specific errors sources (e.g. gain errors, offsets, noise, etc.). It does not include the contribution of externally selected user components like resistor tolerances.
- 3) Functionally tested only.
- 4) Calculated from best fit least mean squares method.

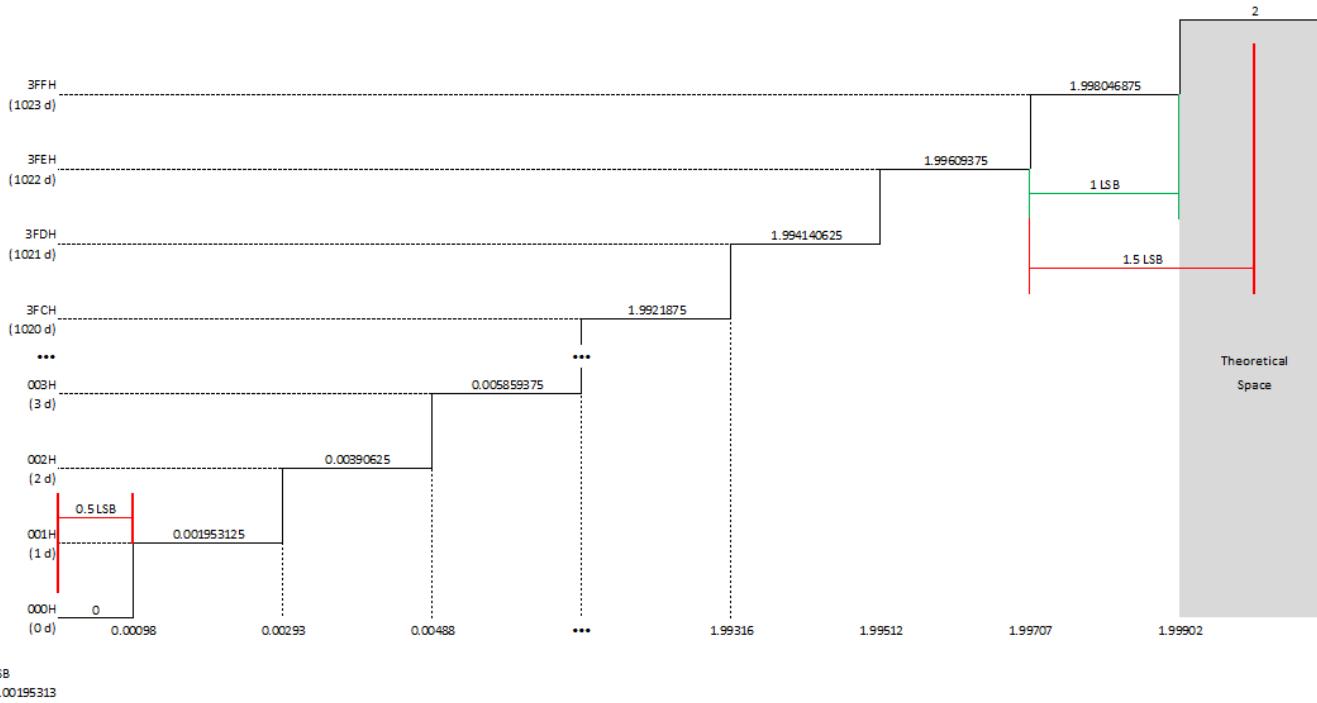


Figure 10-1. ADC Ideal Transfer Function

11 Timing Characteristics

(AVDD = 8V to 36V, VDD = 3.3V ± 0.3V, -55°C < T_C < +125°C);

Unless otherwise noted, T_C is per the temperature range ordered.

Table 11-1: Current Limit Response Timing

Unless otherwise noted, the following parameters are tested with AVDD = 8V & 36V and VDD = 3.0V & 3.6V

Symbol	Parameter	Condition	Min	Max	Units
$R_{IMON} = 1.6k\Omega$; $C_{IMON} = 2.2nF$; C_FAULT = Open (~30pF); EN_B = LOW; MRST_B = SLEEP_B = EN_INR = HIGH; PMB_EN = EN_OR = HIGH or LOW;					
t_{CL2INR} ⁽¹⁾	Current Limit Detection to G_INR HIGH	VGS_DRV = HIGH; ($V_{AVDD}-V_{SENSEM}$) transition from 0V to $1.25*V_{T_{CL}}$		38	μs
$t_{CL2IMON}$	Current Limit Detection to IMON HIGH	($V_{AVDD}-V_{SENSEM}$) transition from 0V to $1.25*V_{T_{CL}}$		22	μs
$t_{IMON2FLT}$	IMON HIGH to C_FAULT HIGH	AVDD = 8V		18	μs
$t_{FLT2CLB}$	C_FAULT HIGH to CURR_LIM_B LOW			10	μs
$t_{FLT2OFF}$ ⁽¹⁾	C_FAULT HIGH to G_INR HIGH	VGS_DRV = HIGH ⁽²⁾		15	μs
		VGS_DRV = LOW		12	μs
$t_{MRBL2FLT}$	MRST_B LOW to C_FAULT LOW	AVDD = 8V		4	μs
t_{CLB_RESET}	CURR_LIM_B Reset Delay	AVDD = 8V; $R_{PULL-UP}=1k\Omega$; $C_{LOAD}=50pF$		5	μs

Note:

1) Test performed without contribution of Miller Capacitance or Gate Charge on pin under test.

2) Guaranteed by design, not tested

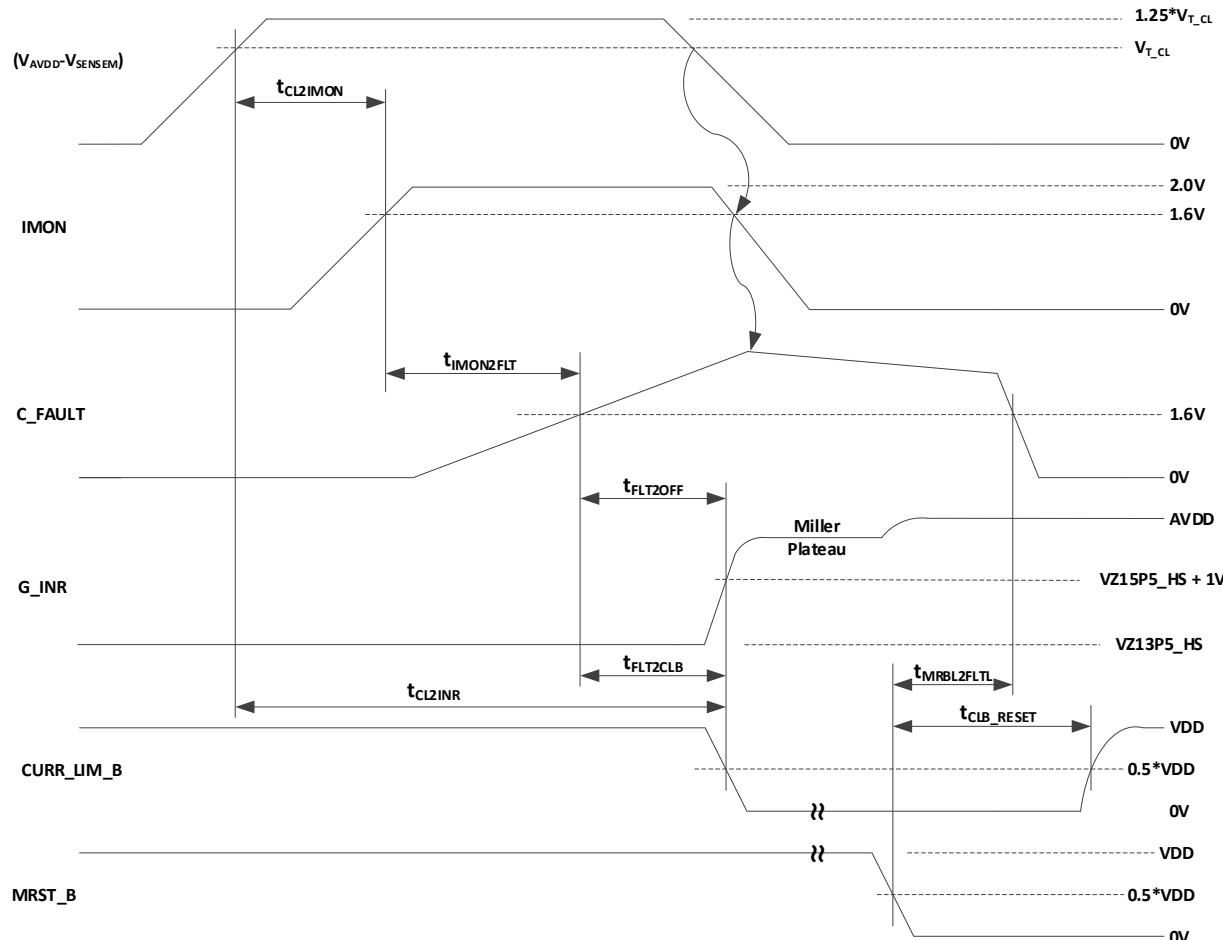


Figure 11-1. Current Limit Response Timing Diagram

Table 11-2: Reverse Current and Short Circuit Break Timing

Unless otherwise noted, the following parameters are tested with AVDD = 8V & 36V and VDD = 3.0V & 3.6V

Symbol	Parameter	Conditions	Min	Max	Units
EN_B = LOW; EN_INR = EN_OR = HIGH; SLEEP_B = HIGH; PMB_EN = X;					
t_{BREAK_INR} ⁽¹⁾	INR FET Short Circuit Break Timing	$(V_{AVDD}-V_{SENSEM})$ transitions from 0mV to $1.25*V_{T_SC}$	VGS_DRV = HIGH	500	ns
t_{BREAK_OR} ⁽¹⁾	OR FET Reverse Current Break Timing	$(V_{AVDD}-V_{VIN})$ transitions from 0mV to $1.25*V_{T_RVRS}$	VGS_DRV = HIGH	500	ns
$t_{SC2CLBL}$	Short Circuit Detect to CURR_LIM_B LOW	$(V_{AVDD}-V_{SENSEM})$ transitions from 0mV to $1.25*V_{T_SC}$		10	μs
$t_{RVRS2CLBL}$	Reverse Current Detect to CURR_LIM_B LOW	$(V_{AVDD}-V_{VIN})$ transitions from 0mV to $1.25*V_{T_RVRS}$		10	μs
t_{CLB_RESET}	CURR_LIM_B Reset Delay	AVDD = 8V; $R_{PULL-UP}=1k\Omega$; $C_{LOAD}=50pF$		5	μs
$t_{RETRIGGER}$ ⁽²⁾	Retrigger Delay	CURR_LIM_B \uparrow to MRST_B \uparrow	0		ns

Notes:

- 1) Test performed without contribution of Miller Capacitance or Gate Charge on pin under test.
 2) Provided as applications information only, neither guaranteed nor tested.

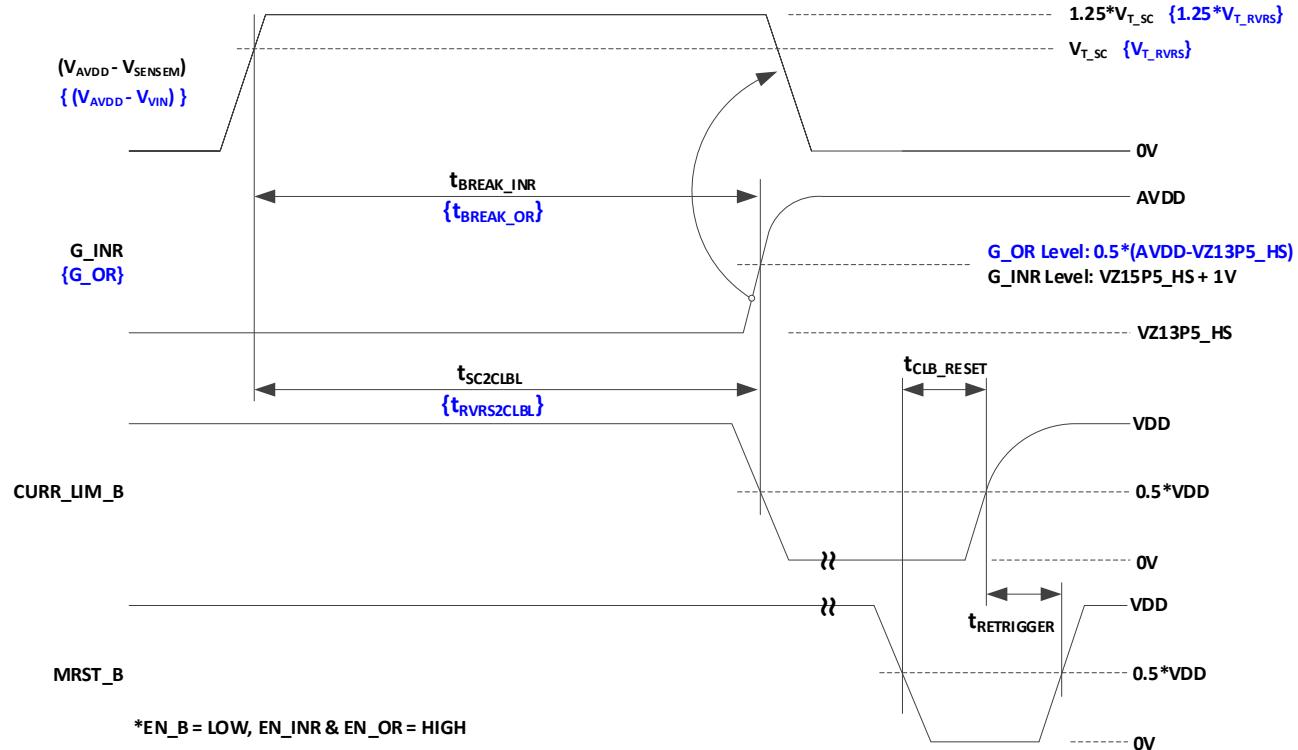


Figure 11-2. Reverse Current and Short Circuit Break Timing Diagram

Table 11-3: Voltage Fault and PGOOD Timing

Unless otherwise noted, the following parameters are tested with AVDD = 36V and VDD = 3.0V & 3.6V

Symbol	Parameter	Conditions	Min	Max	Units
MRST_B = SLEEP_B = HIGH; PMB_EN = EN_OR = X; EN_B = LOW; EN_INR = HIGH; (Only tested with VGS_DRV = HIGH)					
$t_{LOCKOUT}^{(1)}$	OVLO/UVLO Lockout ON Delay	OVLO \uparrow or UVLO \downarrow to G_INR \uparrow		40	μs
$t_{LOCK2PGL}$	OVLO/UVLO to PGOOD False Delay	OVLO \uparrow or UVLO \downarrow to PGOOD \downarrow		5	μs
$t_{LOCKOFF}^{(1)}$	OVLO/UVLO Lockout OFF Delay	OVLO \downarrow or UVLO \uparrow to G_INR \downarrow		40	μs
t_{PGOOD1}	OVLO/UVLO to PGOOD True Delay	OVLO \downarrow or UVLO \uparrow to PGOOD \uparrow		5	μs
t_{FB2PGL}	FEEDBACK to PGOOD False Delay	FEEDBACK \downarrow to PGOOD \downarrow		10	μs
t_{PGOOD2}	FEEDBACK to PGOOD True Delay	FEEDBACK \uparrow to PGOOD \uparrow		10	μs

Note:

- 1) Test performed without contribution of Miller Capacitance or Gate Charge on pin under test.

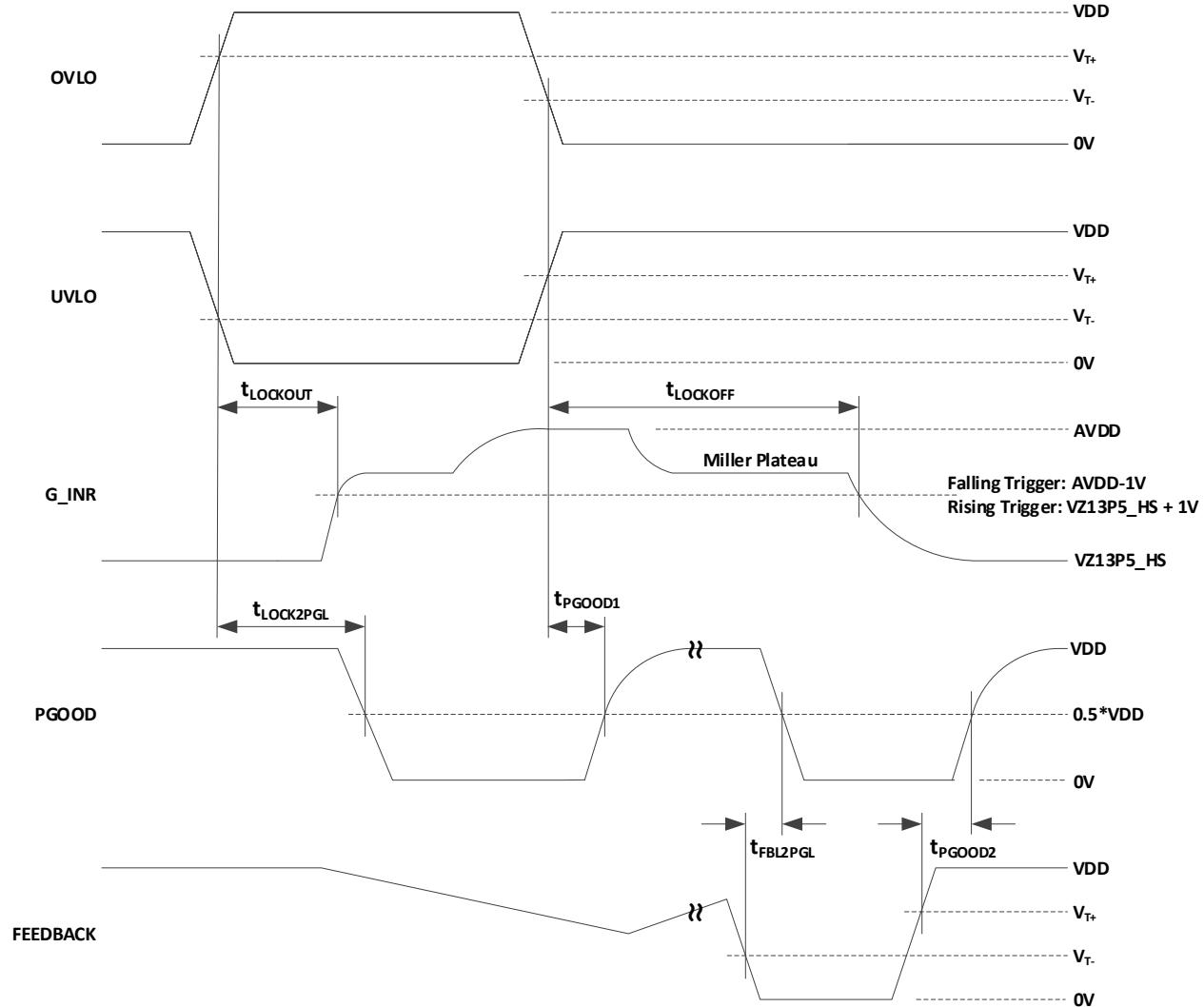


Figure 11-3. Voltage Fault and PGOOD Timing Diagram

Table 11-4: Commanded Enable and Disable Timing

Unless otherwise noted, the following parameters are tested with AVDD = 36V and VDD = 3.0V & 3.6V

Symbol	Parameter	Conditions	Min	Max	Units
MRST_B = SLEEP_B = HIGH; PMB_EN = X; (Only tested with VGS_DRV = HIGH)					
$t_{DIS_INR}^{(1)}$	EN_INR False to G_INR Disabled	EN_B = LOW; EN_OR = X		40	μs
$t_{EN_INR}^{(1)}$	EN_INR True to G_INR Enabled	EN_B = LOW; EN_OR = X		40	μs
$t_{DIS_OR}^{(1)}$	EN_OR False to G_OR Disabled	EN_B = LOW; EN_INR = X		10	μs
$t_{EN_OR}^{(1)}$	EN_OR True to G_OR Enabled	EN_B = LOW; EN_INR = X		10	μs
$t_{DIS_ALL}^{(1)}$	EN_B False to G_INR & G_OR Disabled	EN_INR = HIGH; G_INR Rising EN_OR = HIGH; G_OR Rising		40	μs
$t_{EN_ALL}^{(1)}$	EN_B True to G_INR & G_OR Enabled	EN_INR = HIGH; G_INR Falling EN_OR = HIGH; G_OR Falling		40	μs
				10	μs

Note:

- 1) Test performed without contribution of Miller Capacitance or Gate Charge on pin under test.

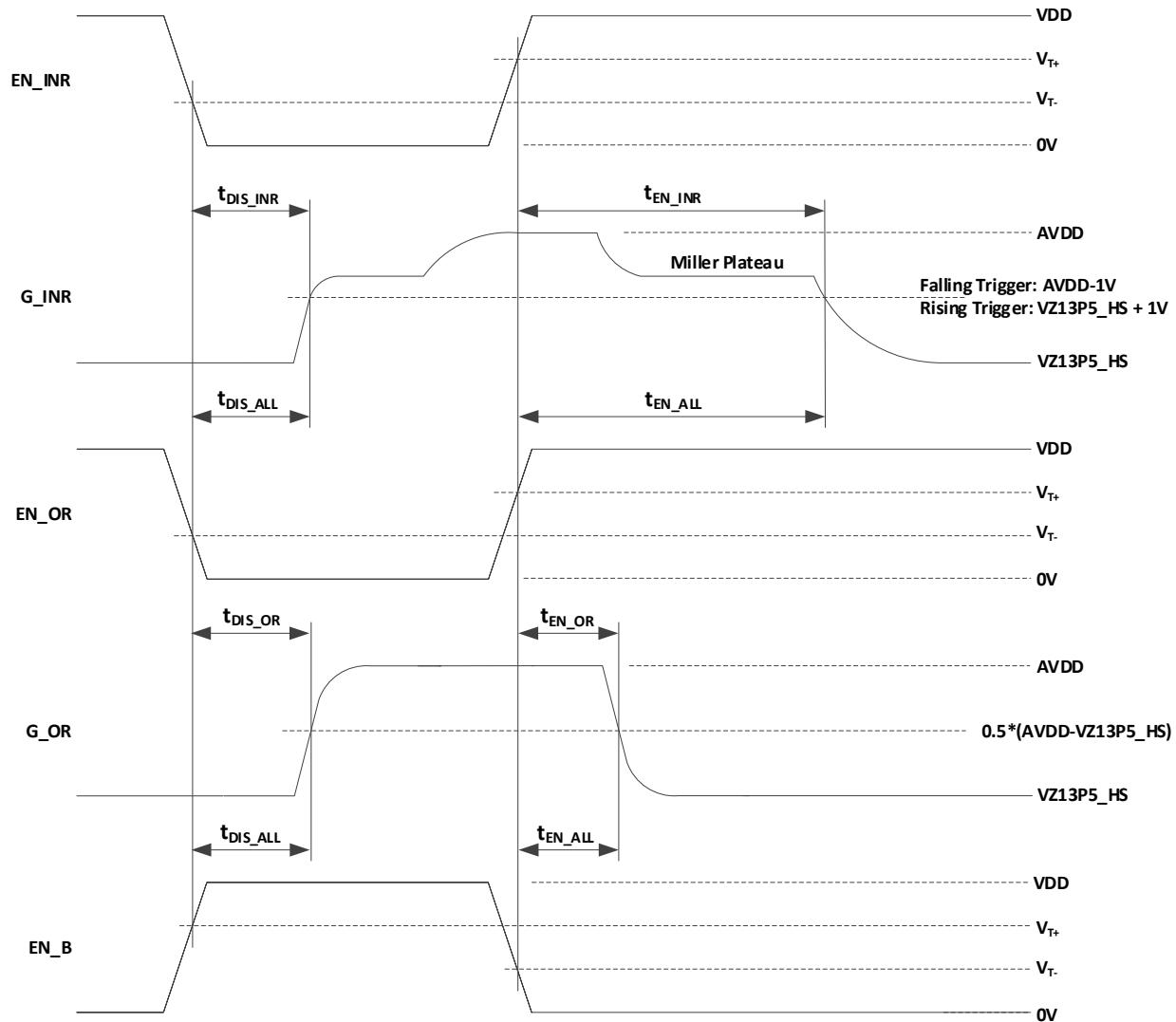


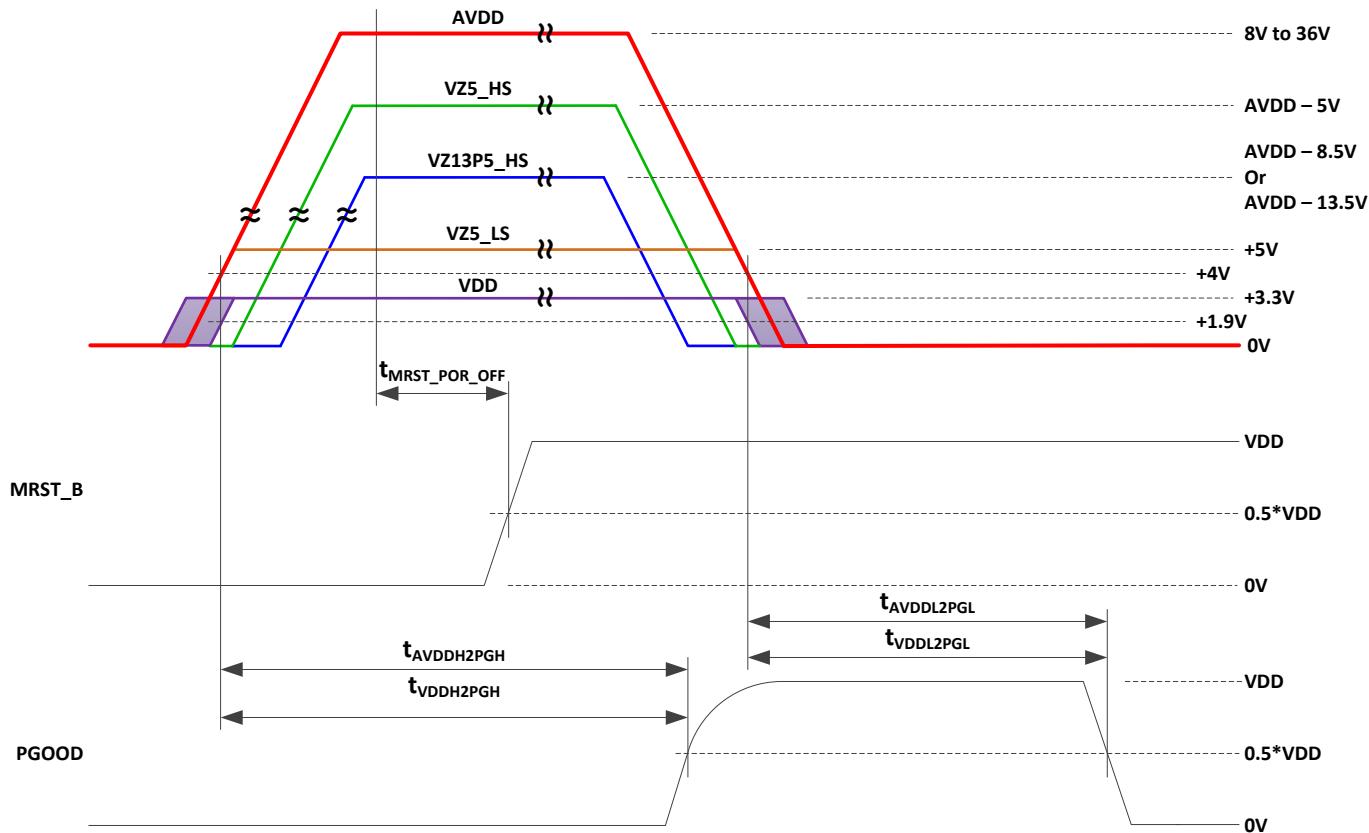
Figure 11-4. Commanded Enable and Disable Timing Diagram

Table 11-5: Power Up/Down and Reset Timings

Symbol	Parameter	Conditions	Min	Max	Units
In dual supply mode (INT_VDD_DIS = VZ5_HS) VDD does NOT have power sequencing requirements.					
In single supply mode (INT_VDD_DIS = DGND) VDD will track AVDD until it reaches its regulated voltage.					
$t_{MRST_POR_OFF}^{(1)}$	AVDD & VDD On to MRST_B False		50		μs
$t_{AVDDH2PGH}^{(2)}$	AVDD HIGH to PGOOD True		120		μs
$t_{VDDH2PGH}^{(2)}$	VDD HIGH to PGOOD True		120		μs
$t_{AVDDL2PGL}^{(2)}$	AVDD LOW to PGOOD False		120		μs
$t_{VDDL2PGL}$	VDD LOW to PGOOD False		120		μs

Notes:

- 1) Functionally tested only
 2) Provided as applications information only, neither guaranteed nor tested.



**Note: To evaluate the effect of VDD, AVDD and MRST_B on PGOOD, voltage monitoring inputs UVLO, OVLO, and FEEDBACK must be in their non-fault states.

Figure 11-5. Power Up/Down and Reset Timing Diagram

Table 11-6: Master Reset Timing

Unless otherwise noted, the following parameters are tested with AVDD = 36V and VDD = 3.0V & 3.6V

Symbol	Parameter	Conditions	Min	Max	Units
EN_INR = EN_OR = SLEEP_B = UVLO = FEEDBACK = HIGH; EN_B = OVLO = LOW; (Only tested with VGS_DRV = HIGH)					
$t_{MRSTB_LOW}^{(1)}$	MRST_B Pulse Width LOW		50		μs
$t_{SETUP}^{(1)}$	Configuration Inputs SETUP time to MRST_B False	PMB_EN = HIGH	1		μs
$t_{HOLD}^{(1)}$	Configuration Inputs HOLD time from MRST_B False	PMB_EN = HIGH	10		μs
$t_{MRSTBH2SMBRDY}^{(1)}$	MRST_B Deassertion to SMBus Ready for Communication	PMB_EN = HIGH	100		μs
$t_{MRSTBL2INR_DIS}^{(2)}$	MRST_B True to G_INR Disabled	PMB_EN=LOW	500		ns
$t_{MRSTBH2INR_EN}^{(2)}$	MRST_B False to G_INR Enabled	PMB_EN=LOW	40		μs
$t_{MRSTBL2OR_DIS}^{(2)}$	MRST_B True to G_OR Disabled	PMB_EN=LOW	500		ns
$t_{MRSTBH2OR_EN}^{(2)}$	MRST_B False to G_OR Enabled	PMB_EN=LOW	10		μs

Notes:

- 1) Functionally tested only.
- 2) Test performed without contribution of Miller Capacitance or Gate Charge on pin under test.

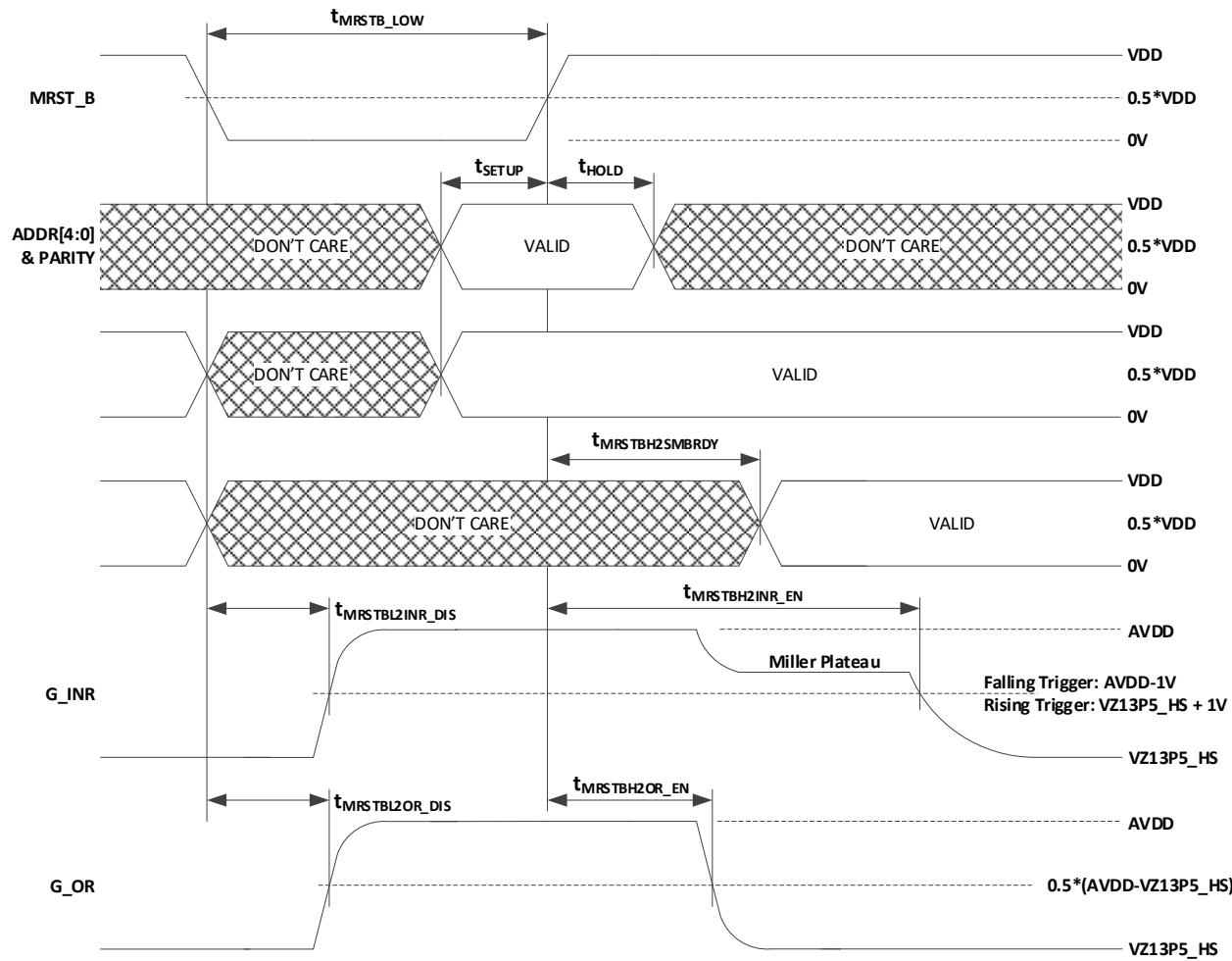


Figure 11-6. Master Reset Timing Diagram

Table 11-7: Sleep Timing

Unless otherwise noted, the following parameters are tested with AVDD = 36V and VDD = 3.0V & 3.6V

Symbol	Parameter	Conditions	Min	Max	Units
EN_INR = EN_OR = PMB_EN = MRST_B = UVLO = HIGH; EN_B = OVLO = FEEDBACK = LOW; (Only tested with VGS_DRV = HIGH)					
$t_{SLEEP_ON}^{(1)}$	Time to Enter Sleep Mode			100	μs
$t_{SLEEP_OFF}^{(1)}$	Time to Exit Sleep Mode			100	μs
$t_{SLPL2INR_DIS}^{(2)}$	SLEEP_B True to G_INR Disabled			50	μs
$t_{SLPH2INR_EN}^{(1)}$	SLEEP_B False to G_INR Enabled			70	μs
$t_{SLPL2OR_DIS}^{(2)}$	SLEEP_B True to G_OR Disabled			50	μs
$t_{SLPH2OR_EN}^{(1)}$	SLEEP_B False to G_OR Enabled			20	μs

Notes:

- 1) Provided as applications information only, neither guaranteed nor tested.
- 2) Test performed without contribution of Miller Capacitance or Gate Charge on pin under test.

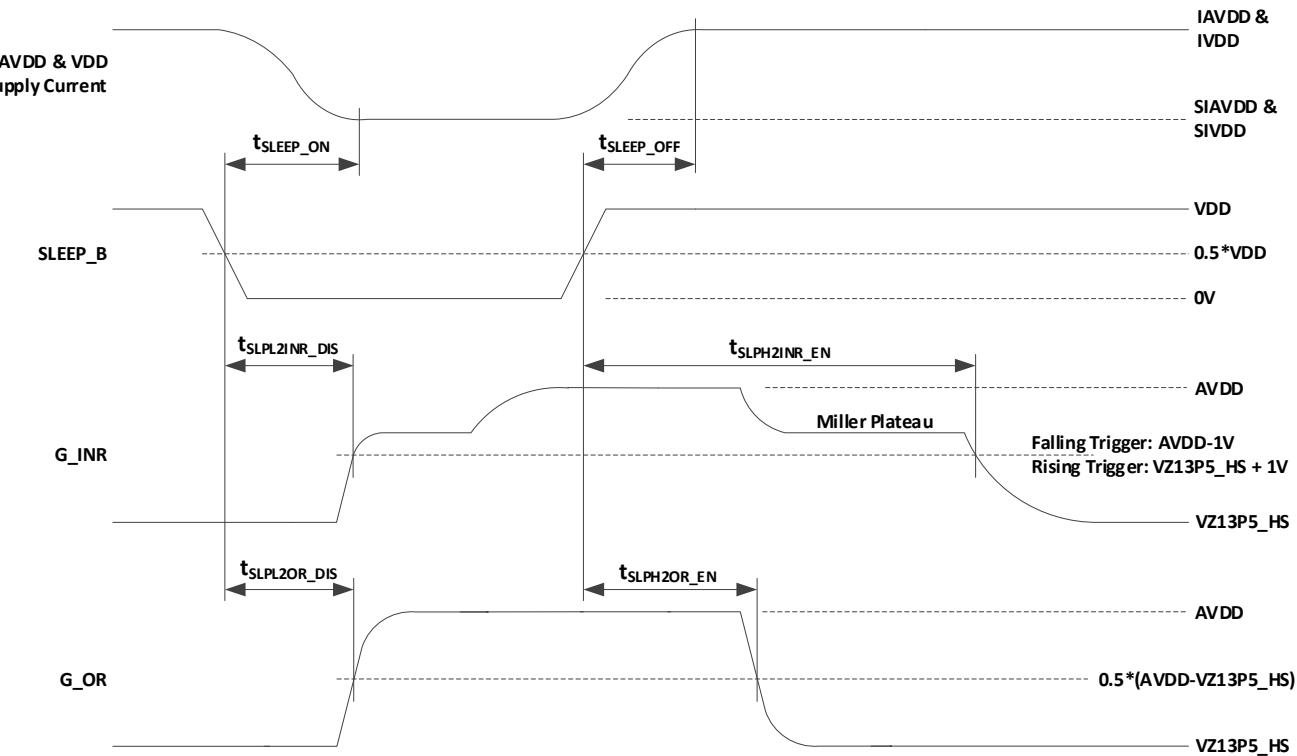


Figure 11-7. Sleep Timing Diagram

Table 11-8: SMBus Timing

Unless otherwise noted, the following parameters are tested with AVDD = 8V and VDD = 3.0V & 3.6V

Symbol	Parameter	Conditions	Min	Max	Units
MRST_B = SLEEP_B = HIGH; PMB_EN = HIGH;					
t_{H_START}	SMBCLK Hold Time After (REPEATED) Start Condition		0.6		μs
$t_{H_DATA_IN}^{(1)}$	SMBDIO Input Hold Time After SMBCLK		0		ns
$t_{S_DATA_IN}^{(1)}$	SMBDIO Input Setup Time Before SMBCLK		100		ns
$t_{DATA_OUT}^{(2)}$	SMBDIO Output Data Valid After SMBCLK		0.6		μs
t_{S_START}	SMBCLK Setup Time Before REPEATED START Condition		0.6		μs
t_{S_STOP}	SMBCLK Setup Time Before STOP Condition		0.6		μs
t_{BUF}	Bus Free Time Between STOP and START Condition		1.3		μs
$f_{SMB}^{(5)}$	SMBus Operating Frequency		400		kHz
T_{SMB}	SMBCLK Period		2.5		μs
t_{SCL_LOW}	SMBCLK LOW Time		1.3		μs
t_{SCL_HIGH}	SMBCLK HIGH Time		0.6	50	μs
$t_{FALL}^{(4)}$	SMBCLK/SMBDIO Fall Time		300		ns
$t_{RISE}^{(4)}$	SMBCLK/SMBDIO Rise Time		300		ns
$t_{NOISE_SPIKE}^{(3, 4)}$	Noise Spike Suppression Time		50		ns

Notes:

- 1) SMBDIO input setup and hold times must be assured at the corresponding pins of the UT36PFD103 in relation to the input threshold voltages V_{T+} (rising edge) and V_{T-} (falling edge).
- 2) SMBDIO out will be valid (above/below threshold voltage) at the corresponding UT36PFD103 pin the specified duration after SMBCLK is detected LOW. $C_{LOAD} = 40pF$.
- 3) Noise spikes up to the maximum Noise Spike Suppression time will be filtered by the UT36PFD103.
- 4) Provided as applications information only, neither guaranteed nor tested.
- 5) Functionally tested only.

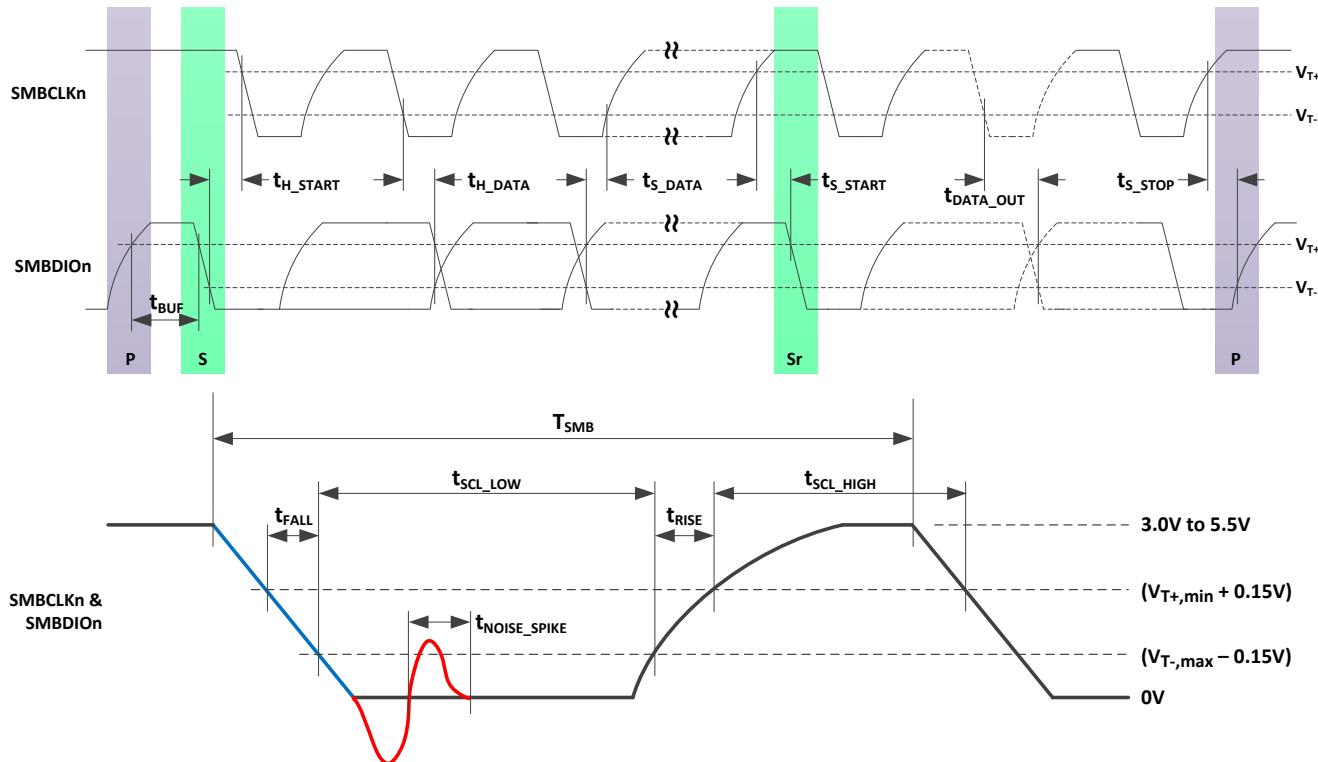


Figure 11-8. SMBus Timing Diagram

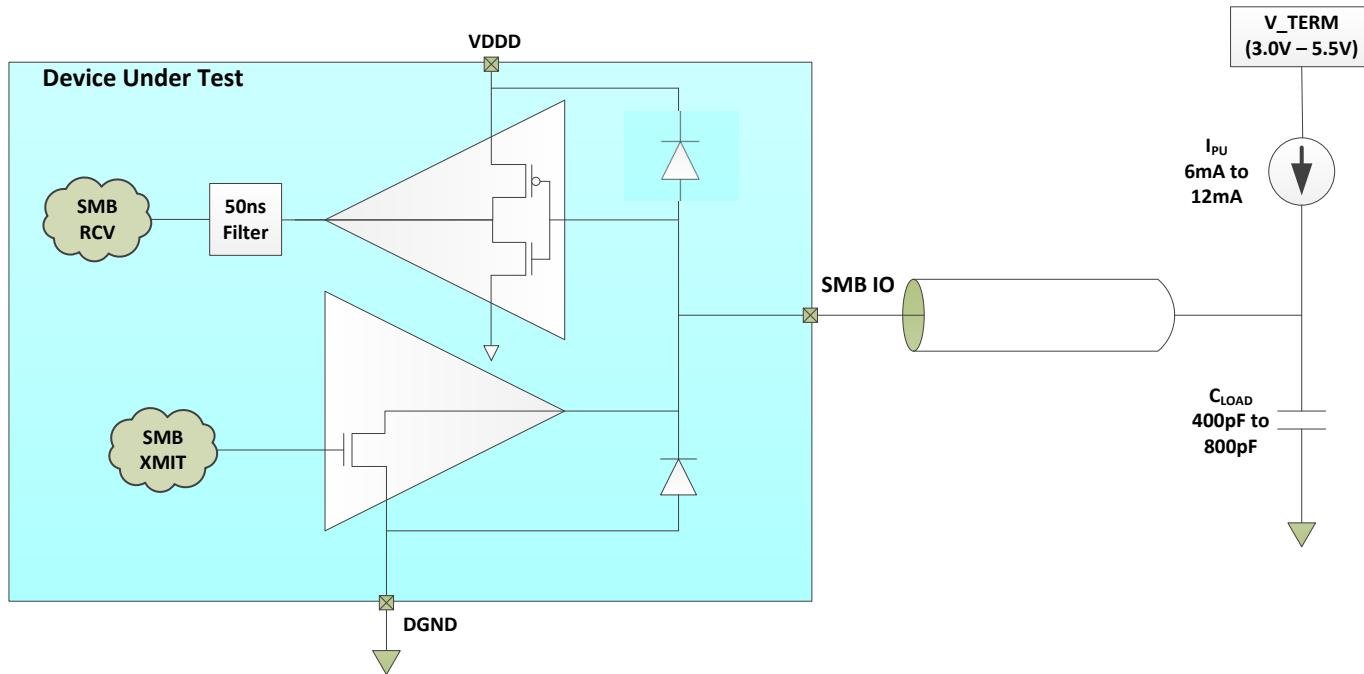
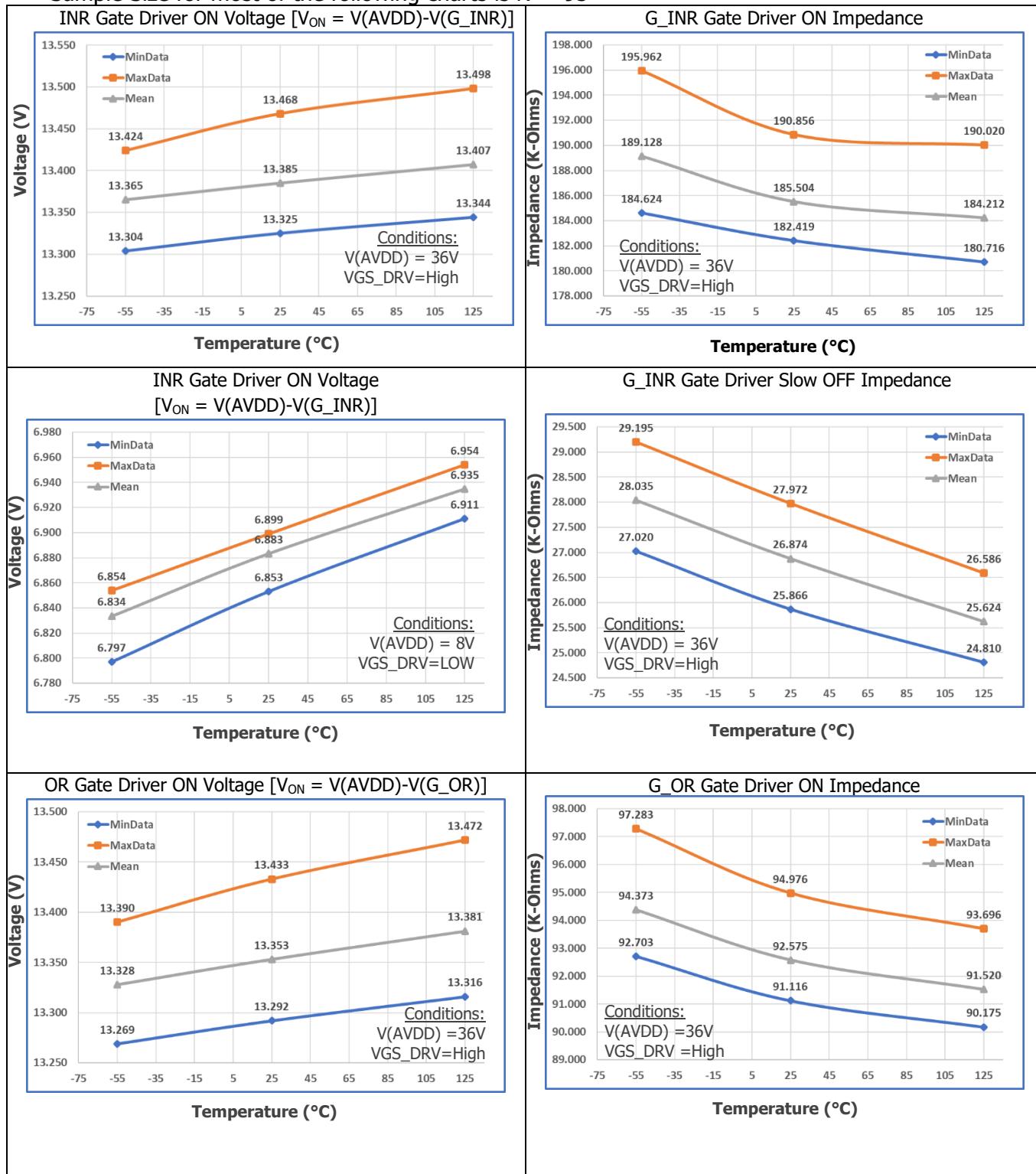
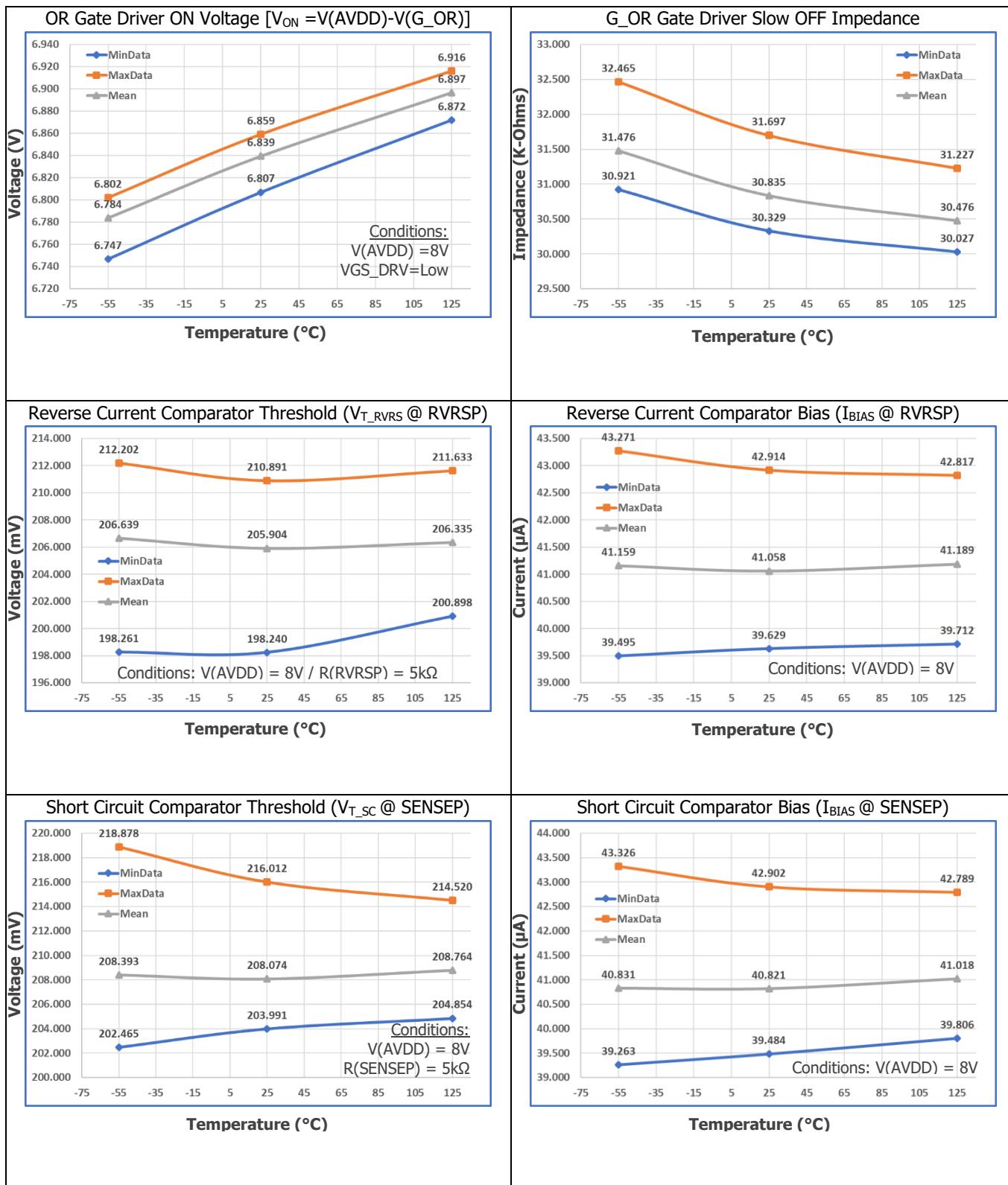


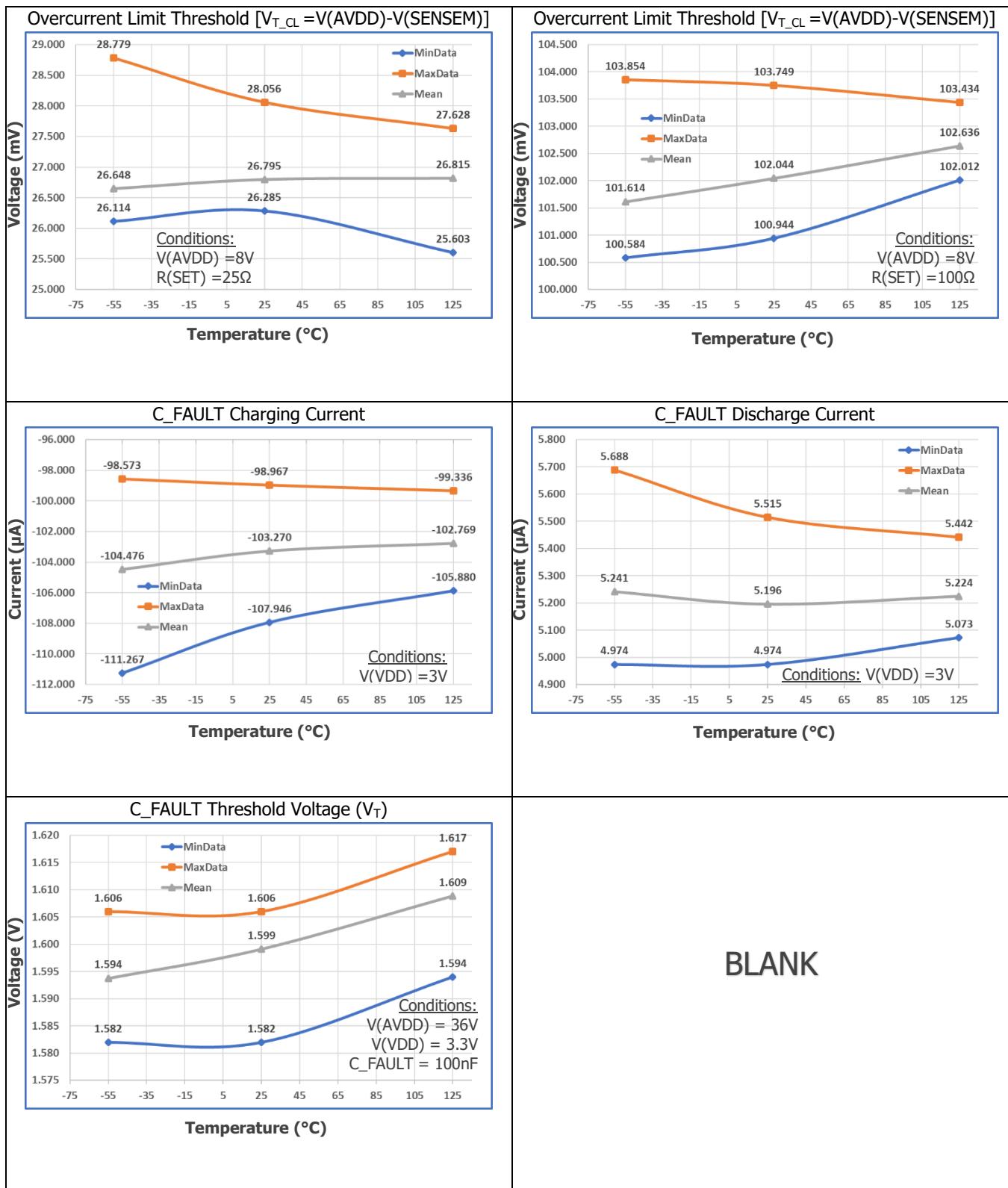
Figure 11-9. SMBus IO Test Load

12 Typical Performance Characteristics ⁽¹⁾

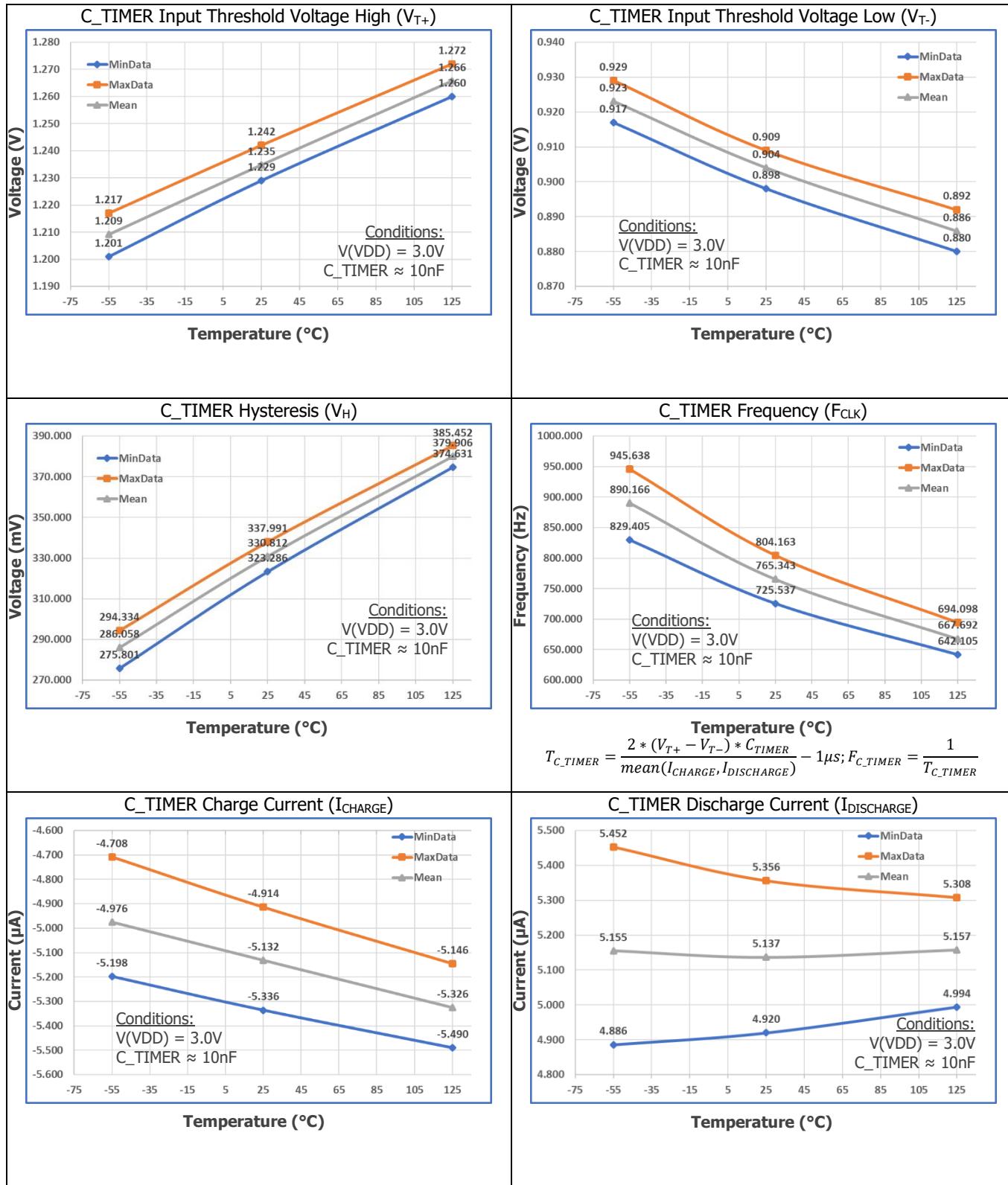
Sample Size for most of the following charts is N>=95

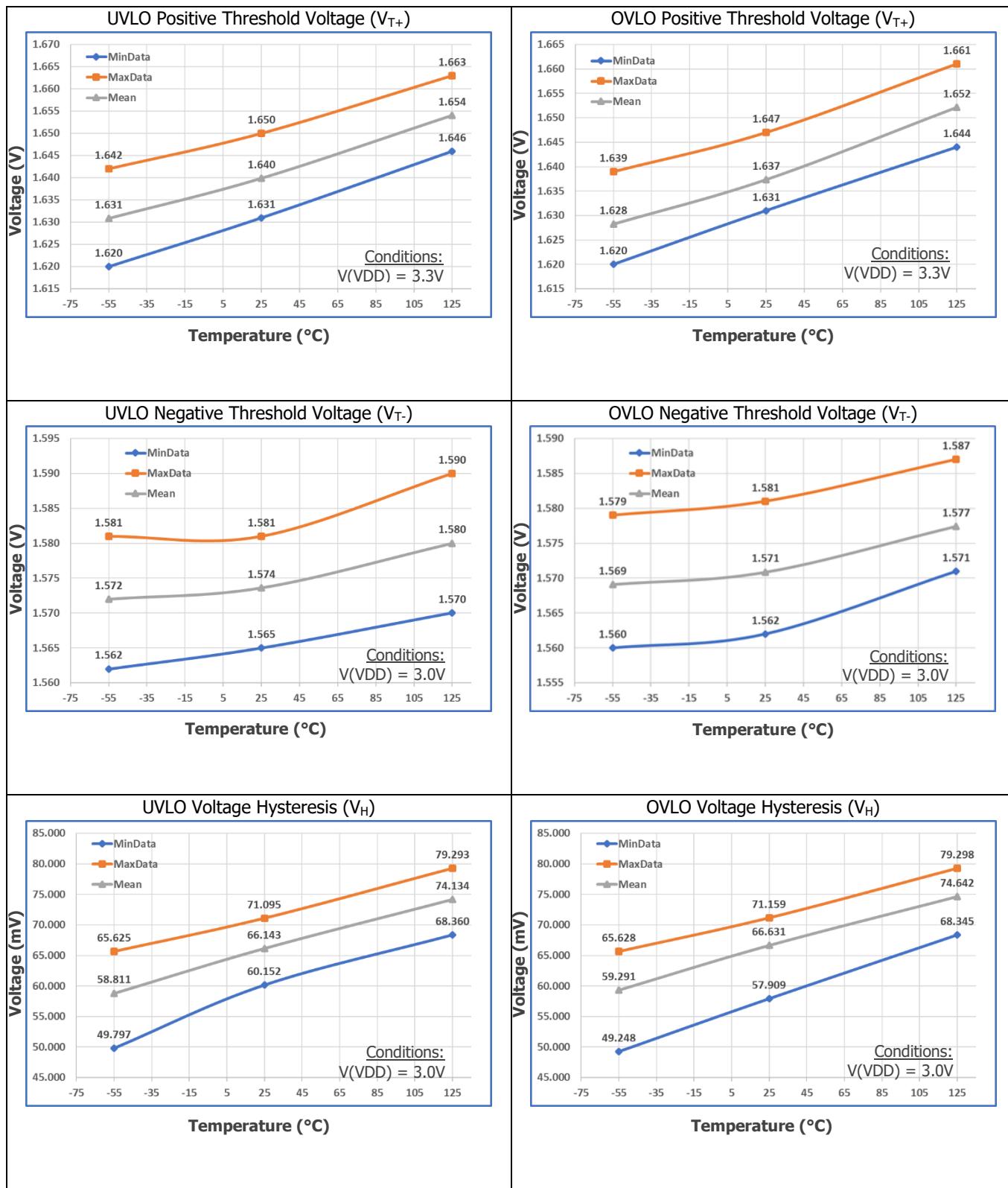


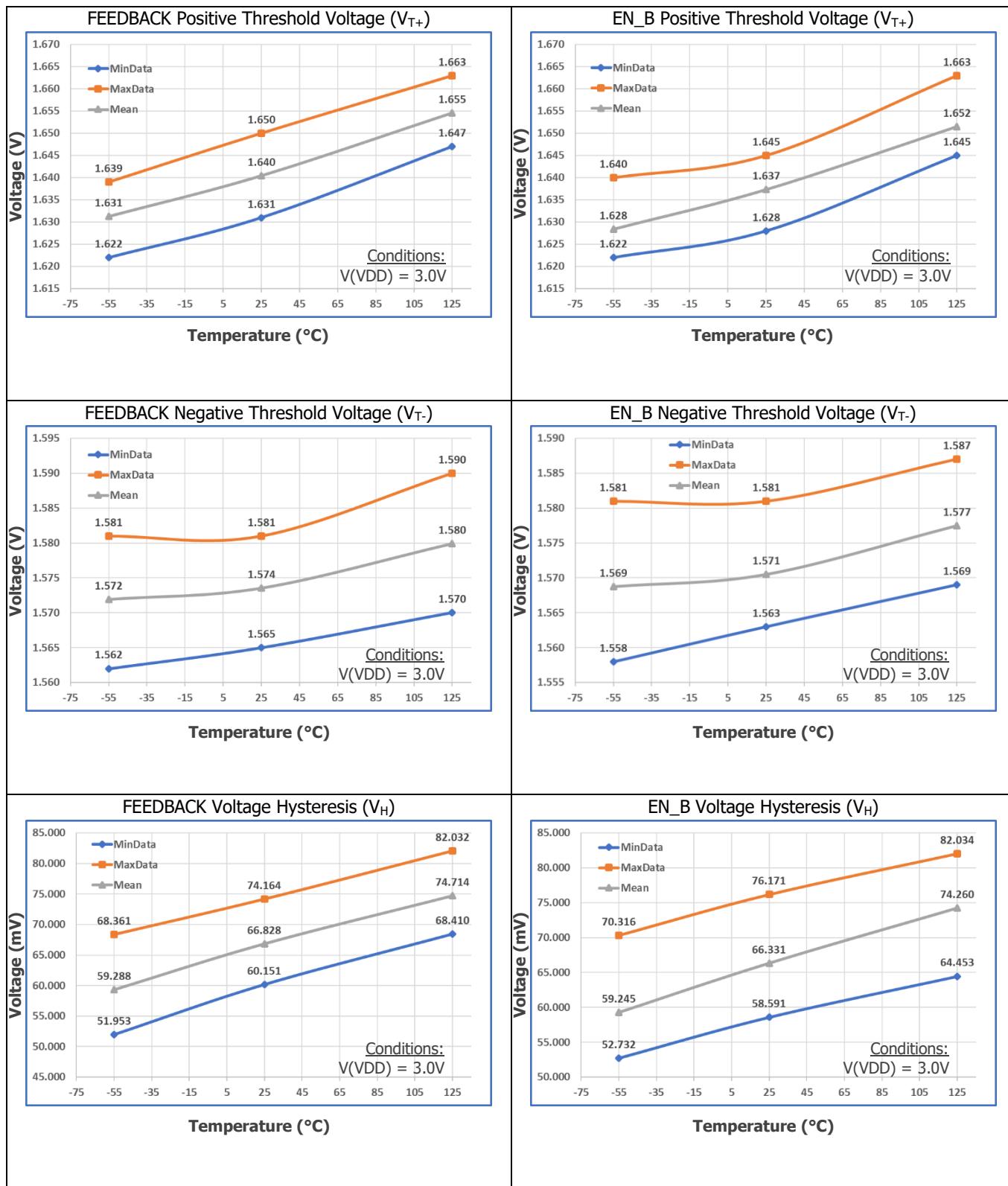


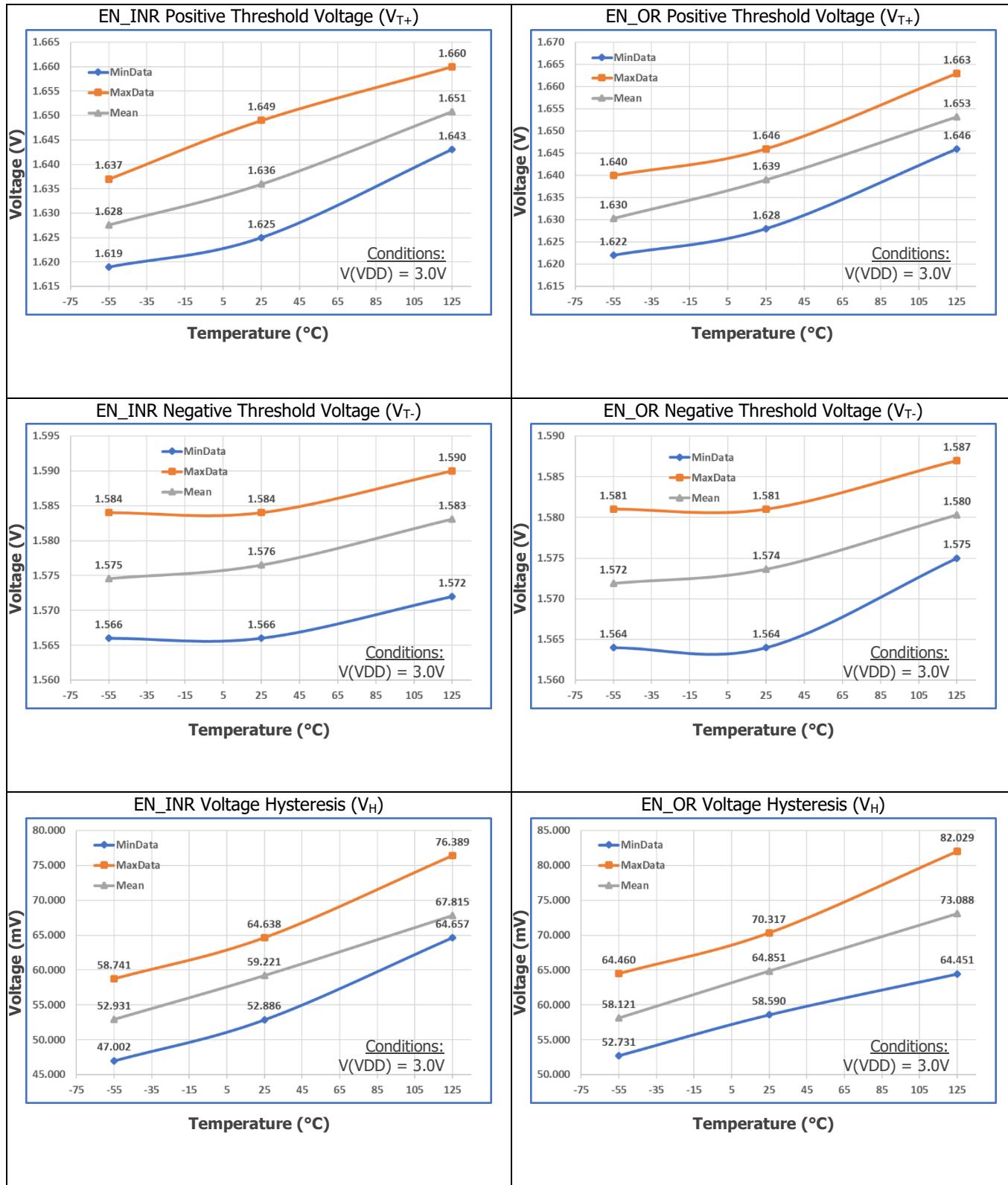


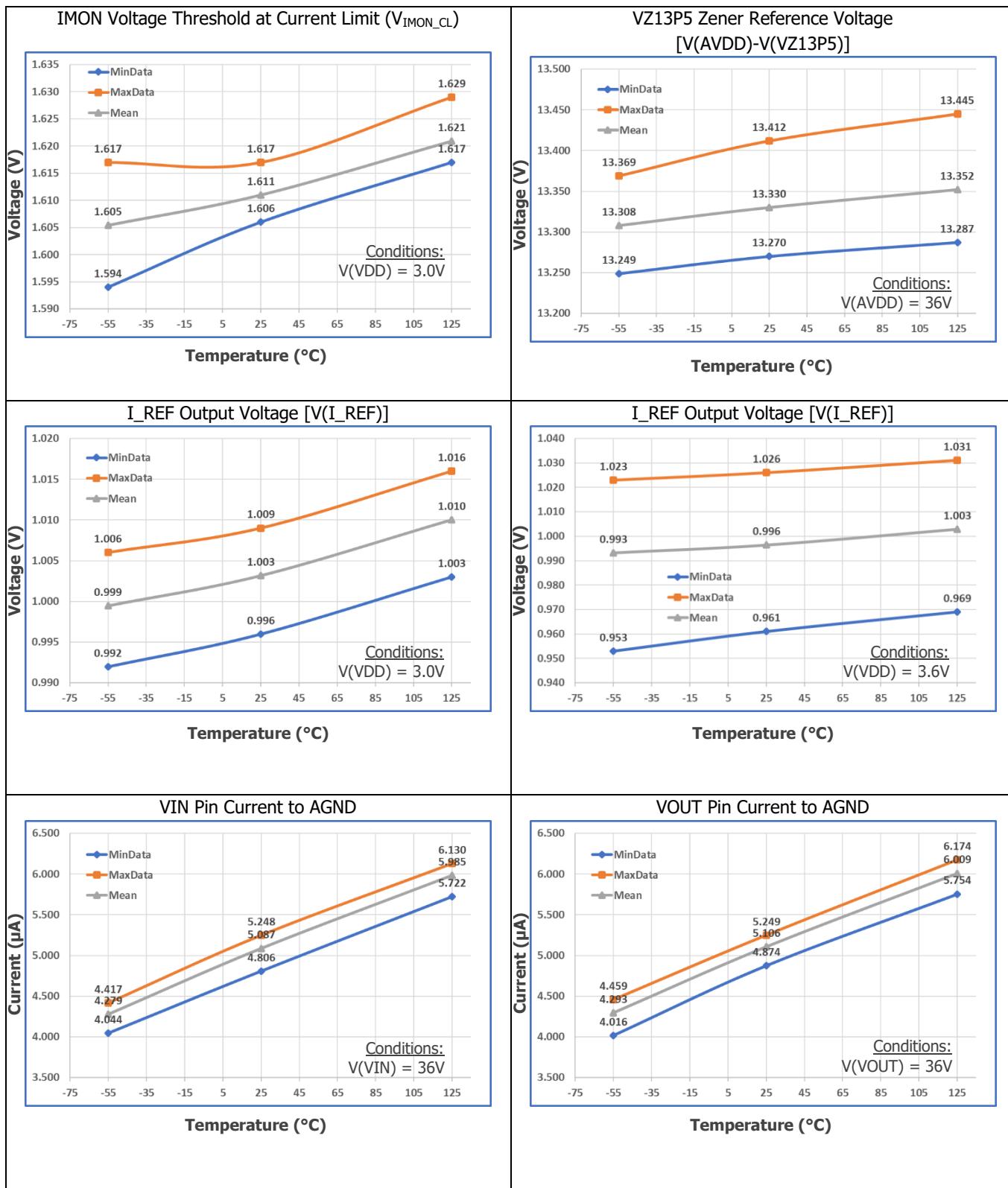
BLANK

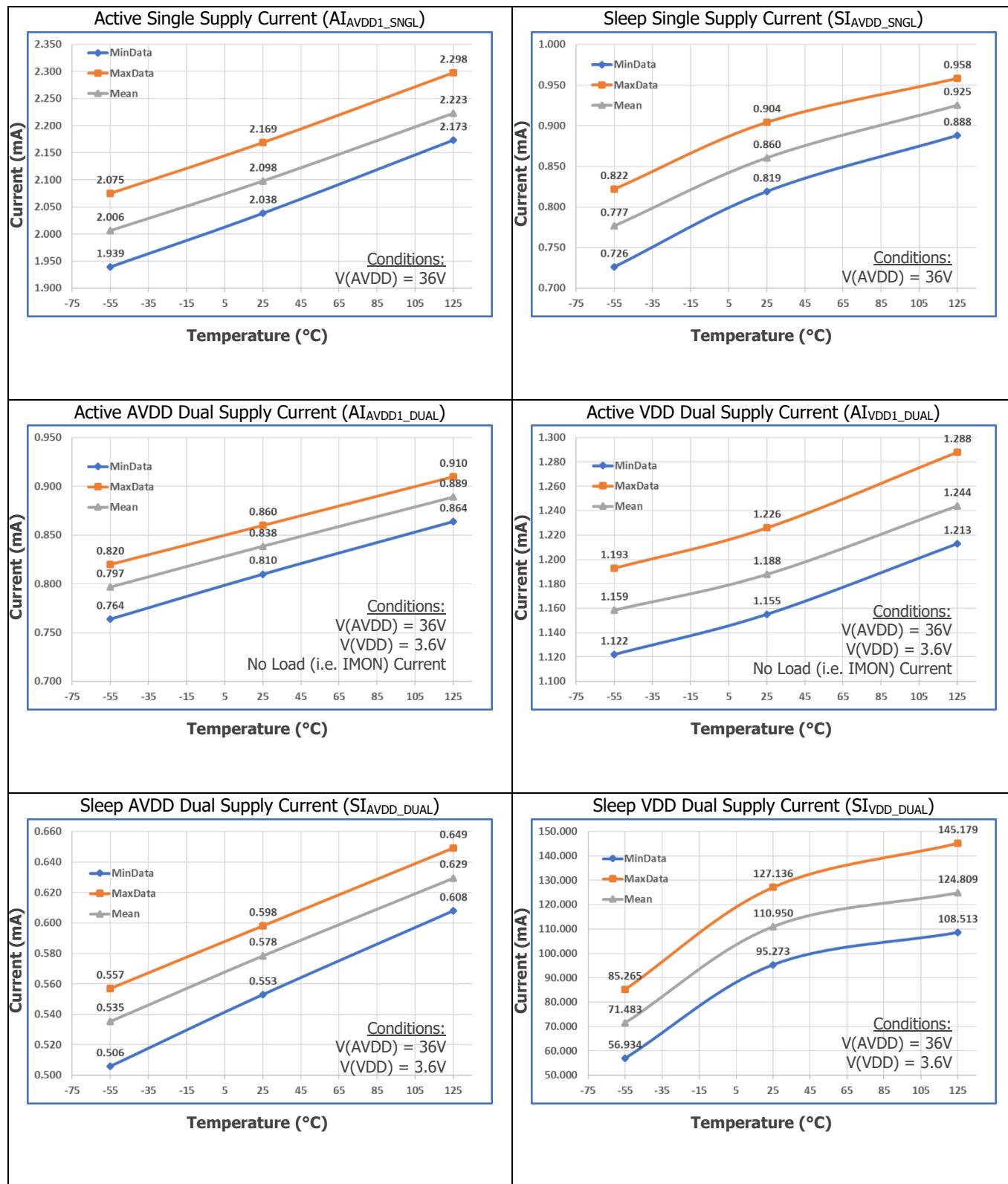


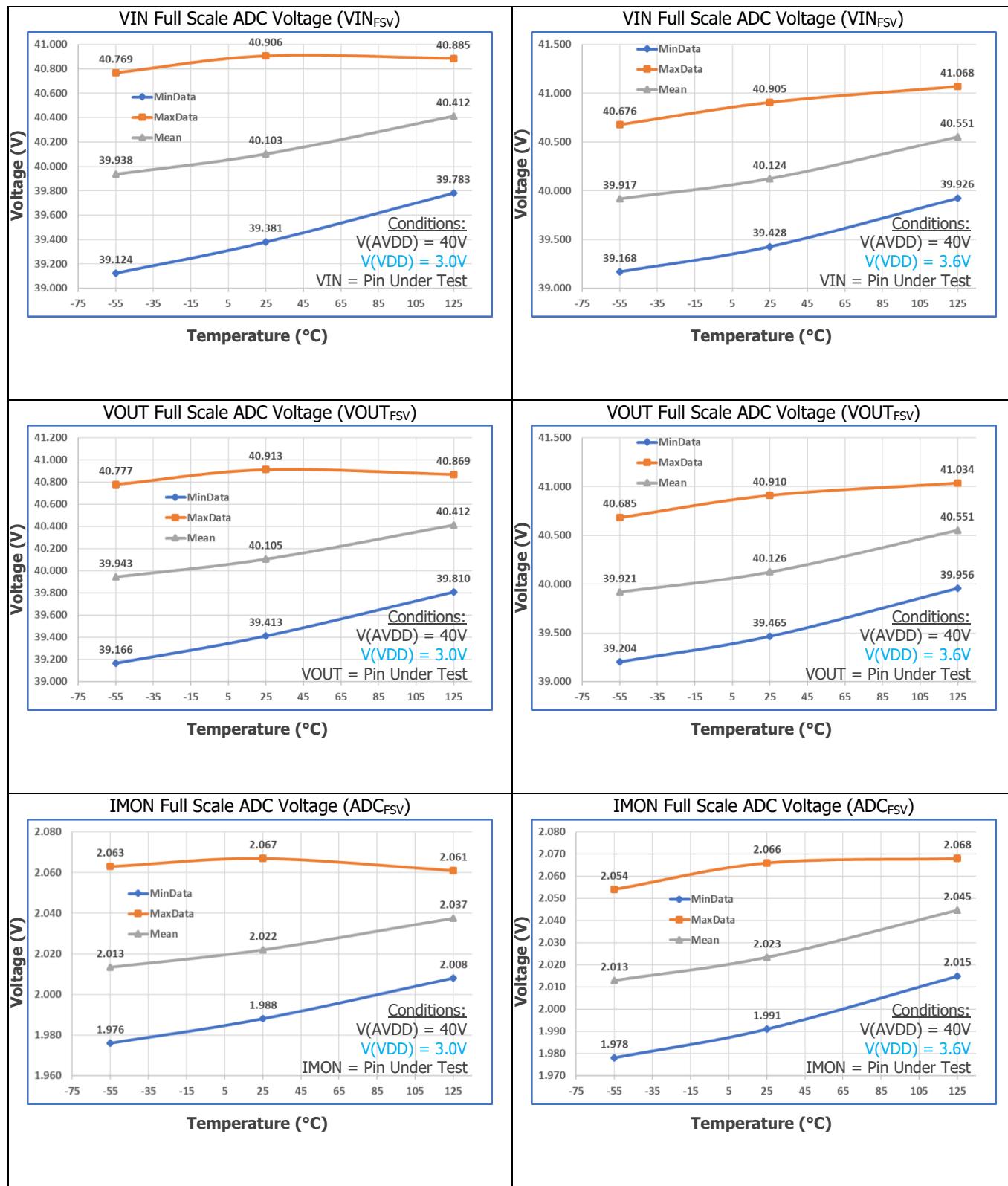


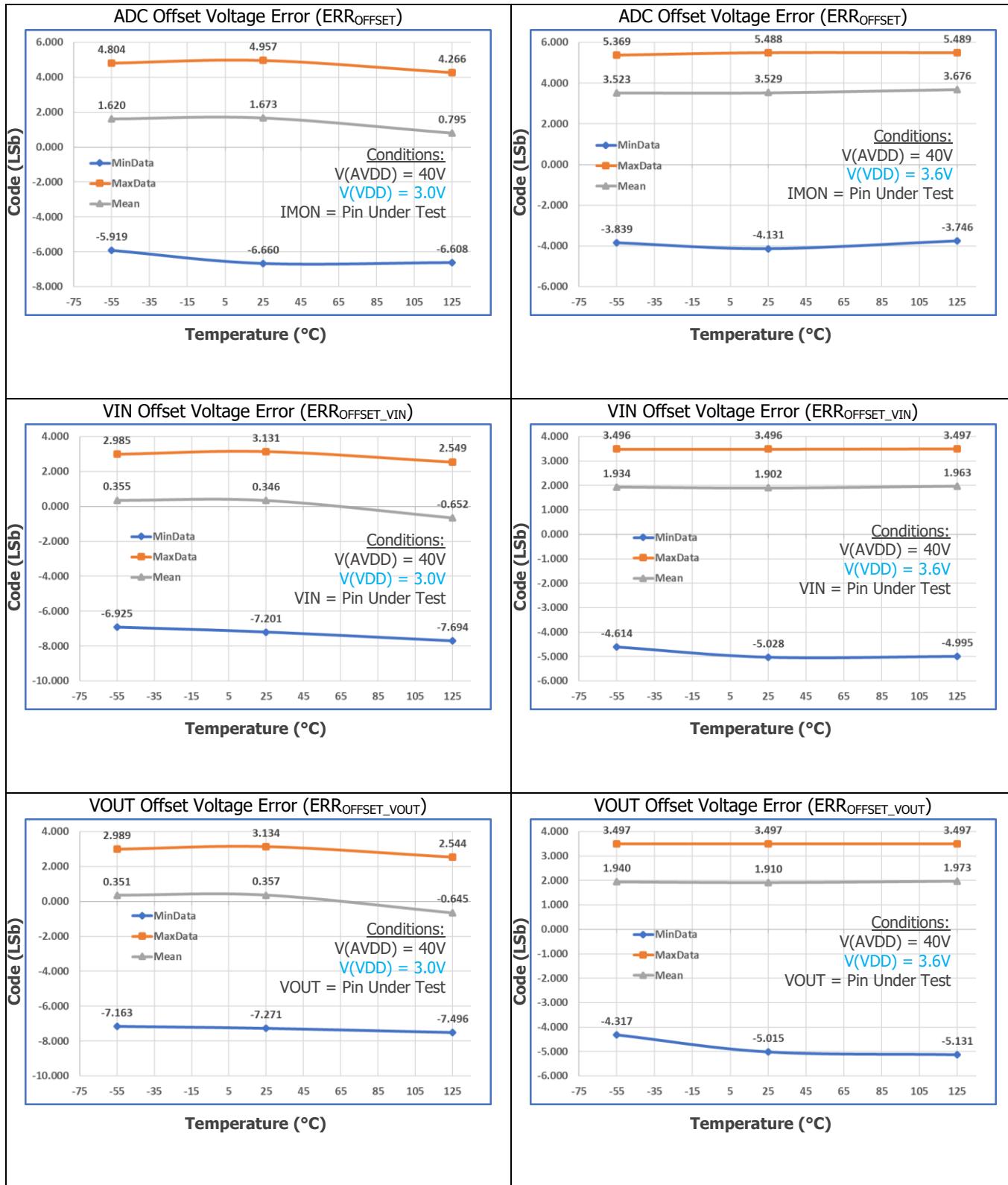


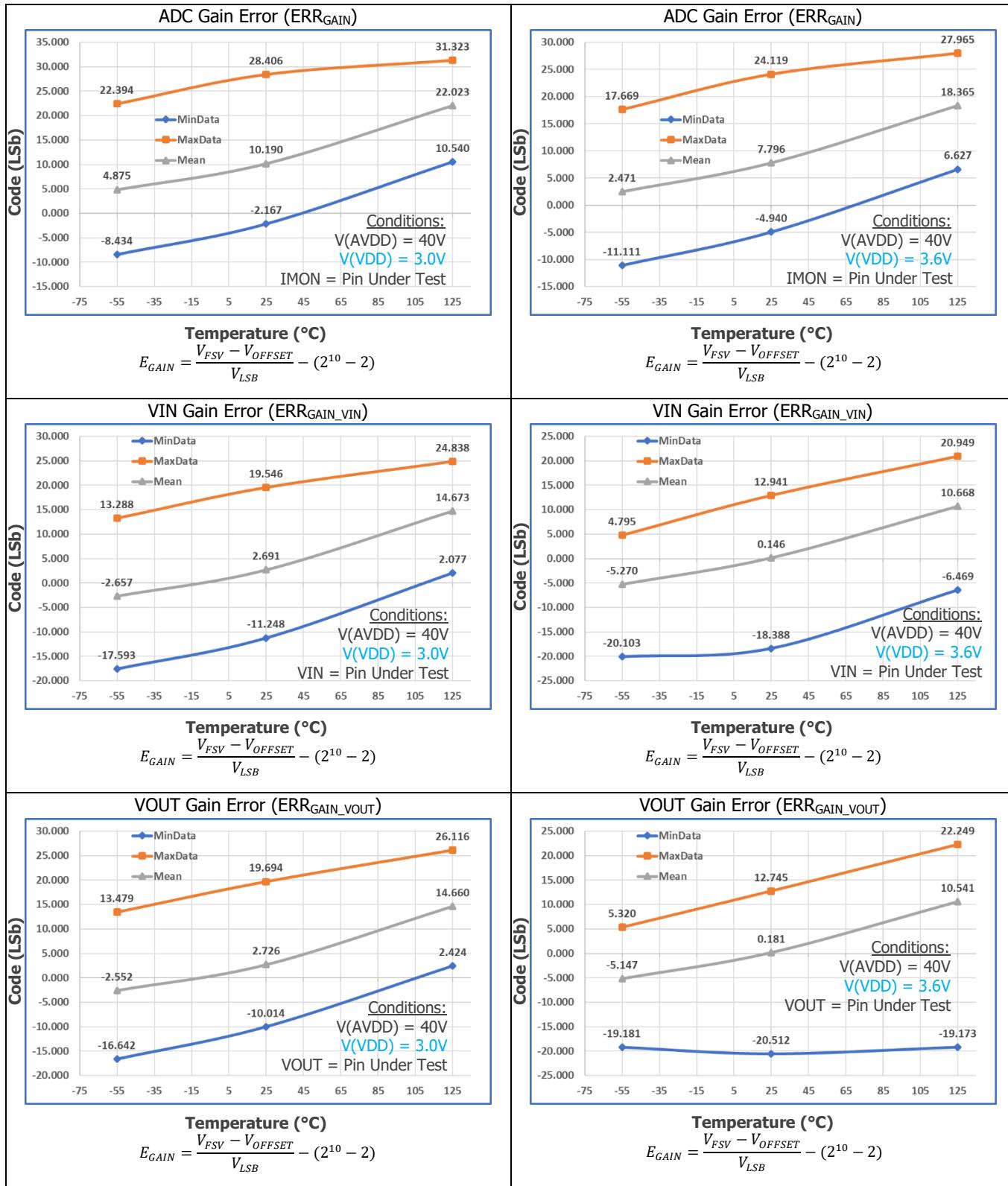


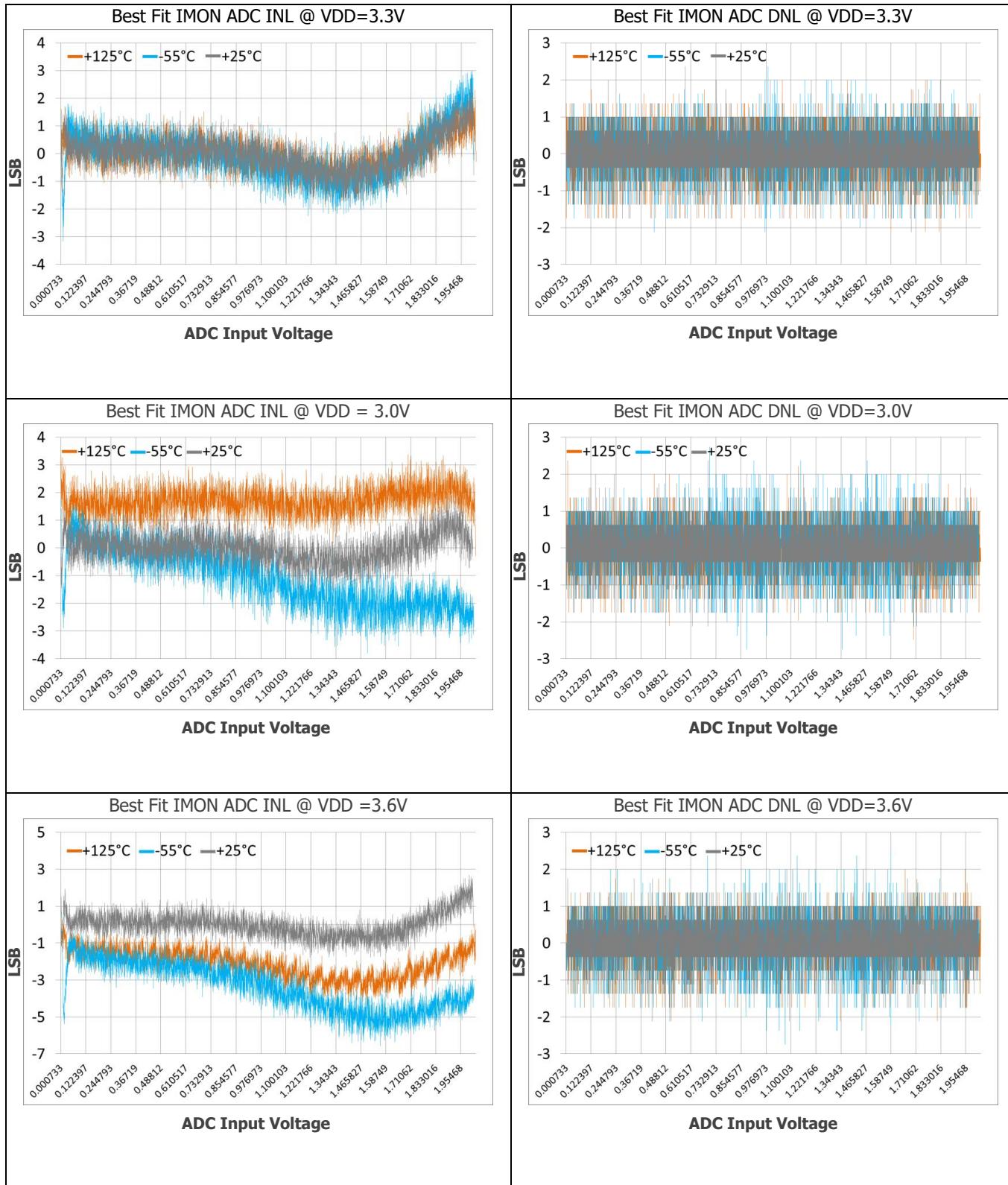












13 Detailed Functional Description

The following sections detail the UT36PFD103 features and operational behavior in detail.

13.1 PMBus® / SMBus Functional Description

Power Management Bus (PMBus) is a powerful communication protocol standard finding extensive use in commercial power system management applications. PMBu applies a protocol transport layer to configure, control, and gather data & telemetry from targeted power system component via an SMBus network layer. The SMBus network layer of the protocol stack performs packetization and handles bus commands delivered over an I²C link and physical layer.

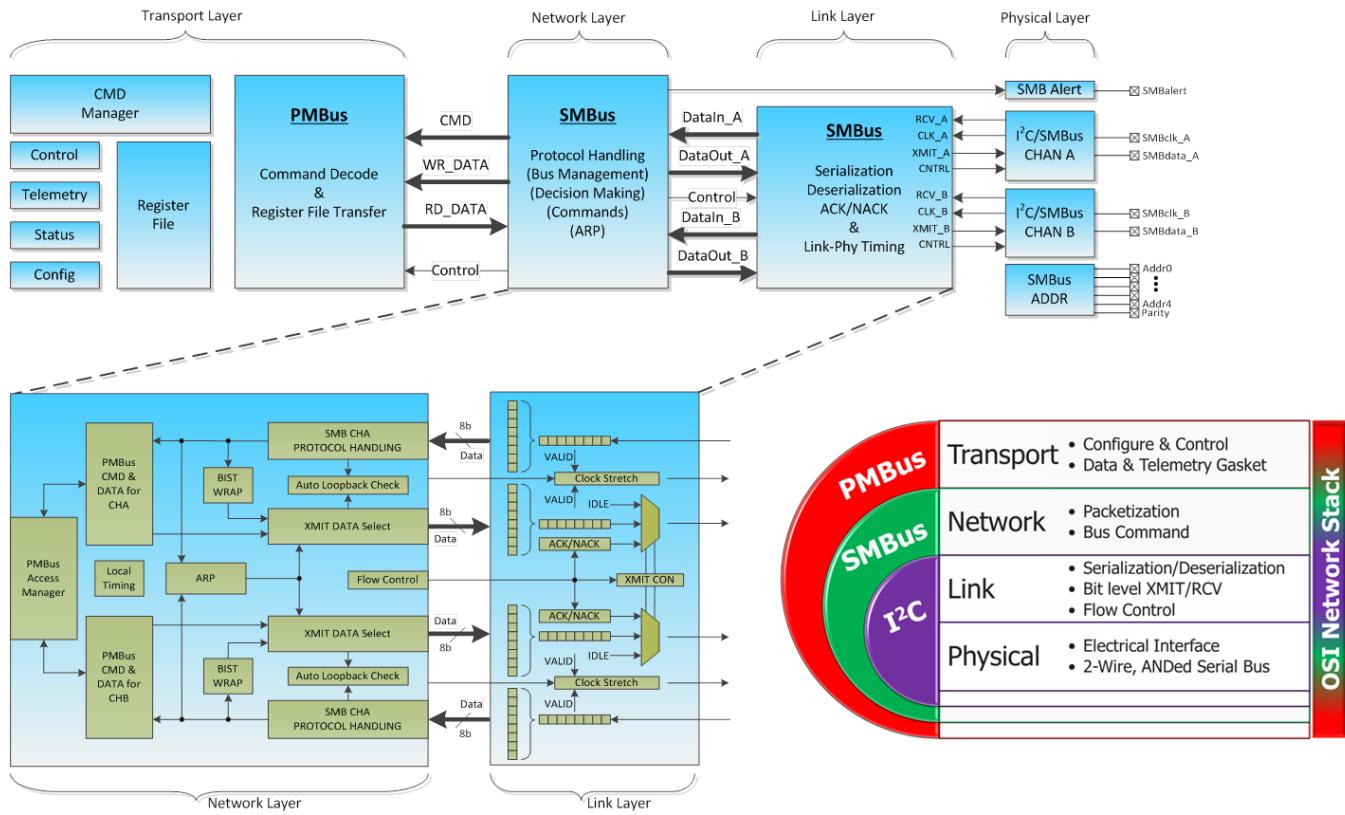
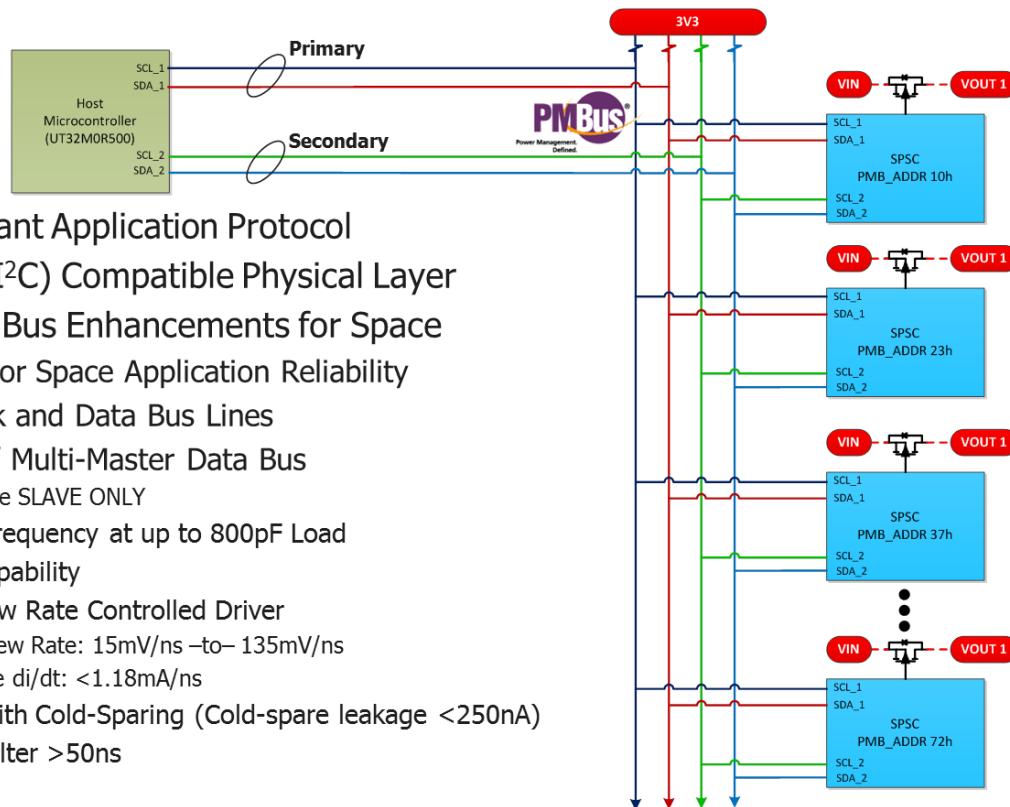


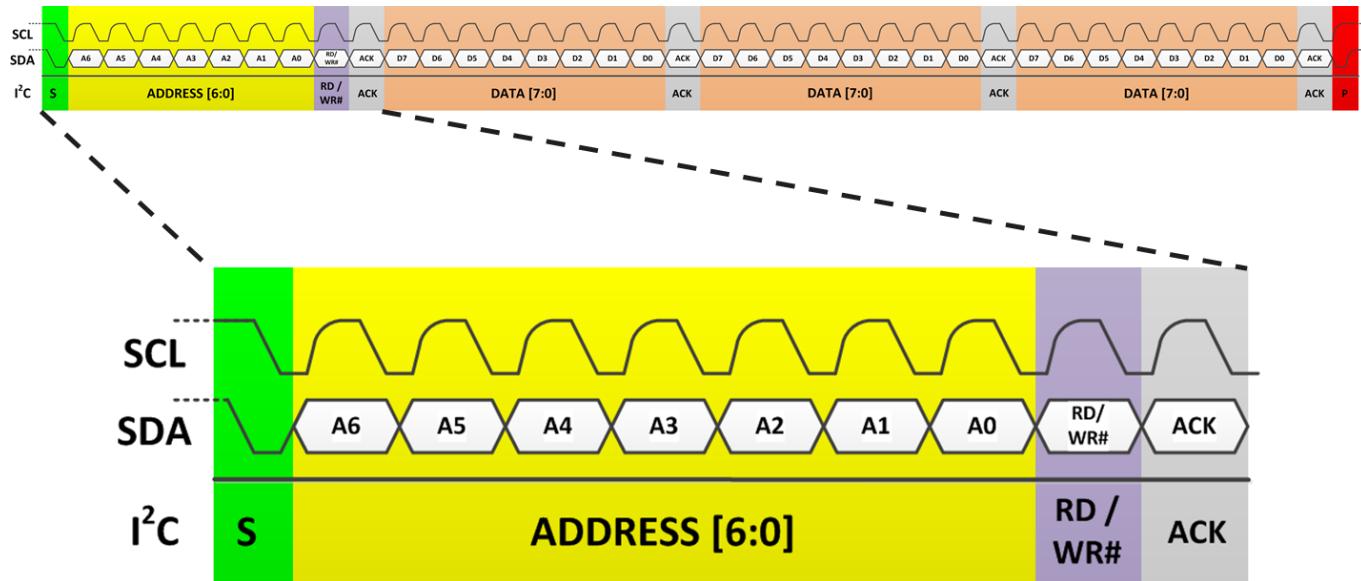
Figure 13-1. SPSC PMBus / SMBus Block Diagram

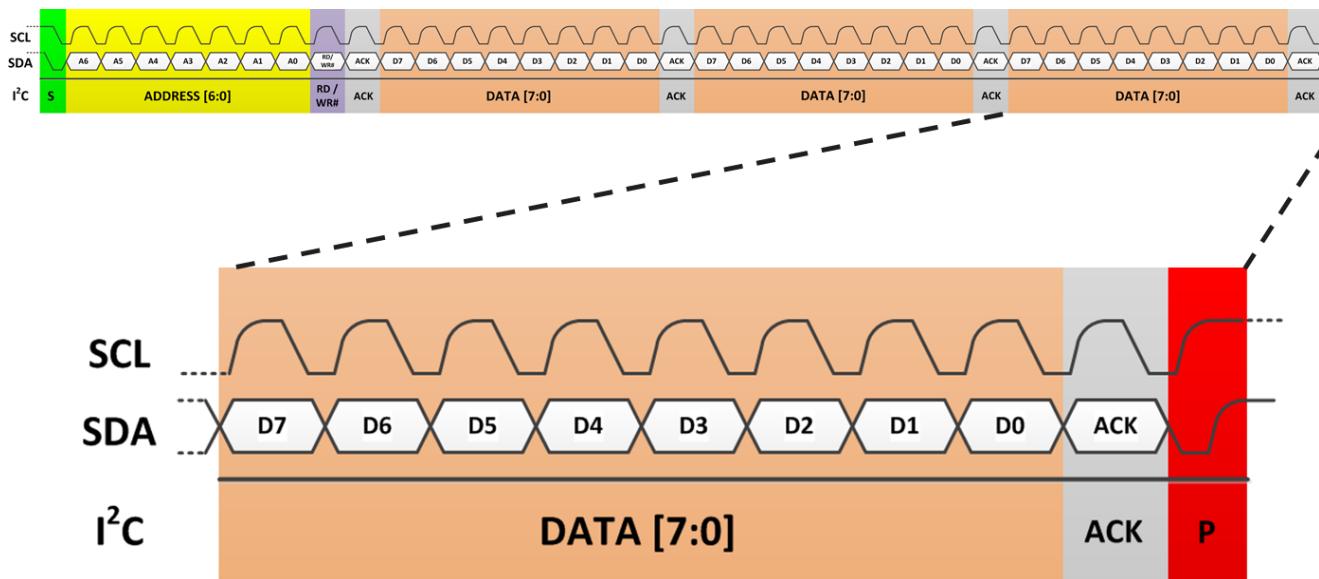


- PMBus™ Compliant Application Protocol
- SMBus (applied I²C) Compatible Physical Layer
- UT63PFD103 PMBus Enhancements for Space
 - Redundant for Space Application Reliability
 - ANDed Clock and Data Bus Lines
 - Multi-Slave / Multi-Master Data Bus
 - SPSC's are SLAVE ONLY
 - 400kHz Bus Frequency at up to 800pF Load
 - 12mA Sink Capability
 - Low Noise Slew Rate Controlled Driver
 - Falling Slew Rate: 15mV/ns → 135mV/ns
 - Low Drive di/dt: <1.18mA/ns
 - 5V Tolerant with Cold-Sparing (Cold-spare leakage <250nA)
 - Input Glitch Filter >50ns
 - 4kV ESD HBM

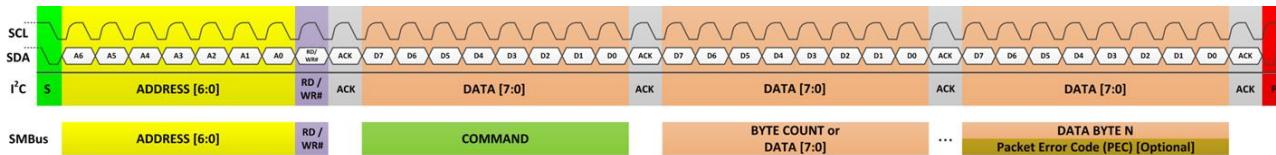
Figure 13-2. PMBus / SMBus System At a Glance

The I²C link level protocol is a very simple 2-wire, AND'ed protocol which starts with an ADDRESS and DATA Direction byte followed by a packet of data being READ or WRITTEN. The following figures present typical I²C communication. The SPSC supports 100 kbps Standard Mode (SM) and 400 kbps Fast-Mode (FM) I²C data rates.

Figure 13-3. I²C Address Byte Formatting

Figure 13-4. I²C Data Byte Formatting

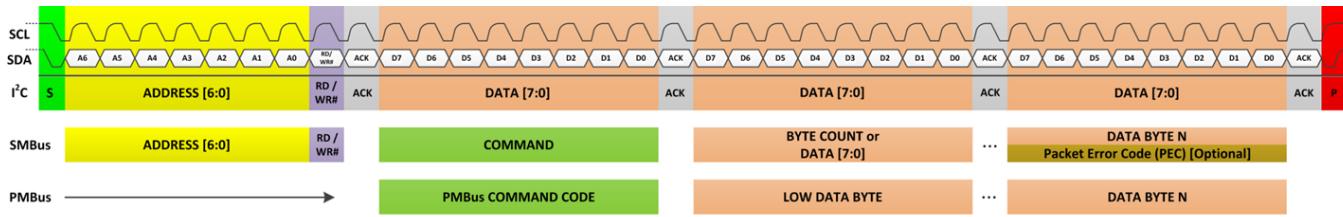
The SMBus protocol can be thought as "Applied I²C". The following figure summarizes the SMBus application of the I²C protocol for the purpose of facilitating PMBus™ interactions with the SPSC. For the purpose of fault tolerance, the SPSC supports a redundant pair of SMBus ports, each of which can coherently interact with the PMBus layer.



<u>ADDRESSING</u>	<u>COMMAND</u>	<u>PAYOUT</u>
<ul style="list-style-type: none"> • 7-bits • Host ID = 01 • 37 Reserved • 89 Slaves • Node Limit driven by: <ul style="list-style-type: none"> • Bus Cap • Slew Rate • VIL/VIH 	<ul style="list-style-type: none"> • Always WRITTEN to target • Followed by "Repeated Start" and Repeated Address for READ accesses 	<ul style="list-style-type: none"> • WRITE to Target <ul style="list-style-type: none"> • N-Data Bytes, or... • Byte Count + n-Data bytes • READ from Target <ul style="list-style-type: none"> • Repeated Start + RD Address + n-Data Bytes, or... • Repeated Start + RD Address + Byte Count + n-Data Bytes • Optionally, if supported, final byte is Packet Error Code (PEC)

Figure 13-5. SMBus Network Layer Protocol Formatting Summary

Finally, the PMBus Transport layer of the network stack manages the actual register manipulations within the SPSC for the purpose of configuring, controlling, and gathering data & telemetry from the SPSC. The SPSC supports 11 PMBus commands.



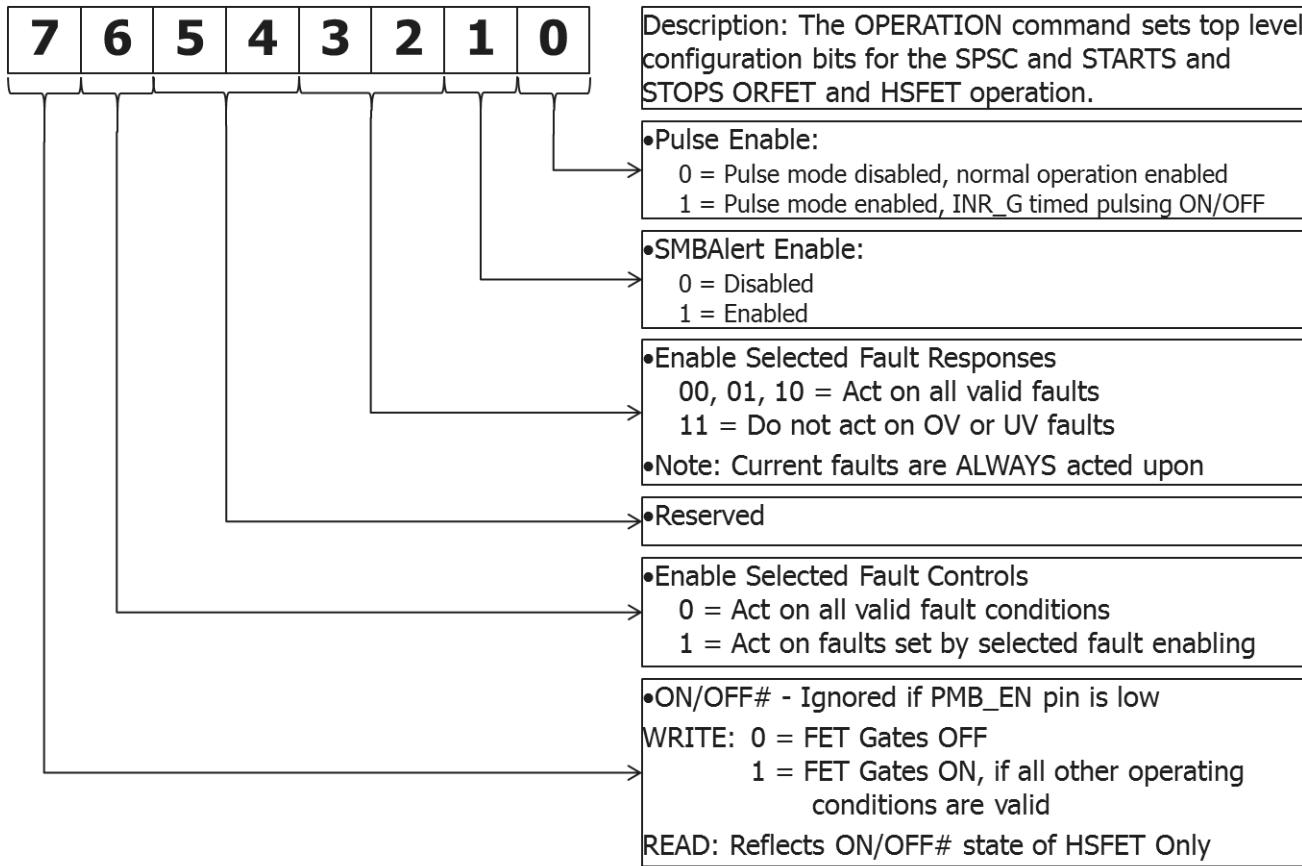
PMBus COMMAND and DATA Examples

Command Code	Command Name	Write Size	Read Size	PMBus Spec. Reference
01h	OPERATION	Write Byte	Read Byte	12.1
03h	CLEAR_FAULTS	N/A	N/A	15.1
19h	CAPABILITY	N/A	Read Byte	11.12
47h	IOUT_OC_FAULT_RESPONSE	Write Byte	Read Byte	15.9
7Ah	STATUS_VOUT	Write Byte	Read Byte	17.3
7Bh	STATUS_IOUT	Write Byte	Read Byte	17.4
7Ch	STATUS_INPUT	Write Byte	Read Byte	17.5
88h	READ_VIN	N/A	Read Word	18.1
8Bh	READ_VOUT	N/A	Read Word	18.4
8Ch	READ_IOUT	N/A	Read Word	18.5
D0h	GATE_OFF_DELAY	Write Byte	Read Byte	N/A
D1h	GATE_ON_DELAY	Write Byte	Read Byte	N/A

Figure 13-6. PMBus Protocol Formatting and Supported Commands

13.1.1 PMBus Command Definitions

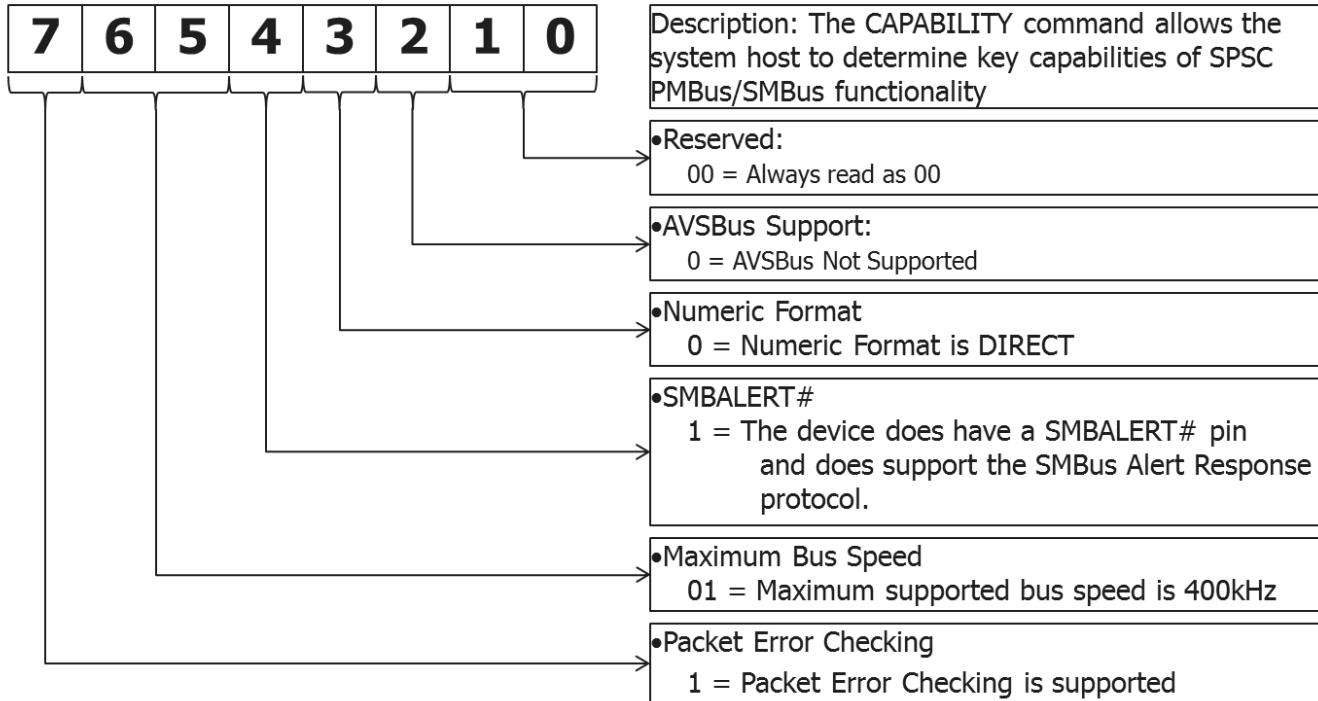
Command: 01h OPERATION (BYTE READ and WRITE)



Command: 03h CLEAR_FAULTS (WRITE-only / No Data Included)

- The CLEAR_FAULTS command is a WRITE-ONLY command with NO DATA included.
- The CLEAR_FAULTS command is used to clear any fault bits that have been set.
- This command clears all bits in all status registers simultaneously.
- At the same time, the device negates (clears, releases) its SMBALERT# signal output if the device is asserting the SMBALERT# signal.
- The CLEAR_FAULTS command does not cause a unit that has latched off for a fault condition to restart.
 - Units that have shut down for a fault condition are restarted by usual means.
 - If the fault is still present when the bit is cleared, the fault bit immediately sets again and the host is notified by the usual means.

Command: 19h CAPABILITY (BYTE READ)



Command: 47h IOUT_OC_FAULT_RESPONSE (BYTE READ and WRITE)

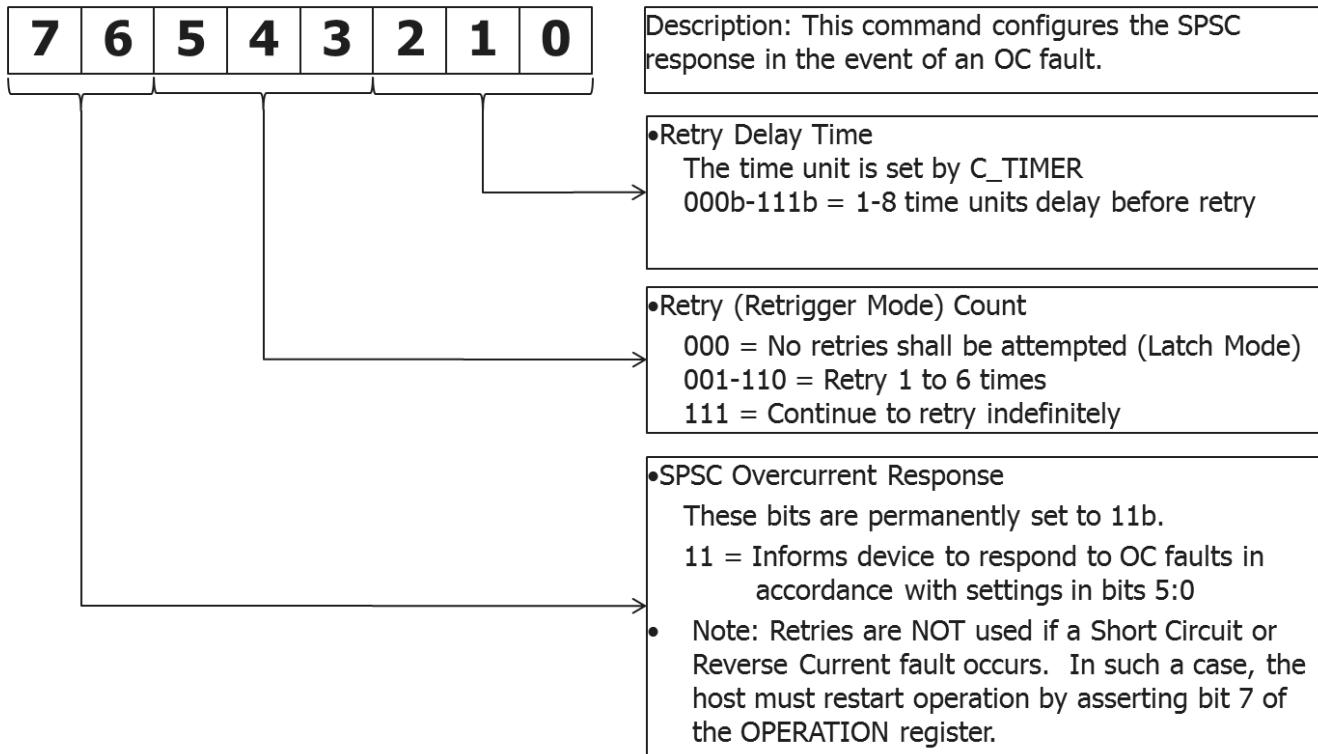
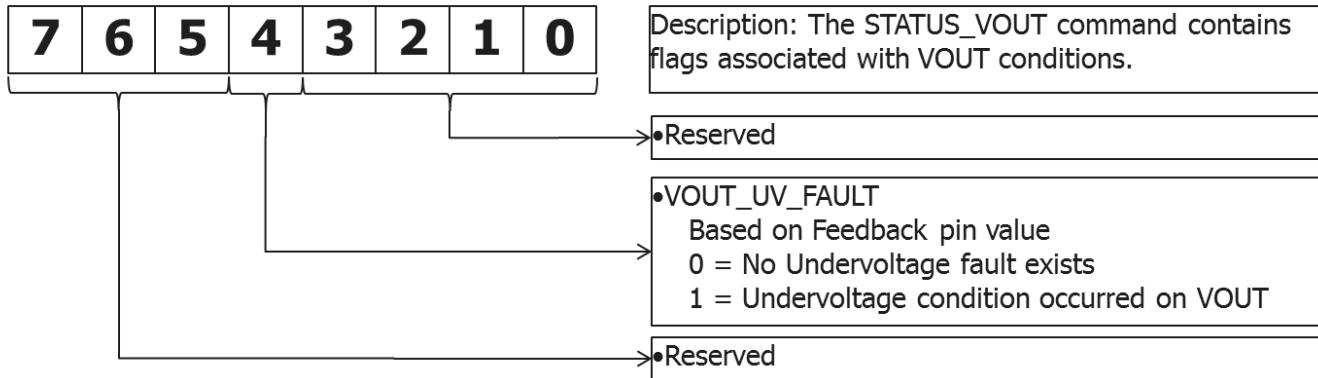


Table 13-1. Actual Retry Delay Values

Command 47H Retry_Delay Time Value	+ Delay Offset	= Actual Cool-off Period (# of CLK_ADJ Periods)
0 (000b)	+2.5 to +3.5	2.5 to 3.5
1 (001b)	+1.5 to +2.5	2.5 to 3.5
2 (010b)	+0.5 to +1.5	2.5 to 3.5
3 (011b)	+0.5 to +1.5	3.5 to 4.5
4 (100b)	+0.5 to +1.5	4.5 to 5.5
5 (101b)	+0.5 to +1.5	5.5 to 6.5
6 (110b)	+0.5 to +1.5	6.5 to 7.5
7 (111b)	+0.5 to +1.5	7.5 to 8.5

**Note that the typical delay offset of "0.5 to 1.5" is due to the sampling of the current fault latch on the next falling edge of the user's adjustable clock period (C_TIMER), following the 2-period sampling the SPSC's internal 1.5Mhz clock. The 1.5Mhz sampling is required to synchronize the current fault latch before turning off the G_INR FET driver.

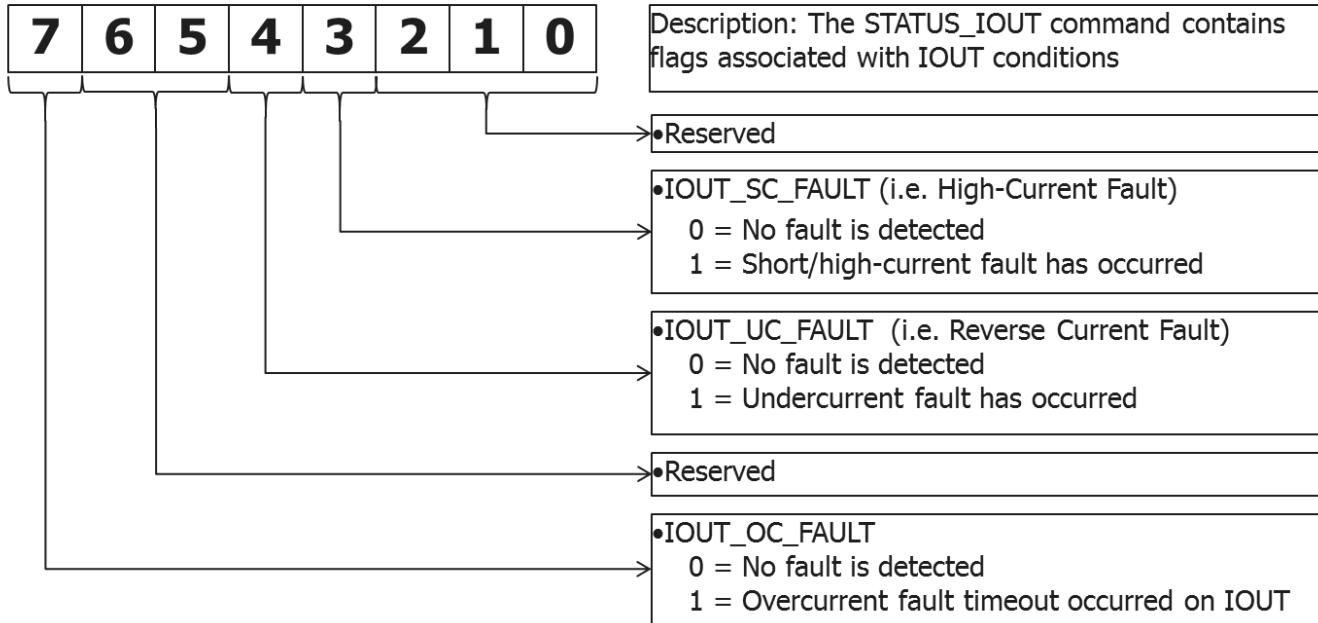
Command: 7Ah STATUS_VOUT (BYTE READ and WRITE)



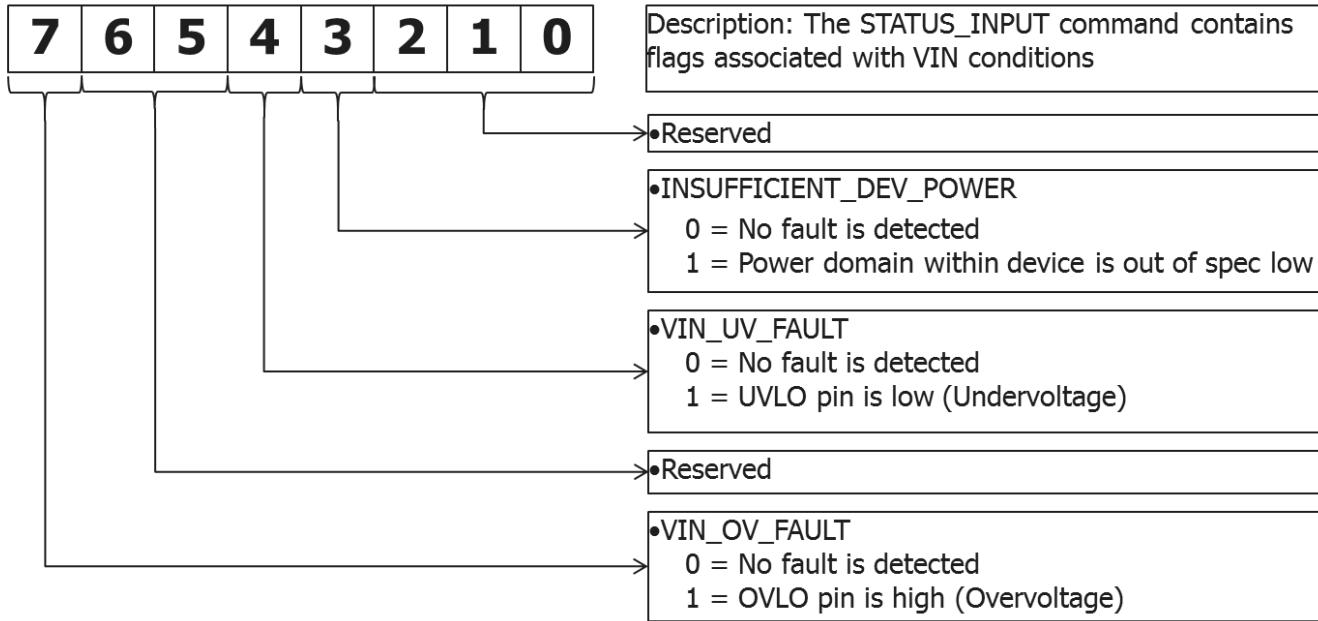
Notes:

- VOUT_UV_FAULT is ONLY set when the FEEDBACK input transitions from HIGH-to-LOW
- If no preceding fault exists at the time VOUT_UV_FAULT sets, then it will be the source of the SMBAlert# assertion

Command: 7Bh STATUS_IOUT (BYTE READ and WRITE)

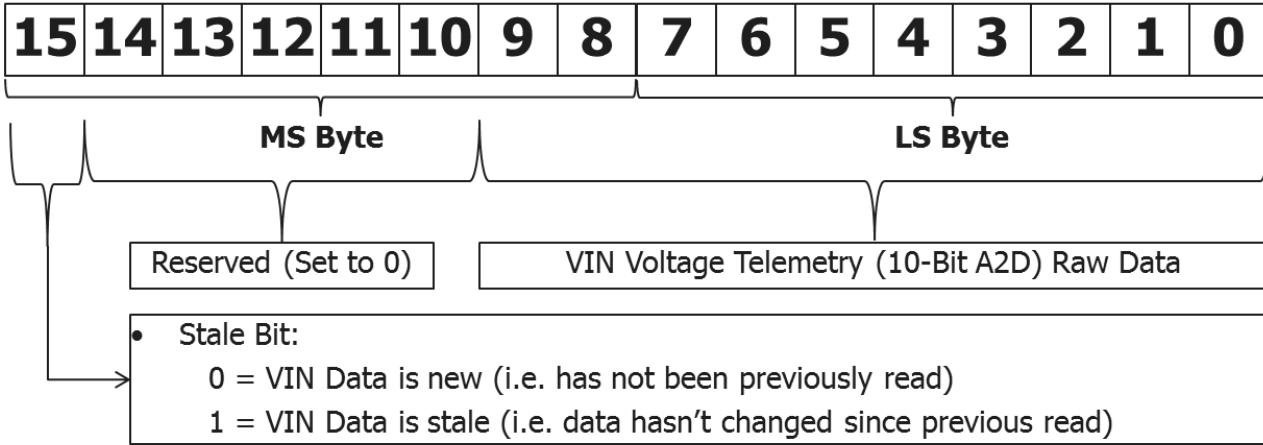


Command: 7Ch STATUS_INPUT (BYTE READ and WRITE)



Command: 88h READ_VIN (WORD READ-only)

Description: The READ_VIN command provides a two-byte (word) data value representing the converted output of the 10-bit A2D. Data is in the PMBus DIRECT data format.



$$X(V) = \frac{39.065mV}{bit} * READ_VIN_{10}$$

Example:

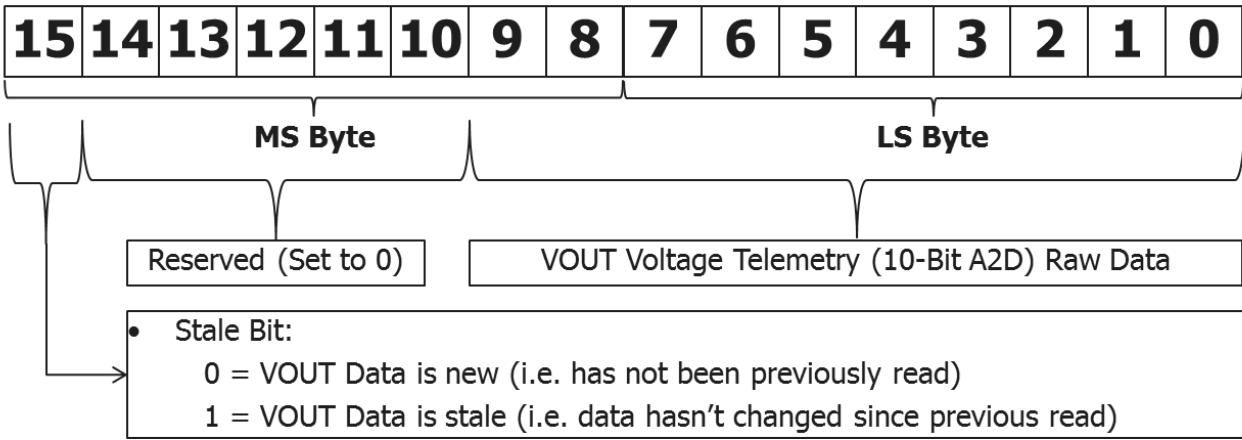
READ_VIN = 03FFh (1023₁₀) then:

$$X_{VIN} = .039065 * 1023 = 39.9635V$$

**Note: The data structure shown above is after constructing the 16-bit word received over the SMBus "READ WORD" protocol were data comes over the bus as LOW byte bits 7..0 followed by HIGH byte bits 15..8.

Command: 8Bh READ_VOUT (WORD READ-only)

Description: The READ_VOUT command provides a two-byte (word) data value representing the converted output of the 10-bit A2D. Data is in the PMBus DIRECT data format.



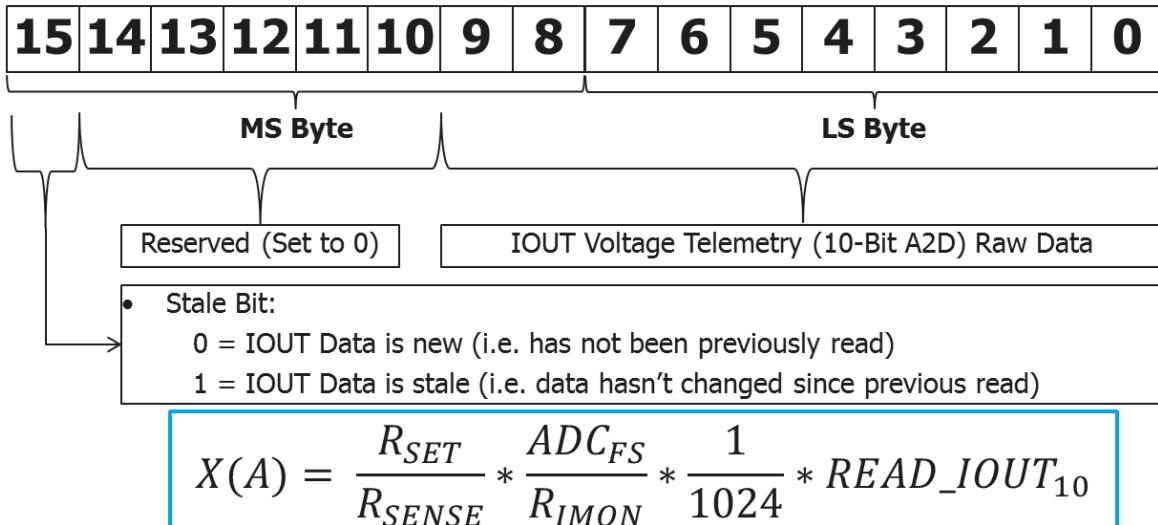
$$X(V) = \frac{39.065mV}{bit} * READ_VOUT_{10}$$

Example:
READ_VOUT = 02ADh (685₁₀) then:
 $X_{VOUT} = .039065 * 685 = 26.7595V$

**Note: The data structure shown above is after constructing the 16-bit word received over the SMBus "READ WORD" protocol where data comes over the bus as LOW byte bits 7..0 followed by HIGH byte bits 15..8.

Command: 8Ch READ_IOUT (WORD READ-only)

Description: The READ_IOUT command provides a two-byte (word) data value representing the converted output of the 10-bit A2D. Data is in the PMBus DIRECT data format.



$$X(A) = \frac{R_{SET}}{R_{SENSE}} * \frac{ADC_{FS}}{R_{IMON}} * \frac{1}{1024} * READ_IOUT_{10}$$

Example: $R_{SET} = 25\Omega$; $R_{SENSE} = 10m\Omega$; $R_{IMON} = 1.6k\Omega$; $ADC_{FS} = 2V$; $READ_IOUT = 0309h$ (777_{10}) then:

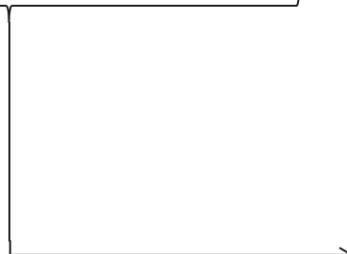
$$X_{IOUT} = \frac{25}{0.01} * \frac{2}{1600} * \frac{1}{1024} * 777 = 2.3712A$$

****Note:** The data structure shown above is after constructing the 16-bit word received over the SMBus "READ WORD" protocol where data comes over the bus as LOW byte bits 7..0 followed by HIGH byte bits 15..8.

Command: D0h GATE_OFF_DELAY

(BYTE READ and WRITE)

7	6	5	4	3	2	1	0
---	---	---	---	---	---	---	---



Description: The GATE_OFF_DELAY command sets the duration that the G_INR (Inrush FET Gate) is held in the "OFF" state.

- This command is only applicable when the PULSE_EN bit is set in the OPERATION register (OPERATION.0)

• GATE_OFF_DELAY Time Counter

The time unit is set by C_TIMER

00h = 1 Time Unit

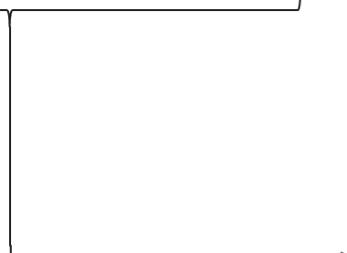
...

FFh = 256 Time Units

Command: D1h GATE_ON_DELAY

(BYTE READ and WRITE)

7	6	5	4	3	2	1	0
---	---	---	---	---	---	---	---



Description: The GATE_ON_DELAY command sets the duration that the G_INR (Inrush FET Gate) is held in the "ON" state.

- This command is only applicable when the PULSE_EN bit is set in the OPERATION register (OPERATION.0)

• GATE_ON_DELAY Time Counter

The time unit is set by C_TIMER

00h = 1 Time Unit

...

FFh = 256 Time Units

General Call Address: 00h / Command: 06h SOFT_RESET (WRITE-only)

Description: Address 00h is the General Call Address (GCA) which behaves as a "Broadcast" address to all slave devices that support the GCA. For the GCA, the SPSC supports only the SOFT_RESET command 06h.

Behavior:

- Upon receipt of the GCA with WRITE bit, the SPSC provides and ACK and observes the COMMAND byte. If the COMMAND byte is anything other than 06h, the SPSC will NACK the message and return to wait for a new START bit.
- If the COMMAND byte is 06H, the SPSC will ACK the COMMAND byte and observe for a STOP bit or a valid PEC byte to follow.
- After receipt of the STOP bit or valid PEC with STOP bit, the SPSC will execute the SOFT_RESET.
- SOFT_RESET results in the following SPSC actions:
 - All resettable flops in the SPSC digital macro are reset

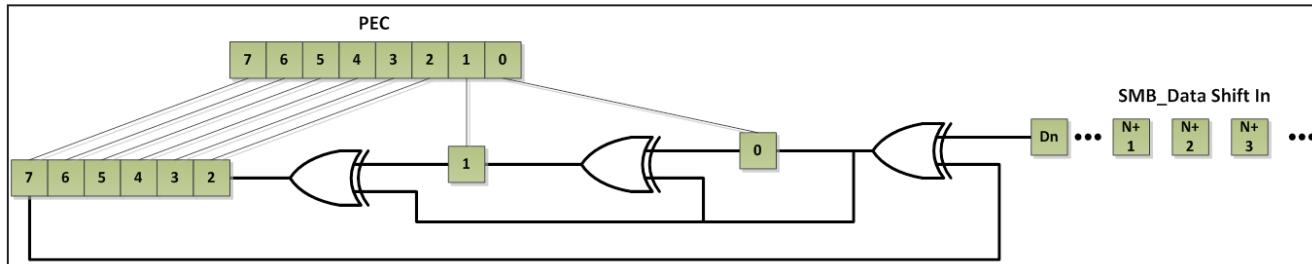
SMBus Packet Error Code (PEC)

- The UT36PFD103 Supports PEC verification on WRITE commands and PEC generation on READ commands
- SMBus PEC uses a CRC-8-CCITT algorithm

– https://en.wikipedia.org/wiki/Cyclic_redundancy_check

$$C(x) = x^8 + x^2 + x + 1$$

- Logically, the CRC-8 Algorithm can be implemented according to the following circuit diagram with the initialization value of **00H**:



- A simple C based algorithm using a CRC8 lookup table is located here:
 - <https://www.3dbrew.org/wiki/CRC-8-CCITT>

13.1.2 SMBus Ternary Addressing with Parity

Using 5 ternary address pins plus a binary parity pin, the SPSC supports addressing for every possible SMBus slave address. Unlike binary pins, ternary pins support three states: LOW, MID, HIGH. The choice of ternary IO was used to provide full 7-bit SMBus addressing with fewer pins. The SPSC supports PMBus™ plug & play through its implementation of the SMBus Address Resolution Protocol (ARP). If the SMBus address and parity are invalid or duplicate, the power SMBus host is responsible for ARP'ing to determine which valid terminals are connected to the bus and assign new addresses to terminals that have an invalid or duplicate address set by the switch bank. The SPSC only reads the state of its ADDR[4:0] and Parity inputs while in reset. The following table provides the ternary to decimal decoding of the address pins and associated odd parity. ODD parity is calculated against the binary equivalent of the decimal value for the device address.

Table 13-2. SMBus Address and Parity Decoding

Decimal Value	Ternary Pins (MSA:LSA)	Parity Switch	Decimal Value	Ternary Pins (MSA:LSA)	Parity Switch
16	LLMHM	LOGIC 0	70	LHMHM	LOGIC 0
17	LLMHH	LOGIC 1	71	LHMHH	LOGIC 1
18	LLHLL	LOGIC 1	76	LHHMM	LOGIC 0
19	LLHLM	LOGIC 0	77	LHHMH	LOGIC 1
20	LLHLH	LOGIC 1	78	LHHHL	LOGIC 1
21	LLHML	LOGIC 0	79	LHHHM	LOGIC 0
22	LLHMM	LOGIC 0	80	LHHHH	LOGIC 1
23	LLHMH	LOGIC 1	81	HLLLL	LOGIC 0
24	LLHHL	LOGIC 1	82	HLLLW	LOGIC 0
25	LLHHM	LOGIC 0	83	HLLLH	LOGIC 1
26	LLHHH	LOGIC 0	84	HLLML	LOGIC 0
27	LMLLL	LOGIC 1	85	HLLMM	LOGIC 1
28	LMLLM	LOGIC 0	86	HLLMH	LOGIC 1
29	LMLLH	LOGIC 1	87	HLLHL	LOGIC 0
30	LMMLM	LOGIC 1	88	HLLHM	LOGIC 0
31	LMMLM	LOGIC 0	89	HLLHH	LOGIC 1
32	LMMLH	LOGIC 0	90	HLMLL	LOGIC 1
33	LMLHL	LOGIC 1	91	HLMLM	LOGIC 0
34	LMLHM	LOGIC 1	92	HMLHL	LOGIC 1
35	LMLHH	LOGIC 0	93	HLMML	LOGIC 0
36	LMMLL	LOGIC 1	94	HLMMM	LOGIC 0
37	LMMLM	LOGIC 0	95	HLMMH	LOGIC 1
38	LMM LH	LOGIC 0	96	HLMHL	LOGIC 1
39	LMMML	LOGIC 1	98	HLMHH	LOGIC 0
41	LMMMH	LOGIC 0	99	HLHLL	LOGIC 1
42	LMMHL	LOGIC 0	100	HLHLM	LOGIC 0
43	LMMHM	LOGIC 1	101	HLHLH	LOGIC 1
46	LMHLM	LOGIC 1	102	HLHML	LOGIC 1
47	LMHLH	LOGIC 0	103	HLHMM	LOGIC 0
48	LMHML	LOGIC 1	104	HLHMH	LOGIC 0
49	LMHMM	LOGIC 0	105	HLHHL	LOGIC 1
50	LMHMH	LOGIC 0	106	HLHHM	LOGIC 1
51	LMHHL	LOGIC 1	107	HLHHH	LOGIC 0
52	LMHHM	LOGIC 0	108	HMLLL	LOGIC 1
53	LMHHH	LOGIC 1	109	HMLLM	LOGIC 0
54	LHLLL	LOGIC 1	110	HMLLH	LOGIC 0
56	LHLLH	LOGIC 0	111	HMLML	LOGIC 1
57	LHLML	LOGIC 1	112	HMLMM	LOGIC 0
58	LHLMM	LOGIC 1	113	HMLMH	LOGIC 1
59	LHLMH	LOGIC 0	114	HMLHL	LOGIC 1
60	LHLHL	LOGIC 1	115	HMLHM	LOGIC 0
61	LHLHM	LOGIC 0	116	HMLHH	LOGIC 1
62	LHLHH	LOGIC 0	117	HMMLL	LOGIC 0
63	LHM LL	LOGIC 1	118	HMMLM	LOGIC 0
69	LHMHL	LOGIC 0	119	HMM LH	LOGIC 1

13.1.3 SMBus Address Resolution Protocol (ARP) and Unique Device Identification (UDID)

One of the more advantageous features of PMBus/SMBus is the ability for the host controller to resolve address conflicts, enumerate the system, and dynamically assign new addresses to the target devices connected to the bus. These capabilities fall under the SMBus Address Resolution Protocol (ARP) facility. Refer to SMBus Standard Specification version 3.2, section 6.6, for full details on performing ARP. (https://470q2hhkn9g15l4bc2btba1-wpengine.netdna-ssl.com/wp-content/uploads/2022/01/SMBus_3_2_20220112.pdf).

The following lists some of the distinguishing traits of the SMBus ARP:

- Utilizes the SMBus physical layer arbitration mechanism (ref. SMBus Specification v3.2 section 5.3.2)
- Relies on target devices having a Unique Device Identification (UDID)
- Assigned addresses remain constant while target device is powered, but retention through power loss is allowed
- No additional SMBus packet overhead is incurred after address assignment
- Any SMBus host can enumerate the bus
- Devices supporting ARP also need to support Packet Error Code (PEC)

Although describing the details of the SMBus ARP is beyond the scope of this datasheet, the Smart Power Switch Controller UDID is appropriate to describe herein.

13.1.3.1 SPSC UDID

The SMBus Unique Device ID (UDID) is a 16 byte (128-bit) packet consisting of eight distinct fields. Table 13-3 depicts the SMBus UDID byte order and name of fields that make up the 16-byte UDID. The information provided by the various UDID fields serves two purposes. The first is they provide a unique code for each device connected to the SMBus network, which is essential for the host to leverage the SMBus arbitration mechanism and uniquely discover the individual devices connected to the bus. And secondly, some of the information gathered provides insight and knowledge for the host controller to understand the capabilities and relevant attributes regarding each device on the bus. A priori knowledge of expected device attributes can then be coded into the host controller's device management, or look-up tables, thereby affording it more intelligent configuration of devices connected to the SMBus network.

Table 13-3. SMBus 16-byte UDID Fields

MSB Byte 15	Byte 14	Byte 13	Byte 12	Byte 11	Byte 10	Byte 9	Byte 8
Device Capabilities	Version / Revision	Vendor ID		Device ID		Interface	
Byte 7	Byte 6	Byte 5	Byte 4	Byte 3	Byte 2	Byte 1	LSB Byte 0
Subsystem Vendor ID	Subsystem Device ID			Vendor Specific ID			

Because the full UDID contains deterministic and variable fields it is actually a pseudo-unique device identifier. Only the last 4 bytes of the UDID are expected to be truly unique (variable) amongst devices on an SMBus network. Table 13-4 provide a more detailed breakdown of the full UDID code and includes the constant and variable bit descriptions that are specific to the SPSC.

Table 13-4. UDID Byte Field Breakdown with SPSC Specific Bit Values

Bits	Byte(s)	SPSC Value	Field	Description
[127:120]	15	41h (8'b0100 0001)	Device Capabilities	<p>Address Type = 2'b01 (Dynamic & Persistent) Reserved = 5'b0 0000 PEC Supported = 1'b1 (Yes)</p> <p>*Note: If SPSC powers up with a TERNARY ADDRESS PARITY ERROR, the Address Type bits will switch to '2b10 indicating Dynamic & Volatile address type, and device will take on the DEFAULT SMBus address 61h (7b'110 0001). While using the DEFAULT address, the SPSC can only be addressed with the ARP GENERAL commands; it will not respond to DIRECTED ARP commands.</p>
[119:112]	14	08h (8'b0000 1000)	Version / Revision	<p>Reserved = 2'b 00 UDID Version = 3'b 001 (UDID Version 1) Silicon Revision = 3'b 000 (Initial Revision)</p>
[111:96]	[13:12]	1AD0h (16'b0001 1010 1101 0000)	Vendor ID	FRONTGRADE PCI SIG ID = 16'b 0001 1010 1101 0000
[95:80]	[11:10]	DC05h (16'b1101 1100 0000 0101)	Device ID	SPSC Die ID = 16'b 1101 1100 0000 0101
[79:64]	[9:8]	8005h (16'b1000 0000 0000 0101)	Interface	<p>Reserved bits [15:8] = 8'b 1000 0000 Zone bit [7] = 1'b 0 (Zone not supported) IPMI bit [6] = 1'b 0 (IPMI not supported) ASF bit [5] = 1'b 0 (ASF not supported) OEM bit [4] = 1'b 0 (No special vendor access) SMBus Version bits [3:0] = 4'b 0101 (Ver. 3.0)</p>
[63:48]	[7:6]	0000h (16'b 0000 0000 0000 0000)	Subsystem Vendor ID	ID = 16'b 0000 0000 0000 0000 (Not supported)
[47:32]	[5:4]	0000h (16'b 0000 0000 0000 0000)	Subsystem Device ID	ID = 16'b 0000 0000 0000 0000 (Not supported)
[31:0]	[3:0]	00XXXXYYh (32'b 0000 0000 xxxx xxxx xxxx xxxx yyyy yyyy0)	Vendor Specific ID (Note 1)	<p>Byte [3] = 8'b 0000 0000 (Default to 00h) Bytes [2:1] = 16'b xxxx xxxx xxxx xxxx (Counter) Byte [0] = 8'b yyyy yyyy0 (Ternary Address)</p>

- Note 1: The 32-bit Vendor Specific ID is designed to produce a unique code within the full 128-bit UDID. Recognizing that all bytes 15 down to 3 are mask programmed (i.e. permanent) in the SPSC, the final three bytes are the only variable portion of the UDID and are expected to change with each power-up or master reset of the SPSC. Beginning with the counter represented in bytes [2:1], a free running counter based on an internal RC oscillator runs while the SPSC is in reset and is latched into these bytes when reset is de-asserted. The last byte [0] contains the device's SMBus Address as set by the Ternary Address pins (ADDR[4:0]). It is assumed that during PCB assembly, the user application will pin strap the ternary addresses to create unique and purposeful addresses for each SPSC on the SMBus network. If the pin strapped address plus parity do not agree or result in an invalid (i.e. reserved) SMBus address, the SPSC will take on the SMBus Default Address 61h (7b'110 0001). If the SPSC in question is using the default address, then ARP commands can only use GENERAL command format to the device until a working address is assigned to the SPSC. If the SPSC in question has a known assigned SMBus address, then ARP commands to the device can use the DIRECTED format. Reference SMBus Specification section 6.6.3 for more details regarding GENERAL and DIRECTED ARP commands.

13.1.3.2 SPSC Response to GET UDID Commands (GENERAL and DIRECTED)

While the UDID code consists of 16-bytes, the SMBus host controller performing an ARP GET UDID command in both the GENERAL and DIRECTED formats will result in 22-byte packets; with only a small variation in the second (2nd) and twenty-first (21st) bytes of the packet. If the application will employ ARP, it is strongly recommended that the software engineer thoroughly read section 6.6 and the corresponding subsections of the SMBus standard specification. As a means to help the software engineer decipher the GET UDID packets from the SPSC, Figure 13-7 and Figure 13-8 depict the GENERAL and DIRECTED GET UDID byte values expected from the SPSC, respectively. Note, the gray shading in the two SMBus packet diagrams indicate a data bit driven by the SMBus target device and unshaded bits are driven by the SMBus host. This is consistent with the diagram shading convention used by the SMBus specification.

Start	Default Address (61h)	WR	Ack	GET UDID Command (03h)	Ack	
S	1 1 0 0 0 0 1 0 0 0 0 0 0 1 1 0 ...					
Byte 0			Byte 1			
Repeated Start	Default Address (61h)	RD	Ack	Byte Count (11h)	Ack	
SR	1 1 0 0 0 0 1 1 0 0 0 0 1 0 0 0 1 0 ...					
Byte 2			Byte 3			
Device Capabilities (41h)	Ack	Version/Revision (08h)	Ack	Vendor ID MSB (1Ah)	Ack	Vendor ID LSB (D0h)
0 1 0 0 0 0 0 1 0 0 0 0 0 1 0 0 0 0 0 1 1 0 1 0 0 0 0 0 ...						
Byte 4 (UDID Byte 15)			Byte 5 (UDID Byte 14)			Byte 7 (UDID Byte 12)
Device ID MSB (DCh)	Ack	Device ID LSB (05h)	Ack	Interface MSB (80h)	Ack	Interface LSB (05h)
1 1 0 1 1 1 0 0 0 0 0 0 1 0 1 0 1 0 0 0 1 1 0 1 0 1 0 ...						
Byte 8 (UDID Byte 11)			Byte 9 (UDID Byte 10)			Byte 11 (UDID Byte 8)
Subsystem Vendor ID MSB (00h)	Ack	Subsystem Vendor ID LSB (00h)	Ack	Subsystem Device ID MSB (00h)	Ack	Subsystem Device ID LSB (00h)
0 ...						
Byte 12 (UDID Byte 7)			Byte 13 (UDID Byte 6)			Byte 15 (UDID Byte 4)
Vendor Specific ID MSB (00h)	Ack	Vendor Specific ID COUNTER MSB (XXh)	Ack	Vendor Specific ID COUNTER LSB (XXh)	Ack	Ternary Address (e.g. [7:1] = 29h & [0] = 1'b 0)
0 0 0 0 0 0 0 0 0 x x x x x x x x 0 x x x x x x x 0 0 1 0 1 0 0 ...						
Byte 16 (UDID Byte 3)			Byte 17 (UDID Byte 2)			Byte 19 (UDID Byte 0)
Byte 20			Byte 21			
Device Target Address (e.g. [7:1] = 29h & [0] = 1'b 1) or No Valid Address (FFh)	Ack	Packet Error Code (Calculated PEC)	Nack	Stop		
0 1 0 1 0 0 1 1 0 z z z z z z z z 1 P						

Figure 13-7. ARP **GENERAL** GET UDID Command with SPSC Ternary Address 29h (41 decimal)

Start	Default Address (61h)		WR	Ack	Targeted Device Address (e.g. [7:1] = 29h & [0] = 1'b 1)		Ack
S	1	1	0	0	0	0	1
	Byte 0		Byte 1		0	0	1
Repeated Start	Default Address (61h)		RD	Ack	Byte Count (11h)		Ack
SR	1	1	0	0	0	0	1
	Byte 2		Byte 3		0	0	0
Device Capabilities (41h)		Ack	Version/Revision (08h)		Ack	Vendor ID MSB (1Ah)	
0	1	0	0	0	0	0	1
	Byte 4 (UDID Byte 15)		Byte 5 (UDID Byte 14)		Byte 6 (UDID Byte 13)		0
Byte 7 (UDID Byte 12)		Byte 8 (UDID Byte 11)		Byte 9 (UDID Byte 10)		Byte 10 (UDID Byte 9)	
Byte 11 (UDID Byte 8)		Byte 12 (UDID Byte 7)		Byte 13 (UDID Byte 6)		Byte 14 (UDID Byte 5)	
Byte 15 (UDID Byte 4)		Byte 16 (UDID Byte 3)		Byte 17 (UDID Byte 2)		Byte 18 (UDID Byte 1)	
Byte 19 (UDID Byte 0)		Device ID MSB (DCh)		Ack	Device ID LSB (05h)		Ack
1	1	0	1	1	1	0	0
	Byte 20		Byte 21		Interface MSB (80h)		Ack
Interface LSB (05h)		Byte 22 (UDID Byte 19)		Byte 23 (UDID Byte 18)		Byte 24 (UDID Byte 17)	
Byte 25 (UDID Byte 16)		Byte 26 (UDID Byte 15)		Byte 27 (UDID Byte 14)		Byte 28 (UDID Byte 13)	
Byte 29 (UDID Byte 12)		Byte 30 (UDID Byte 11)		Byte 31 (UDID Byte 10)		Byte 32 (UDID Byte 9)	
Byte 33 (UDID Byte 8)		Byte 34 (UDID Byte 7)		Byte 35 (UDID Byte 6)		Byte 36 (UDID Byte 5)	
Byte 37 (UDID Byte 4)		Byte 38 (UDID Byte 3)		Byte 39 (UDID Byte 2)		Byte 40 (UDID Byte 1)	
Byte 41 (UDID Byte 0)		Byte 42 (UDID Byte 19)		Byte 43 (UDID Byte 18)		Byte 44 (UDID Byte 17)	
Byte 45 (UDID Byte 16)		Byte 46 (UDID Byte 15)		Byte 47 (UDID Byte 14)		Byte 48 (UDID Byte 13)	
Byte 49 (UDID Byte 12)		Byte 50 (UDID Byte 11)		Byte 51 (UDID Byte 10)		Byte 52 (UDID Byte 9)	
Byte 53 (UDID Byte 8)		Byte 54 (UDID Byte 7)		Byte 55 (UDID Byte 6)		Byte 56 (UDID Byte 5)	
Byte 57 (UDID Byte 4)		Byte 58 (UDID Byte 3)		Byte 59 (UDID Byte 2)		Byte 60 (UDID Byte 1)	
Byte 61 (UDID Byte 0)		Byte 62 (UDID Byte 19)		Byte 63 (UDID Byte 18)		Byte 64 (UDID Byte 17)	
Byte 65 (UDID Byte 16)		Byte 66 (UDID Byte 15)		Byte 67 (UDID Byte 14)		Byte 68 (UDID Byte 13)	
Byte 69 (UDID Byte 12)		Byte 70 (UDID Byte 11)		Byte 71 (UDID Byte 10)		Byte 72 (UDID Byte 9)	
Byte 73 (UDID Byte 8)		Byte 74 (UDID Byte 7)		Byte 75 (UDID Byte 6)		Byte 76 (UDID Byte 5)	
Byte 77 (UDID Byte 4)		Byte 78 (UDID Byte 3)		Byte 79 (UDID Byte 2)		Byte 80 (UDID Byte 1)	
Byte 81 (UDID Byte 0)		Byte 82 (UDID Byte 19)		Byte 83 (UDID Byte 18)		Byte 84 (UDID Byte 17)	
Byte 85 (UDID Byte 16)		Byte 86 (UDID Byte 15)		Byte 87 (UDID Byte 14)		Byte 88 (UDID Byte 13)	
Byte 89 (UDID Byte 12)		Byte 90 (UDID Byte 11)		Byte 91 (UDID Byte 10)		Byte 92 (UDID Byte 9)	
Byte 93 (UDID Byte 8)		Byte 94 (UDID Byte 7)		Byte 95 (UDID Byte 6)		Byte 96 (UDID Byte 5)	
Byte 97 (UDID Byte 4)		Byte 98 (UDID Byte 3)		Byte 99 (UDID Byte 2)		Byte 100 (UDID Byte 1)	
Byte 101 (UDID Byte 0)		Byte 102 (UDID Byte 19)		Byte 103 (UDID Byte 18)		Byte 104 (UDID Byte 17)	
Byte 105 (UDID Byte 16)		Byte 106 (UDID Byte 15)		Byte 107 (UDID Byte 14)		Byte 108 (UDID Byte 13)	
Byte 109 (UDID Byte 12)		Byte 110 (UDID Byte 11)		Byte 111 (UDID Byte 10)		Byte 112 (UDID Byte 9)	
Byte 113 (UDID Byte 8)		Byte 114 (UDID Byte 7)		Byte 115 (UDID Byte 6)		Byte 116 (UDID Byte 5)	
Byte 117 (UDID Byte 4)		Byte 118 (UDID Byte 3)		Byte 119 (UDID Byte 2)		Byte 120 (UDID Byte 1)	
Byte 121 (UDID Byte 0)		Byte 122 (UDID Byte 19)		Byte 123 (UDID Byte 18)		Byte 124 (UDID Byte 17)	
Byte 125 (UDID Byte 16)		Byte 126 (UDID Byte 15)		Byte 127 (UDID Byte 14)		Byte 128 (UDID Byte 13)	
Byte 129 (UDID Byte 12)		Byte 130 (UDID Byte 11)		Byte 131 (UDID Byte 10)		Byte 132 (UDID Byte 9)	
Byte 133 (UDID Byte 8)		Byte 134 (UDID Byte 7)		Byte 135 (UDID Byte 6)		Byte 136 (UDID Byte 5)	
Byte 137 (UDID Byte 4)		Byte 138 (UDID Byte 3)		Byte 139 (UDID Byte 2)		Byte 140 (UDID Byte 1)	
Byte 141 (UDID Byte 0)		Byte 142 (UDID Byte 19)		Byte 143 (UDID Byte 18)		Byte 144 (UDID Byte 17)	
Byte 145 (UDID Byte 16)		Byte 146 (UDID Byte 15)		Byte 147 (UDID Byte 14)		Byte 148 (UDID Byte 13)	
Byte 149 (UDID Byte 12)		Byte 150 (UDID Byte 11)		Byte 151 (UDID Byte 10)		Byte 152 (UDID Byte 9)	
Byte 153 (UDID Byte 8)		Byte 154 (UDID Byte 7)		Byte 155 (UDID Byte 6)		Byte 156 (UDID Byte 5)	
Byte 157 (UDID Byte 4)		Byte 158 (UDID Byte 3)		Byte 159 (UDID Byte 2)		Byte 160 (UDID Byte 1)	
Byte 161 (UDID Byte 0)		Byte 162 (UDID Byte 19)		Byte 163 (UDID Byte 18)		Byte 164 (UDID Byte 17)	
Byte 165 (UDID Byte 16)		Byte 166 (UDID Byte 15)		Byte 167 (UDID Byte 14)		Byte 168 (UDID Byte 13)	
Byte 169 (UDID Byte 12)		Byte 170 (UDID Byte 11)		Byte 171 (UDID Byte 10)		Byte 172 (UDID Byte 9)	
Byte 173 (UDID Byte 8)		Byte 174 (UDID Byte 7)		Byte 175 (UDID Byte 6)		Byte 176 (UDID Byte 5)	
Byte 177 (UDID Byte 4)		Byte 178 (UDID Byte 3)		Byte 179 (UDID Byte 2)		Byte 180 (UDID Byte 1)	
Byte 181 (UDID Byte 0)		Byte 182 (UDID Byte 19)		Byte 183 (UDID Byte 18)		Byte 184 (UDID Byte 17)	
Byte 185 (UDID Byte 16)		Byte 186 (UDID Byte 15)		Byte 187 (UDID Byte 14)		Byte 188 (UDID Byte 13)	
Byte 189 (UDID Byte 12)		Byte 190 (UDID Byte 11)		Byte 191 (UDID Byte 10)		Byte 192 (UDID Byte 9)	
Byte 193 (UDID Byte 8)		Byte 194 (UDID Byte 7)		Byte 195 (UDID Byte 6)		Byte 196 (UDID Byte 5)	
Byte 197 (UDID Byte 4)		Byte 198 (UDID Byte 3)		Byte 199 (UDID Byte 2)		Byte 200 (UDID Byte 1)	
Byte 201 (UDID Byte 0)		Byte 202 (UDID Byte 19)		Byte 203 (UDID Byte 18)		Byte 204 (UDID Byte 17)	
Byte 205 (UDID Byte 16)		Byte 206 (UDID Byte 15)		Byte 207 (UDID Byte 14)		Byte 208 (UDID Byte 13)	
Byte 209 (UDID Byte 12)		Byte 210 (UDID Byte 11)		Byte 211 (UDID Byte 10)		Byte 212 (UDID Byte 9)	
Byte 213 (UDID Byte 8)		Byte 214 (UDID Byte 7)		Byte 215 (UDID Byte 6)		Byte 216 (UDID Byte 5)	
Byte 217 (UDID Byte 4)		Byte 218 (UDID Byte 3)		Byte 219 (UDID Byte 2)		Byte 220 (UDID Byte 1)	
Byte 221 (UDID Byte 0)		Byte 222 (UDID Byte 19)		Byte 223 (UDID Byte 18)		Byte 224 (UDID Byte 17)	
Byte 225 (UDID Byte 16)		Byte 226 (UDID Byte 15)		Byte 227 (UDID Byte 14)		Byte 228 (UDID Byte 13)	
Byte 229 (UDID Byte 12)		Byte 230 (UDID Byte 11)		Byte 231 (UDID Byte 10)		Byte 232 (UDID Byte 9)	
Byte 233 (UDID Byte 8)		Byte 234 (UDID Byte 7)		Byte 235 (UDID Byte 6)		Byte 236 (UDID Byte 5)	
Byte 237 (UDID Byte 4)		Byte 238 (UDID Byte 3)		Byte 239 (UDID Byte 2)		Byte 240 (UDID Byte 1)	
Byte 241 (UDID Byte 0)		Byte 242 (UDID Byte 19)		Byte 243 (UDID Byte 18)		Byte 244 (UDID Byte 17)	
Byte 245 (UDID Byte 16)		Byte 246 (UDID Byte 15)		Byte 247 (UDID Byte 14)		Byte 248 (UDID Byte 13)	
Byte 249 (UDID Byte 12)		Byte 250 (UDID Byte 11)		Byte 251 (UDID Byte 10)		Byte 252 (UDID Byte 9)	
Byte 253 (UDID Byte 8)		Byte 254 (UDID Byte 7)		Byte 255 (UDID Byte 6)		Byte 256 (UDID Byte 5)	
Byte 257 (UDID Byte 4)		Byte 258 (UDID Byte 3)		Byte 259 (UDID Byte 2)		Byte 260 (UDID Byte 1)	
Byte 261 (UDID Byte 0)		Byte 262 (UDID Byte 19)		Byte 263 (UDID Byte 18)		Byte 264 (UDID Byte 17)	
Byte 265 (UDID Byte 16)		Byte 266 (UDID Byte 15)		Byte 267 (UDID Byte 14)		Byte 268 (UDID Byte 13)	
Byte 269 (UDID Byte 12)		Byte 270 (UDID Byte 11)		Byte 271 (UDID Byte 10)		Byte 272 (UDID Byte 9)	
Byte 273 (UDID Byte 8)		Byte 274 (UDID Byte 7)		Byte 275 (UDID Byte 6)		Byte 276 (UDID Byte 5)	
Byte 277 (UDID Byte 4)		Byte 278 (UDID Byte 3)		Byte 279 (UDID Byte 2)		Byte 280 (UDID Byte 1)	
Byte 281 (UDID Byte 0)		Byte 282 (UDID Byte 19)		Byte 283 (UDID Byte 18)		Byte 284 (UDID Byte 17)	
Byte 285 (UDID Byte 16)		Byte 286 (UDID Byte 15)		Byte 287 (UDID Byte 14)		Byte 288 (UDID Byte 13)	
Byte 289 (UDID Byte 12)		Byte 290 (UDID Byte 11)		Byte 291 (

14 Application Configurations

Figure 14-1 presents the essential configuration of the SPSC proving Load-Switch control with inrush current limiting and eFuse protection for current and voltage faults. In this application scenario a single discrete command is provided by power system manager to enable/disable device operation. Two digital flags are also provided to the system manager to indicate when a current limit fault has occurred and when the monitored power rails are all good.

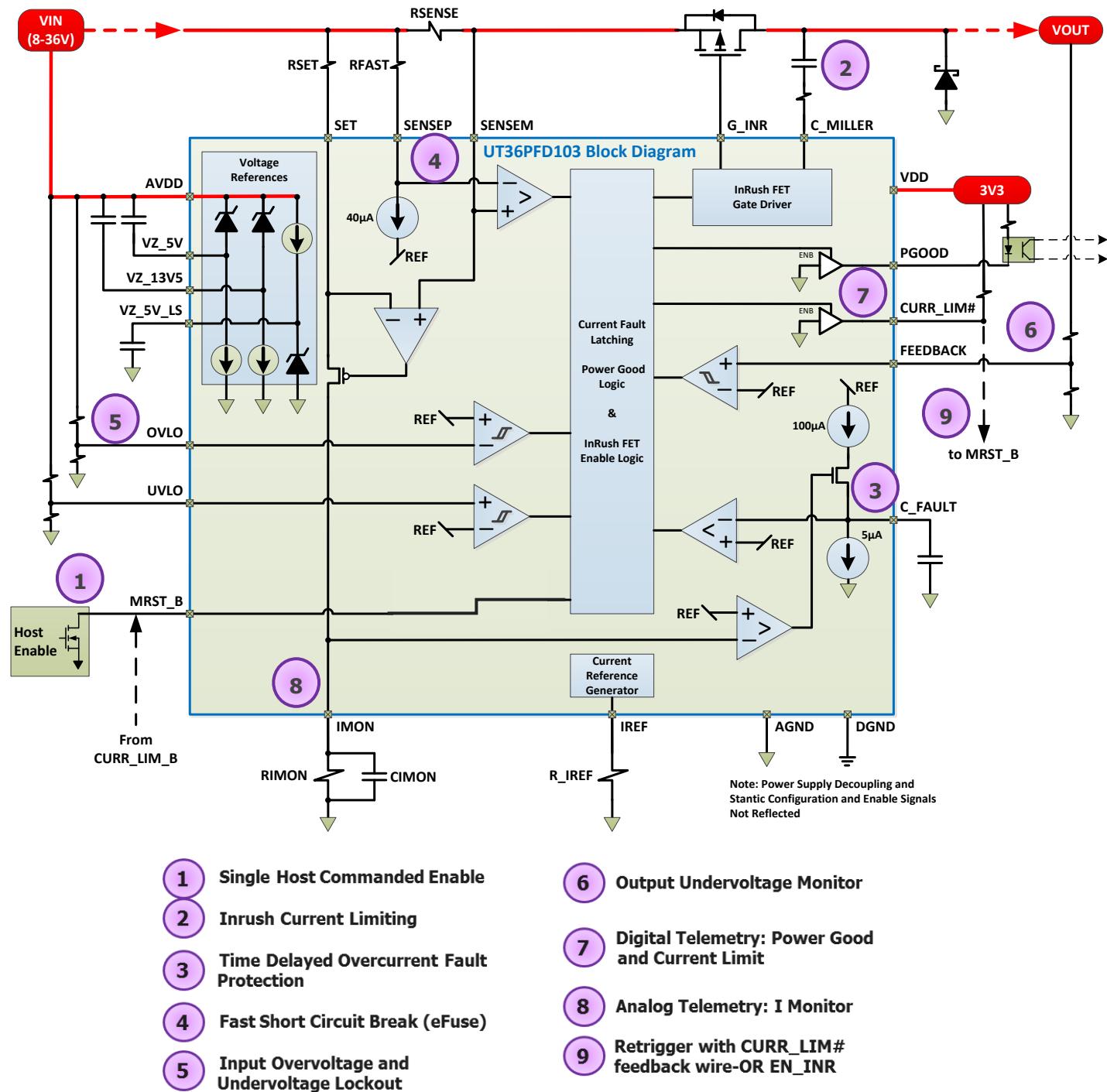


Figure 14-1. Essential Hot Swap Controller Configuration with eFuse Fault Protection

Although power system manager command and control of the SPSC is not depicted, Figure 14-2 demonstrates the efficient routing of essential analog and switch control signals when providing inrush current limited, hot swap control with eFuse protection and an added ORing FET acting as an Ideal Diode. For this application, the EN_B, EN_INR and EN_OR pins could be strapped to automatically enable power switching control or alternatively they could be driven by the power system manager.

If digitized telemetry and more detailed status information is required, employ PMBus functionality by interfacing system manager containing an I²C serial port to the SPSC SMBus port. The available digitized telemetry includes 10-bit, single ended representation of the IMON pin, and a scaled representation of the voltage on VIN and VOUT.

To disable the PMBus feature on the SPSC, simply ground the PMB_EN input. All other PMBus related signals may be left floating.

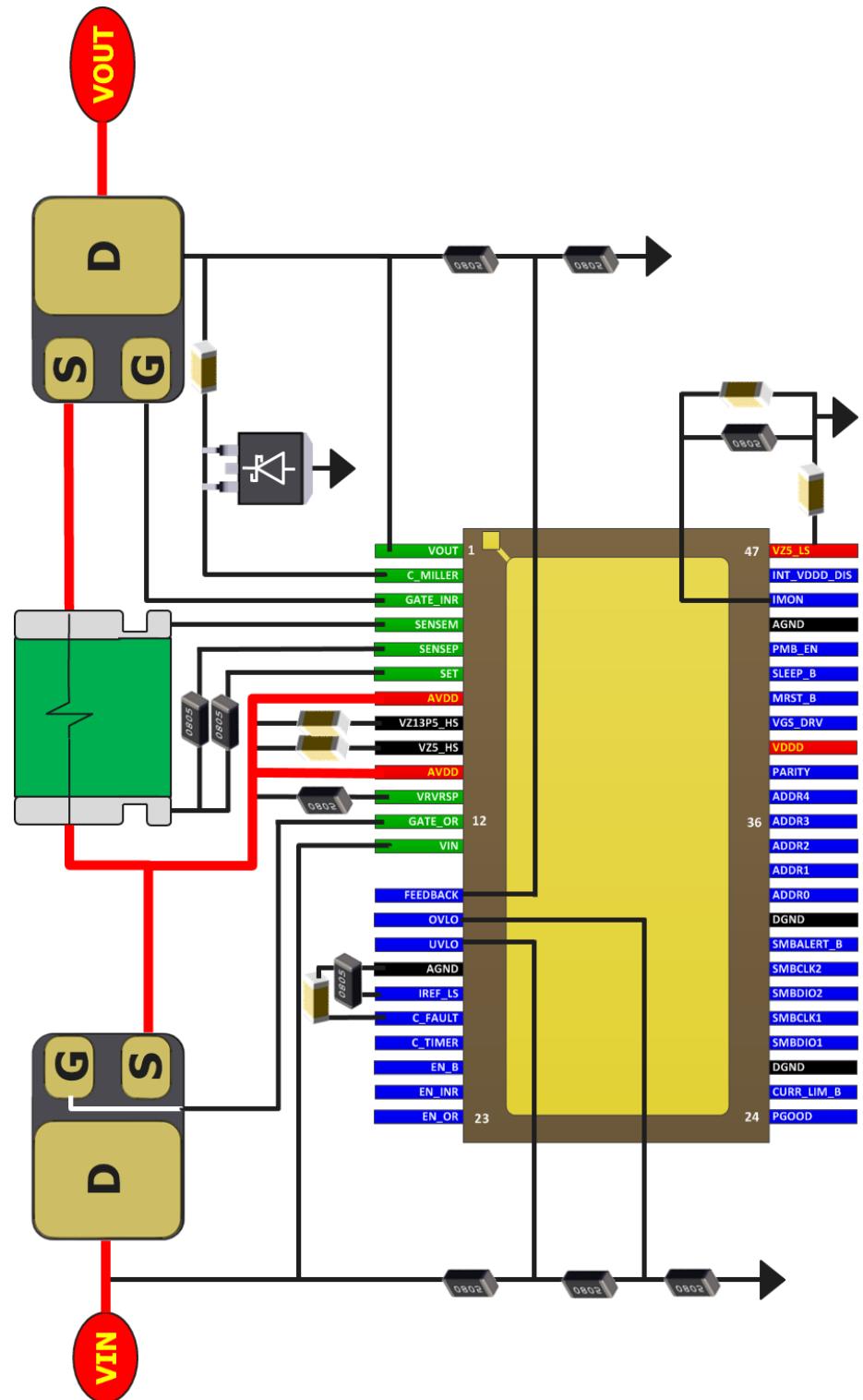


Figure 14-2. Essential SPSC Load-Switch control with eFuse protection and Ideal Diode

15 Packaging Drawings

(Package Mass = 2.3gm)

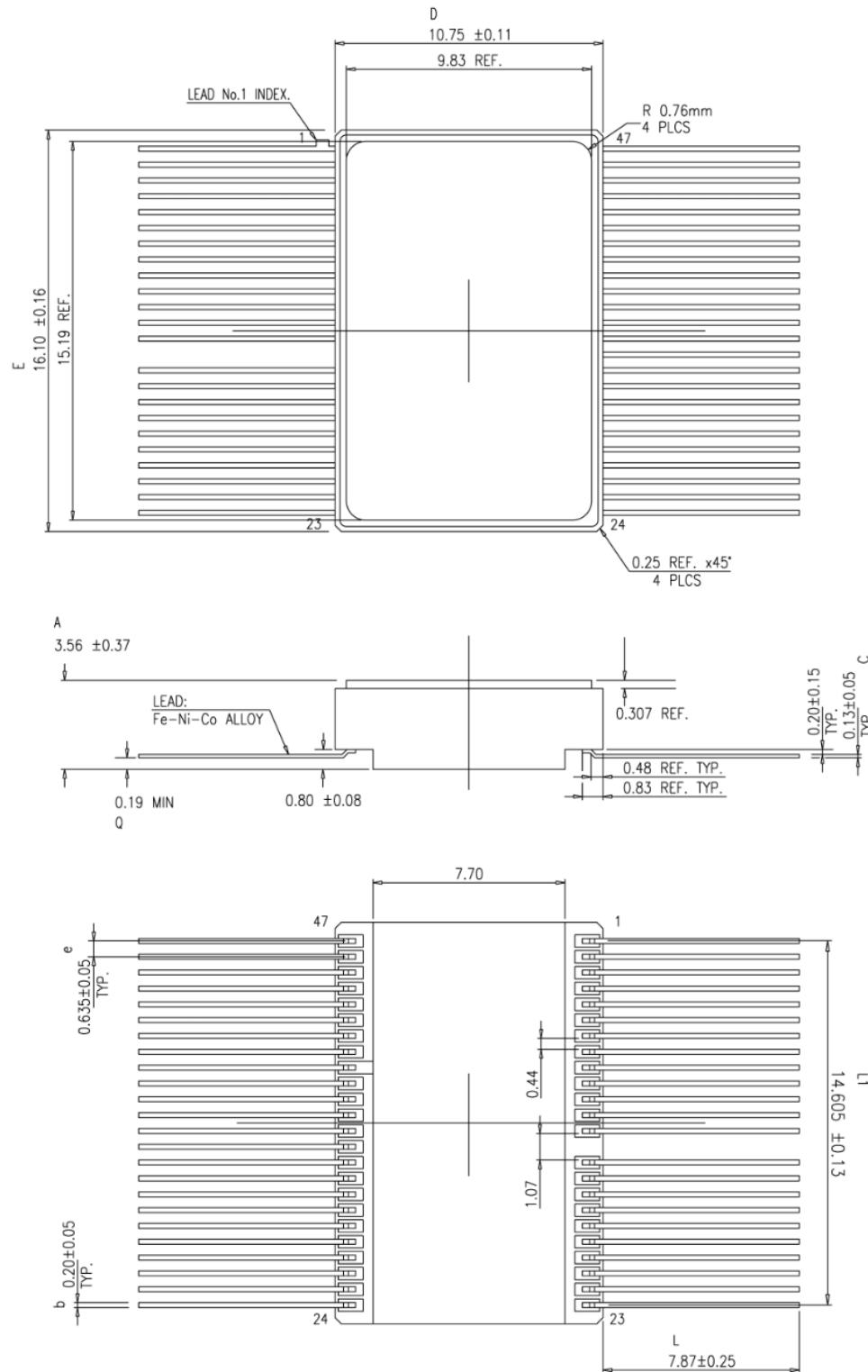
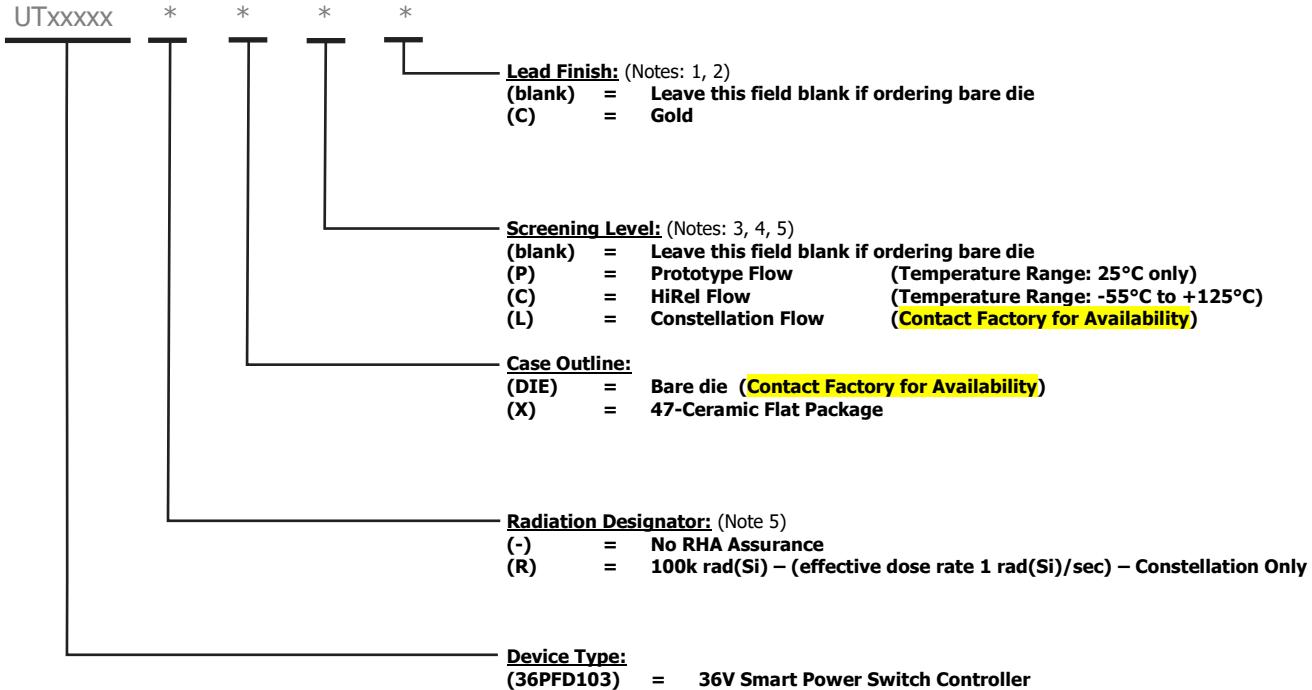


Figure 15-1: 47-Lead Flatpack Outline Drawing

16 Ordering information

16.1 Frontgrade Part Number

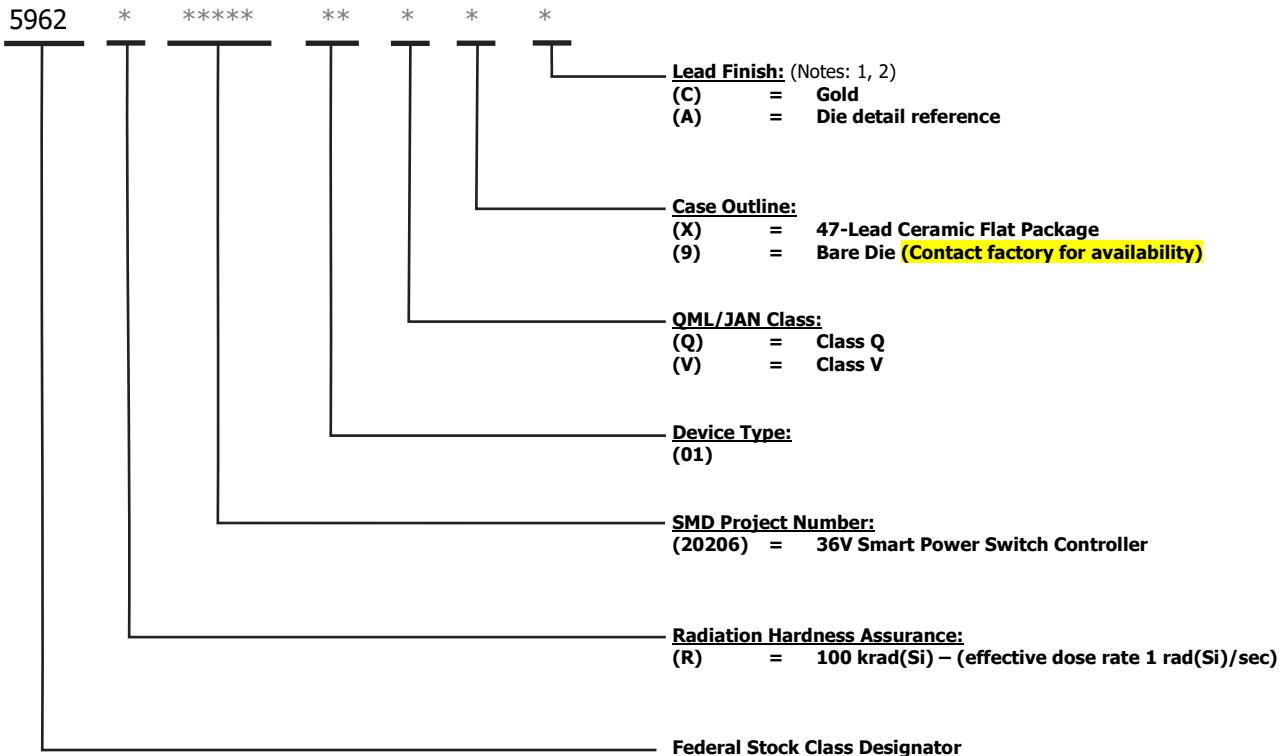
Generic Datasheet Part Numbering



NOTES:

1. Lead finish (A, C, or X) must be specified.
2. If and "X" is specified when ordering, then the part marking will match the lead finish applied to the device shipped
3. Prototype Flow per FRONTGRADE Manufacturing Flows Document. Lead finish is Factory Option "X" - only. Radiation is neither tested nor guaranteed.
4. HiRel Flow per FRONTGRADE Manufacturing Flows Document.
5. Constellation Flow per FRONTGRADE Manufacturing Flows Document. Radiation TID tolerance may (or may not) be ordered.

16.2 SMD Part Number



NOTES:

1. Lead finish must be specified. If "X" is specified when ordering, the factory will determine lead finish. Part marking will reflect the lead finish applied to the device shipped.
2. If ordering bare die, the lead finish refers to the associated die detail drawing in the SMD. The sequence follows the English alphabet, beginning with "A".

17 Revision History

Date	Version	Editor	Datasheet Level	Change Description
8/5/2019	1.0	TLM	Advanced	Initial Customer Release
8/29/2019	1.1	TLM	Advanced	Formatting Edits
10/23/2019	1.2	TLM	Advanced	Added SMD Number and ordering information. Updated ADC parameters. Added ADC Transfer Function. Updated PMBus telemetry readout for VIN, VOUT, and IDS.
12/5/2019	1.3	TLM	Advanced	Added Prototype test coverage note "*" for only parameters tested on prototypes. Updated some parameters in section 10.0 to reflect more accurate test data. Added many typical performance charts taken from recent test data to Section 12.0.
1/30/2020	1.4	TLM	Advanced	Updated Pin list to properly reflect cold-spared IO pins. Added discussion on "hiccup" mode in section 6.4. Added PMBus CAPABILITY command (19h) to list of supported PMBus functions (section 13.1.1). Updated TID capability to 300K rad(Si) and SEL immunity to 100 MeV-cm ² /mg. Added 300k rad(Si) TID offering to ordering pages along with LeanRel product offering. Updated package drawing with pedestal thickness and overall package thickness.
2/26/2020	2.0	TLM	Preliminary	Changed datasheet from Advanced to Preliminary. DC Electrical Tables 10-X updated to more accurately address test conditions, adjust target limits as appropriate, removed non-essential parameters and updated parameter notes to better reflect those that shall not be expected to receive full measurement level testing during production. Timing Characteristics Tables 11-X updated to more accurately reflect test conditions, remove non-essential or non-applicable parameters and updated notes to better reflect those that shall not be expected to receive full measurement level testing during production. Timing parameters associated with the FET Gate Driver outputs (G_OR and G_INR) will not include the contribution of MILLER CAPACITANCE or GATE-CHARGE during production testing. As such their transitional threshold for timing purposes will be to the 50% switching point. Timing diagrams have been updated to reflect this change, even when the show Miller Plateaus, which are provided for application visualization only.
4/30/2021	2.1	TLM	Preliminary	Converted document to new FRONTGRADE template. Added package mass. Clarified PMB_EN pin description. Expanded section 6.1 to provide more accurate VOUT slew rate calculations. Corrected/clarified conditions in Table 10-1. Corrected limits and added 2 new parameters in Table 10-5. Corrected and added previously undefined limits in Table 10-6. Corrected limit in Table 11-6. Added clarifying wording regarding SMBus address parity in section 13.1.2 and corrected SMBus address MSA:LSA ordering Table 13-2. Updated part ordering descriptions.
8/11/2021	2.2	TLM	Preliminary	Added SpaceVPX/SpaceUM VS1 switching in application section of first page. Removed Cold-Sparing as an I/O feature throughout document. Added strong recommendation for series resistor with CMILLER pin for current protection during fast eFuse events in section 6.1. Added Single Event Burnout as parameter in Table 8-1 and updated notes. Added note to Table 9-1 Recommended Operating Conditions to indicate 36V continuous operation is after derating from the technology capability. Corrected/updated limits in Tables 10-2 and 10-4. Corrected conditions, limits, and added note to several parameters in Table 11-7. Added clarifying note to PMBus commands 88h, 8Bh, and 8Ch described in section 13.1.1
4/22/2022	3.0	TLM	Final	Updated many parameter limits in Tables 10-x and 11-x based on full device characterization.
5/12/2022	3.1	TLM	Final	Table 8-1: Updated Radiation Effects parameters Table 10-3 thru 10-5 updated pin capacitances per char Table 11-3: Correct Min/Max column heading type-o Table 11-8: Added Functionally Tested note to fSMB parameter
5/17/2022	3.2	TLM	Final	Table 11-1: Corrected tCLB_RESET from 1us -> 5us max

Date	Version	Editor	Datasheet Level	Change Description
9/22/2022	3.3	TLM	Final	<p>Table 10-x: Updated pin capacitance throughout</p> <p>Table 10-4: Corrected sign on C_TIMER Charge & Discharge limits</p> <p>Table 10-4: Added Note 8 to F_{C_TIMER} parameter to include the expression used to calculate the C_TIMER oscillator frequency</p> <p>Table 11-5: Increased max limit for timing to PGOOD events; $90\mu s \rightarrow 120\mu s$</p> <p>Figures 11-x: Changed G_INR measurement trigger thresholds to reflect Falling Trigger at AVDD-1V and Rising Trigger at VZ13P5_HS+1V</p> <p>Section 12: Added and updated most Typical Characteristic Curves based on final Characterization data</p> <p>Added Section 13.1 and subsections describing SMBus Address Resolution Protocol (ARP) and the Unique Device ID (UDID) for the SPSC</p> <p>Section 16: Added "Contact factory for availability" notes for DIE Sales and Constellation Space ordering options and removed 300krad (Si) from device offerings, and removed solder dipped lead options</p>
3/07/2025	3.4	TLM	Final	<p>Applied new Frontgrade template/formatting to all pages.</p> <p>Page 12: Added new information (Important Note) regarding the efficacy of the PMBus Operation command to re-start operation once the G_INR control is latched off due to an Over Current or Short Circuit fault.</p>

Datasheet Definitions

	Definition
Advanced Datasheet	FRONTGRADE reserves the right to make changes to any products and services described herein at any time without notice. The product is still in the development stage and the datasheet is subject to change . Specifications can be TBD and the part package and pinout are not final .
Preliminary Datasheet	FRONTGRADE reserves the right to make changes to any products and services described herein at any time without notice. The product is in the characterization stage and prototypes are available.
Datasheet	Product is in Production and any changes to the product and services described herein will follow a formal customer notification process for form, fit or function changes.

Product ECCN Classification 9A515.e.1

Frontgrade Technologies Proprietary Information Frontgrade Technologies (Frontgrade or Company) reserves the right to make changes to any products and services described herein at any time without notice. Consult a Frontgrade sales representative to verify that the information contained herein is current before using the product described herein. Frontgrade does not assume any responsibility or liability arising out of the application or use of any product or service described herein, except as expressly agreed to in writing by the Company; nor does the purchase, lease, or use of a product or service convey a license to any patent's rights, copyrights, trademark rights, or any other intellectual property rights of the Company or any third party.

Distribution Statement A: Approved for public release. Distribution is unlimited.